

# COMMISSION OF THE EUROPEAN COMMUNITIES

Brussels,28.05.1996 COM(96) 216 final

Proposal for a

# **COUNCIL REGULATION (EC)**

temporarily suspending the autonomous Common Customs Tariff duties on certain industrial and agricultural products

(presented by the Commission)

#### EXPLANATORY MEMORANDUM

- 1. During the first quarter of this year the Commission, assisted by the Economic Tariff Questions Group, examined all the requests for temporary suspension of autonomous Common Customs Tariff duties submitted by the Member States, including requests for the renewal of suspensions currently in force.
- 2. The enclosed proposal covers industrial and agricultural products.
- 3. The requests for suspensions in respect of these products were examined in the light of criteria laid down in the communication from the Commission to the Council and the Member States on autonomous tariff suspensions (see OJ No C 235 of 13 September 1989, p.2).

On the basis of this examination, the Commission decided that the suspension of or reduction in duties was justified for the products listed in the annex to the proposal.

4. As stipulated in Article 1 of the annexed draft Regulation, the measure will be valid for an indefinite period so that legislation will be required only in the event of amendments or technical adaptations to the tariff suspensions.

#### Proposal for a

## COUNCIL REGULATION (EC) N° /96

1996

of

# temporarily suspending the autonomous Common Customs Tariff duties on certain industrial and agricultural products.

#### THE COUNCIL OF THE EUROPEAN UNION,

Having regard to the Treaty establishing the European Economic Community, and in particular Article 28 thereof,

Having regard to the proposal from the Commission,

Whereas production in the Community of the products specified in this Regulation is currently inadequate or non-existent; whereas producers thus cannot meet the needs of user industries in the Community;

Whereas it is in the interest of the Community to suspend partially or totally the autonomous Common Customs Tariff duties for these products;

Whereas the decision to suspend such autonomous duties should be taken by the Community;

Whereas the regulations temporarily suspending the autonomous Common Customs Tariff duties on certain industrial and agricultural products have largely renewed previous measures; whereas, therefore, in the interests of rationalizing implementation of the measures concerned, it would seem appropriate not to limit the period of validity of this regulation as its scope can be adapted and products added to or removed from the list through a Council Regulation, if necessary;

Whereas the amendments to the combined nomenclature and the Taric codes do not give rise to any substantive amendment; whereas, for reasons of simplification, provision should be made to empower the Commission, following receipt of the opinion of the Customs Code Committee, to make the necessary amendments and technical adaptations of the annex to this Regulation, including the publication of a consolidated version;

### HAD ADOPTED THIS REGULATION:

## Article 1

The autonomous Common Customs Tariff duties for the products listed in the Annex hereto shall be suspended at the level indicated against each of them.

#### Article 2

The amendments and technical adaptations, including the publication of a consolidated version, arising from amendments of the combined nomenclature and Taric codes shall be adopted by the Commission in accordance with the procedure laid down in Article 3.

#### Article 3

1. The Commission shall be assisted by the Customs Code Committee set up by Article 247 of Regulation (EEC) No 2913/92<sup>1</sup>.

2. The representative of the Commission shall submit to the Committee a draft of the measures to be taken. The Committee shall deliver its opinion on the draft within a time limit which the chairman may lay down according to the urgency of the matter. The opinion shall be delivered by the majority laid down in Article 148 (2) of the Treaty in the case of decisions which the Council is required to adopt on a proposal from the Commission. The votes of the representatives of the Member States within the Committee shall be weighted in the manner set out in that Article. The chairman shall not vote.

<sup>&</sup>lt;sup>1</sup> OJ No L 302, 19.10.1992, p. 1. As amended by the Act of Accession.

The Commission shall adopt measures which apply immediately. However, if these measures are not in accordance with the opinion of the Committee, they shall be communicated by the Commission to the Council forthwith. In that event, the Commission shall defer application of the measures which it has decided for three months from the date of such communication.

The Council, acting by a qualified majority, may take a different decision within the period referred to in the previous indent.

3. The Committee may examine any question concerning the application of Article 2 of this

Regulation which is raised by its chairman, either on his own initiative or at the request of a Member State.

#### Article 4

This Regulation shall enter into force on the day following its publication in the *Official Journal of the European Communities*.

It shall apply from I July 1996.

This Regulation shall be binding in its entirety and directly applicable in all Member States.

Done at ,

#### For the Council

The President

## ANNEX

	CN code	TARIC	Description of goods	Autonomous duties (X)
1	sx07102100	¥19	Pass in pods, of the species <i>Pisue setivue</i> of the variety <i>Hortense exiphius</i> , frozen, of a thickness not exceeding Sem, to be used, in their pods, in the manufacture of prepared meals (a) (b)	8
2	ex87119868	*11 #91	Mushrooms, excluding mushrooms of the species Agaricus spp., provisionally preserved in brine, in sulphur water, or in other preservative molutions, but unsuitable in that state for immediate consumption, for the food-canning industry (a)	8
3	ex07123000	*17 *24	Mushrooms, excluding mushrooms of the species Agericus spp., dried, whole or in identifiable slices or pieces, for treatment other then simple repecking for retail sale (m) (b)	8
4	ex07133390 -	¥28	Beans, white, dried, of the species <i>Phaseolus vulgeris</i> , of which not more than 2% by weight are retained by a screen with apertures of a diameter of 8mm, for use in the food-cenning industry (a)	e .
5	ex88841888	#11 #21	Datas, frash or dried, for the processing industry, other than for the production of alcohol (a)	θ
6	ex88841888	#12 #22	Datas, fresh or dried, for pecking for retail sale into issediate packings of a net content not exceeding 11kg (a)	θ
7	ex08104050	₹19	Fruit of the species Vaccinius aacrocarpon, fresh	8
8	ex08109085	<b>≇</b> 19	Rose-hips, fresh	θ
9	08119070 ex88119895	*66 *67	Fruit of the genus <i>Vacciniua</i> , uncooked or cooked by steasing or boiling in water, frozen, not containing added sugar or other sweetening matter	8
10	ex08119895	¥49	Rose-hips, uncooked or cooked by steesing or boiling in water, frozen, not containing added sugar or other sweetening matter	θ

	CN code	TARIC	Description	Rate of autonomous duty (X)
1	ex27679911	<b>\$10</b>	Crude light oils containing by weight: - 18% or more of vinyltoluenes, - 18% or more of indene and	
			=no - 1% or more but not more than 5% of naphthalana	θ
5	ex28053010	*10	Alloy of cerium and other rars-sorth metals, containing by weight 47% or more of cerium	8
6	Ex28053010	•28	Alloy of lanthanum and other rare earth metals, containing by weight 43% or more of lanthanum	8
8	ex28111998	¥10	Sulphamidic acid	θ
8	ex28112998	<b>#10</b>	Tellurium dioxide	θ
19	ax28183000	*10	Aluminium hydroxide oxide in the form of pseudo-boshmite	4
11	ex28199000	¥28	Dichromium trioxida: - of a specific surface of 37m <sup>2</sup> /g or more (as determined by the BET method), - of a purity by weight of 99,5% or more calculated on the dry substance, - of a specific gravity of 1,2g/cm <sup>3</sup> or less, for the manufacture of magnetic tapes (a)	8
14	ex28230000	¥10	Titanium dioxide, of a purity by weight of 99,9% or more, with an average grain-size of 1,2 micrometres or more but not axceeding 1,8 micrometres, for the manufacture of goods of heading No8532 or 8533 (m)	θ
15	ex28255000	+19	Copper (II) oxide containing by weight 78% or more of copper and not more than 0,03% of chloride	θ
17	ex28269098	¥10	Potassium hexafluorophosphate	θ
18	ex28273998	<b>#10</b>	Copper monochloride of a purity by weight of 96% or more but not exceeding 99%	θ
19	ax28276888	¥10	Titanium tetraiodide	θ
20	Bx28369100	₹28	Lithium carbonate, containing one or more of the following impurities at the concentrations indicated: - 2mg/kg or more of arsenic - 200mg/kg or more of calcium - 200mg/kg or more of chlorides - 20mg/kg or more of iron - 150mg/kg or more of magnesium - 20mg/kg or more of heavy matals - 300mg/kg or more of potassium - 300mg/kg or more of sodium - 200mg/kg or more of sulphates, determined according to the methods specified in the European Phonescopain	·
21	Ex28399800	<b>#10</b>	Pharmacopeia Lead silicate hydrate, of a lead content by weight of 84,5%	
			(±1,5%), evaluated as lead monoxide, in the form of powder	θ
	8x28439898	\$28	Palladium monoxide	θ
25 26	28451988 28459818		Heavy water (deuterium oxide) ( <i>Eurstom</i> ) Deuterium and compounds thereof; hydrogen and compounds thereof, enriched in deuterium; mixtures and solutions containing these products ( <i>Eurstom</i> )	e
28	ex29829898	#15	1,2-Di(3,4-xylyl)ethans	8
29	ex29829898	#48	p-Cymene	8
30	ex29829898	+45	2-Methylnephthelene	θ ΄
32	ex29029090	€78	1,2,4,5-Tatreesthylbenzene (durene)	θ

	CN code	TARIC	Description	Rate of autonomous duty (%)
3	ax29033010	\$10	Carbon tatrafluoride (tetrafluoromethane)	θ
34	ax29833818	\$20	1,1,1,2,3,3,3-Heplefluoropropene	θ
36	ex29035990	<b>₽10</b>	1,6,7,8,9,14,15,18,17,17,18,18-Dodecachloropentacyclo[12.2.1.1 6,9,0 <sup>2</sup> ,1 <sup>3</sup> ,0 <sup>5</sup> ,1 <sup>9</sup> ]octadeca-7,15-diana, for use in the sanufacture of polyamida, polyathylana, synthetic rubber or polyatyrene (m)	θ
37	sx29835998	¥28	Hexachlorocyclopentadiene	8
38	ex29036990	¥10	Di- or tatrachtorotricyclo[8.2.2.2 <sup>4,7</sup> ]haxadeca-1(12),4,6,10,13,15-h exaene, mixed imomerm	θ
39	8×29841888	#30	Sodium p-styrenemulphonate	θ.
48	ax29842898	¥10	Nitromethanm	8
41	ex29842898	¥28	Nitroethane	θ
42	ex29842898	<b>#</b> 30	1-Nitropropane	θ.
43	ex29842898	<b>≇4</b> 8	2-Nitropropana	θ
44	ex29049020	¥10	Tosyl chloride	θ
45	Bx29049080	<b>#</b> 10	Trichloronitromethame, for the manufacture of goods of subheading 388828 (m)	θ
47	ex29851918	¥10	Potassium <i>tert</i> -butoxidm	θ
48	29852918	-	Allyi sicohol	θ
51	ex29653998	<b>\$</b> 30	2-Kethylpropane-1,3-diol	θ
52	ex29854918	¥10	Ethylidynatri∎ethanol	θ
54	29861188		Manihol	θ
55	ex29861988	<b>≇10</b> ·	Labd-14-ene-8,13-diol	θ
56	Ex29062990	<b>#10</b>	2,2'-(#-Phenylene)dipropan-2-ol	θ
58	вx29872188	<b>#</b> 10	Resorcinol	θ
60	ex29872998	¥50	Disodium 1,4-dihydroanthracana-9,18-diolata, in the form of an aqueous solution	é
61	ex29872998	\$60	4,4'-(3,3,5-Trimethylcyclohexylidenm)diphenol	θ
62	ex29072998	<b>\$</b> 70	4,4',4"-Ethylidyneiriphenol	θ
59	ex29872998	\$88	Mixture of isomers of methylenediphenol	θ
63	ex29089000	\$10	4-Nitroso-o-cresol	8
64	ex29891988	\$18	1,2-Bis(2-chloroethoxy)ethane	θ
67	ex29893898	¥10	4-(p-Tolyloxy)biphenyl	8
68	ex29894488	¥10	2-Hexyloxyethanol	θ
70	ex29895898	<b>#</b> 10	4-(2-Methoxyethyl)phenol	8
71	ex29199888	<b>₽</b> 30	2,3-Epoxypropan-1-ol (glycidol)	θ
72	ex29109000	₹48	Perfluoroepoxypropene	θ
73	ex29124988	\$18	3-Phenoxybenzeldehyde	θ
75	ex29145000	¥30	2'-Hydroxyscetophenone	θ
76	8×29145000	<b>€4</b> 8	4'-Hydroxyscstophenone	8

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	CN code	TARIC	Description	Rate of autono∎ous duty (%)
78	ex29147898	<b>*20</b>	21-Chloro-98,118-apoxy-17-hydroxy-16«-methylpregna-1,4-di mme-3,20-dione	θ
79	ex29152900	\$10	Antimony trincetate	θ
88	ex29153990	¥28	5e-Bromo-8f-hydroxy-1?-oxo-mndrosten-3f-yl acetale	θ
82	ex29159080	<b>\$28</b>	Trimethyl orthoacatate	θ
83	ex29161298	*10	<b>2-tert-Butyl-8-(3-tert-</b> butyl-2-hydroxy-5-methylbenzyl)- <b>4-methylphenyl acrylate</b>	θ
84	ex29181490	¥19	2,3-Epoxypropyl methacrylate	θ
86	ex29162888	*10	Methyl 3-(2,2-dichlorovinyl)-2,2-dimethylcyclopropanecarboxylata	θ -
87	ex29162000	¥30	Empenthrin (180)	8
88	ex29163999	#18	Nethyl 3-chlorobenzoste	θ
89	ex29163988	\$20	3,5-Dichlorobenzcyl chlaride	3.6
92	ex29171990	\$28	<b>Sodiue 1,2-bis(cyclohexyloxycerbonyl)</b> ethanesulphonate	θ
93	ex29172888	\$38	1,4,5,6,7,7-Kexachloro-8,9,10-trinorborn-5-ene-2,3-dicarboxylic anhydride	θ
100	ex29173998	\$35	Dimethyl naphthalene-2,6-dicarboxylata	θ
95	ex29173990	¥75	Benzene-1,2,4,5-tetrecerboxylic acid (pyrometlitic acid)	θ
91	ex29181398	<b>#10</b>	L-(-)-Di-p-toluoyltærtæric æcid	9
182	ex29181788	<b>#10</b>	Phenylglycolic acid (mandalic acid)	θ
103	ax29181910	<b>#</b> 19	Malic acid	θ
185	sx29182918	<b>≋</b> 10	2-Hydroxy-1-naphthoic acid	θ
106	ex29182958	*18	Gallic scid, of a purity by weight of 99,7% or more calculated on the dry weight (measured by acidimetry), with a moisture content by weight of less than 18%, a sulphated ash content by weight of less than 8,86%, an iron content of less than 8mg/kg and an iodine colour number not exceeding 3 on the DIN 6162 scale	θ
107	ex29182998	*10	Hexamethylene bis[3-(3,5-di- <i>tert</i> -butyl-4-hydroxyphenyl:propionate]	θ
111	ex29198898	<b>*</b> 10	2,2'-Methylenebis(4,6-di- <i>tert</i> -butylphenyl) phosphate, ∎onosodiu∎ selt	θ
112	ex29201000	\$10	Fanitrothion (ISO)	θ
113	ex29201000	¥20	Tolclofos-methyl (ISO)	9
114	sx29289818	\$10	Diethyl sulphate	θ
115	29289838		Triaethyl phosphite	θ
116	ex29209080	<b>*</b> 19	0,0'-Dioctadecyl pentaerythritol bis(phosphite)	8
117	ax29209080	\$30	0,0'~Sim(2,4-di- <i>tert</i> -butylphenyl)pentaerythritol bim(phamphite)	θ
118	■x29289885	<b>≇6</b> 0	Tairmathyl orthosilicate, of a purity by weight of 89,99% or more and containing: - 1.0 crogram/kg or less of calcium, 1.8 sicrogram/kg or less of chromium, - 2.0 microgram/kg or less of iron and - 2.0 microgram/kg or less of modium,	
			for use in the manufacture of goods of heading No8542 (a)	θ

	CN code	TARIC	Description	Rate of autonomous duty (X
120	ex29211990	<b>*</b> 38	Trisllylesine	8
121	ex29212900	¥10	N, N, N', N'-Tetrabutythexamethytenediamine	θ
122	8x29212900	\$28	Tris[3-(dimethylmmino)propyl]mminm	θ
123	ex29212900	¥38	Bis[3-(dimethylamino)propyl]methylaminc	0
125	8x29213090	¥20	Dicyclohaxyl(methyl)mmine	8
127	8x29214210	₹19	2,6-Dichloro-4-nitromniling	8
128	ax29214218	¥28	2-Bromo-4,6-dinitromniling	θ
129	ax29214218	¥38	4-Aminobenzene-1,3-dimulphonic modiand its malts	0
130	8x29214390	¥10	5-Amino-2-chlorotolumne-4-mulphonic mcid	θ
131	ex29214500	¥18	3-Aminonaphthmlmnm-1,5-dimulphonic mcid, monomodium mmlt	θ
132	ax29214910	¥20	Pendi∎ethelin (180)	3.5
138	ex29215988	¥60	Mixture of isosers of 3,5-diethyltoluenedissine	θ
139	ex29221900	+55	4,4-Disethoxybutylasine	8
148	ax29221988	¥68	2-[2-(Disethylasino)ethyl(sethyl)ssino]ethanol	θ
141	ex29221988	¥70	N, N, N', N'-Tetrassthyl-2, 2'-oxybis(ethylssins)	θ
142	sx29222188	¥10	2-Amino-5-hydroxynmphthmlenm-1,7-disulphonic moid mnd its salts, of a purity by weight of 80% or more	8
143	ex29222988	<b>#</b> 10	2-Methyl-W-phenyl-p-enisidine	θ
144	ex29222900	¥20	3-Aminophenol	θ
145	ex29222988	#3 <del>0</del>	4-Amino-5-methoxy-2-methylbenzenesulphonic acid	θ
146	ex29222908	¥40	2-Asino-4- <i>tert</i> -pentyl-6-nitrophenol	θ
147	ex29223000	¥10	1-Amino-4-bromo-9,10-dioxoanthrmcmnm-2-sulphonic modiate and its salts	θ
150	ex29225000	¥50	2-(4-Dibutylaminosalicyloyl)benzoic acid	8
151	ex29239000	¥10	Tetramethylammonium hydroxide, in the form of an aqueous solution containing: - 25% (±0,1%) by weight of tetramethylammonium hydroxide, - 5mg/kg or less of halidm, - 10 microgramms/kg or less of sodium, - 10 microgramms/kg or less of calcium, - 10 microgramms/kg or less of iron and	•
			- 18 micrograms/kg or lass of zinc	θ
152	ex29241000	¥20	2-Acrylamido-2-methylpropmnesulphonic acid and its modium or mmmonium salts	θ
153	Ex29241000	≢30	W-(1,1-Diasthyl-3-oxobutyl)scrylaside	8
154	ex29242998	¥48	Diethofencarb (180)	θ
155	ex29242990	#58	3'-Disthylasino-4'-sethoxyscatenilide	8
156	ex29242990	¥69	5-[N-(2-Acetoxyethyl)scetoxyscetseido]-N,N'-bis(2,3-dis cetoxypropyl)-2,4,6-triiodoisophthelseide	θ
157	ex29251100	¥28	Saccharin and its sodium salt	θ
159	ex29251980	<b>#10</b>	∦-Phenyl∎alei∎ide	θ
160	ex29252888	<b>#</b> 10	Dicyclohexylcerbodiimide	θ

	CN code	TARIC	Description	Rate of autonomous duty (X)
162	ax28269886	+15	Nethecrytonitrile	θ
161	8x29269999	¥25	Ethyl 1-cyanocyclohexylacatate	θ
164	ex29269898	¥65	2-Amino-S-nitrobanzonitrile	θ
165	ex29269890	•75	Chlorothelonil (180)	θ
166	ex29269098	*88	2-Cyanoacataa i de	θ
167	ex29269898	•85	Alkyl or alkoxyalkyl astars of cyanoacatic acid	θ
168	ax29278888	¥10	2,2'-Dimethyl-2,2'-szodipropionemidine dihydrochloride	θ
169	ex29270000	₹28	4-Anilino-2-methoxybenzenediszonium hydrogen sulphste	θ
170	ex29288888	+58	3,3'-Bis(3,5-di-tert-butyl-4-hydroxyphanyl)-W,W'-bi propionaaida	θ
171	ex29288888	*68	2,4,8-Trichlorophanylhydrazina	θ
173	ax29291898	+10	Melhylenedicyclohexyl diisocyanate, aixed isomers	θ
174	ex29291090	<b>●</b> 3 <del>0</del>	3,3'-Dimethylbiphenyl-4,4'-diyl diimocymnate	θ
175	ex29291090	\$48	#-Isopropenyl-e,e-dimethylbenzyl isocyanate	θ
176	ex29291898	¥59	s-Phanylanediisopropylidane diisocyanata	θ
178	ex29309895	*84	Thiophenol	8
179	ex29389895	*88	Ethoprophos (180)	θ
180	ex29369895	<b>#69</b>	3,3-Dimethyl-1-methylthiobutanone oxime	θ
181	ex29389895	*11	Thiophanata-aethyl (180)	θ
183	ex29389895	<b>*</b> 15	4-(4-Isopropoxyphenylsulphonyl)phenol	θ
184	ex29309095	*17	3,3'-Thiodi(propionic scid)	θ
185	29310010		Disethyl sethylphosphonsts	θ
186	ex29318888	<b>#10</b>	2-Diphenylphosphinobenzoic acid	θ
187	ex29310060	<b>₩2</b> θ	Chlorodiphanylphosphine	θ
188	ex29310080	<b>#30</b>	Bis(2-chloroethyl) 2-chloroethylphosphonale	θ
189	ex29318888	₹48	8odium phenylphosphinate	θ
190	ex29310080	¥50	Bis(2-chlorosthyl) vinylphosphonate	θ
191	ex29318888	¥60	8odium tetraphenylborate	θ
192	Ex29310080	¥78	N-(Phosphonosethyl)isinodiscatic scid	θ
193	ex29321188	*10	Tetrahydrofuran, containing not more than 40mg per litre in total of tetrahydro-2-methylfuran and tetrahydro-3-methylfuran, for the manufacture of «-4-hydroxybutyl-»-hydroxypoly(oxytetramethylene) (m)	θ
194	ex29321308	•10	Tetrahydrofurfuryl alcohol	8
196	8x29321900	\$48	Furan of a purity by weight of 99% or more	θ
195		#50	2,3-Dihydrofuran	θ
	ex29322990	\$15	2'-Anilino-6'-[ethyl(isopentyl)amino]-3'-methylspiro[isob enzofurmn-1(3H),8'-xmnthen]-3-one	8
100	8x29322998	#30	13,14,15,16-Tetranorlabdano-12,8«-lactone	θ

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	CN code	TARIC	Description	Rais of autonomous duty (X
281	sx29322998	*55	2'-(2-Chloromnilino)-8'-dibutylaminompiru[imobenzofurmn-1(3 H),9'-xanthen]-3-one	8
283	ex29322990	¥61	2'-Anilino-3'-methyl-6'-methyl(propyl)mminompiro[isobenzo furan-1(3#),9'-xanthen]-3-ong 	θ
284	ex29322990	¥62	6'-Diethylamino-3'-metkyl-2'-(2,4-xylidino)mpiro[imobenzo furmn-1(3#),9'-xmtten]-3-onm	8
285	ax29322998	<b>₩</b> 78	2'-Anilino-8'-(W-ethyl-p-toluidino)-3'-methylspir o[isobenzo:uren-1(3H),9'-xenthen]-3-one	8
286	ex29322998	<b>*</b> 75	2'-0∩ilino-8'-sthyl(isobutyl)ssino-3'-sethylspiro[isobenz ciuran-1(3H),8'-xanthan]-3-one	8
287	Bx29322998	<b>#</b> 76	2'-Anilino-B'-cyclohexyl(methyl)emino-3'-methylspiro[isobenzo furen-1(3#),9'-xenthen]-3-one	θ
288	ex29322998	*77	6-Dimethylamino-3,3-bim(4-dimethylaminophenyl)phthalide	θ
216	ex29329970	<b>#</b> 10	Bendiocarb (ISO)	θ
211	ex29332188	<b>\$</b> 10	Hydentoin	8
212	ex29332100	¥28	2-(3-Benzyl-2,5-dioxoimidmzolidin-1-yl)-2'-chloro-5'-(3-dodecyl sulphonyl-2-methylpropionmmido)-4,4-dimethyl-3-oxovmleranilide	θ
213	ex29332100	<b>\$</b> 30	3'-[4,4-Dimethyl-2-(4,4-dimethyl-2,5-dioxoimidazolin-1-yl)-3-ox ovalerylamino]-4'-methoxymlearanilide	θ
214	ex29332998	¥20	Reaction product consisting of the methyl maters of (+/-)-6-(4-isopropyl-4-methyl-5-oxo-2-imidmzolin-2-yl)-m-tol uic methyl (+/-)-2-(4-isopropyl-4-methyl-5-oxo-2-imidmzolin-2-yl)-p-tol uic methyl) (Immzamethylenz-methyl)	4
215	ex29332998	*48	Triflumizole (ISO)	θ
221	ex29333980	<b>#</b> 12	2-Hydroxyethylassonius 3,6-dichloropyridine-2-carboxylate	θ
222	Ex29333988	#14	Cloperasting fendizoate (INNM)	θ
225	ex29333980	#18	Pyridine-2,3~dicarboxylic acid	β
226	∎×29333980	\$23	5-Methyl-2-pyridylasine	θ
229	ex29333980	¥28	I∎azethapyr (ISO)	θ
218	ex29333980	#29	4,4'-Trimethylenedipiperidine	θ
230	Ex29334898	₹28	5,7-Dichloro-4-(4-fluorophenoxy)quinoline	8
232	ex29335980	<b>#</b> 10	1-Ethyl-6-fluoro-1,4-dihydro-4-oxo-7-piperezin-1-yl-1,8-naphthy ridine-3-carboxylic ecid end its selts end esters	θ.
234	ex29336998	¥28	1,3,5-Tris(4- <i>tert</i> -butyl-3-hydroxy-2,6-dimethylbenzyl)-1,3,5 -trimzine-2,4,6(1H,3H,SH)-trione	8
235	вх2933699 <del>0</del>	•38	1,3,5-Tris[(3,5-di- <i>tert</i> -butyl-4-hydroxyphenyl)methyl]-1,3,5 -triazine-2,4,6(1H,3H,5H)-trione	8
236	ex29336998	<b>\$</b> 35	Tris(2,3-spoxypropyl)-1,3,5-triszinanatriona	θ
237	ex29336998	₹48	Cyanazine (ISO)	θ
248	ex29339080	€23	2-(2H-Benzotriezol-2-yl)-4,6-di- <i>tert</i> -butylphenol	θ
241	ex29339080	₹24	2-(2H-Benzotriezol-2-yl)-4,6-di- <i>tert</i> -pentylphenol	θ
242	ex29339080	\$27	2-(2H-Benzotrimzol-2-yl)-4,6-bis(1-methyl-1-phenylsthyl)phe nol	8
243	ex29339080	€28	6,6'-Di-2H-benzotrimzol-2-yl-4,4'-bis(1,1,3,3-tetrameth	θ

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	CN code	TARIC	Description	Rate of autono∎ous duty (X)
244	ex29339888	#30	Quizalofop-P-ethyl (180)	θ
245	ex29339888	<b>#</b> 31	Indoline .	θ
246	ax29341888	<b>#18</b>	Hexythiezox (180)	θ
247	sx28341888	¥28	2-(4-Methylthiszol-5-yl)ethanol	θ
250	#x29349899	•35	7-Chloro-5-methyl-2H-1,4-benzothimzin-3-(4H)-onm	θ
252	#x29349899	<b>\$</b> 37	Carboxin (180)	θ
253	ex29349899	<b>#</b> 38	4-[4-(Tridacyl[branchad]oxy)phanyl]-1,4-thiazinane 1,1-dioxide	8
254	ax29350000	¥38	Salts of sulfathiszols (INN)	0
256	ex29350000	\$48	Toluenesulphonesides	θ
257	ex29350680	#45	Mixture of isosers consisting of N-ethyltoluene-2-sulphoneside and N-ethyltoluene-4-sulphoneside	θ
259	32012000		Tanning extracts of wattle (mimosa)	θ
258	sx32819898	¥18	Tanning extracts of sucslyptus	3.2
261	sx32019090	¥28	Tanning extracts derived from gambier and myrobalan fruits	θ
263	ex32841588	#18	Dye C.I. Vat Orange ?	θ
264	sx32841588	¥28	Dye C.I. Vet Red 15	Q
265	ex32041500	¥38	Dym C.I. Vat Red 14	θ
262	sx32041500	+40	Dye C.I. Vet Brown 5?	θ
266	Ex32041700	<b>#</b> 10	Dym C.I. Pigment Vellow 81	θ
267	ex32864998	<b>≇10</b>	Black preparation of iron-oxide pigments, in liquid form, with a maximum particle-size not exceeding 20 nanometres and contmining by weight 25% or more of iron evaluated as Fe <sub>2</sub> O <sub>3</sub> , for the manufacture of goods of heading No 3304 or 9608 (m)	θ
270	ex32082010	¥18	Copolymer of N-vinylcaprolactas, N-vinyl-2-pyrrolidone and dimethylaminosthyl methacrylsts, in the form of a solution in sthemol containing by weight 34% or more but not more than 48% of copolymer	θ
273	ex32159080	<b>#18</b>	Ink formulation, for use in the manufacture of ink jet cartridgas (m)	θ
275	33011210		Essential oil of orange, not deterpenated	θ
277	ax34829818	¥28	Mixture of docusate sodium (INN) and sodium benzoate	θ
278	ex34029090	<b>\$10</b>	Crystalling powder obtained by the reaction of trisodium phosphate with a mixture of sodium hypochlorite and sodium chloride ('chlorinated trisodium phosphate'), containing by weight: - 3,5% or more of evailable chlorine, measured iodometrically and - 17,8% or more of phosphorus evaluated as P <sub>2</sub> O <sub>5</sub>	θ
279	ex35040000	¥10	Purified entigens obtained from genetically-manipulated yemat-calls, for the manufacture of detection-tests for hepatitis-C (m)	θ
280	ex35040000	¥28	Glycoprolain 188 obtained from Kuman Immunodeficiency Virus, HIV-1 strain	θ
281	ex35051050	¥2 <del>0</del>	0-(2-Hydroxysthyl)-derivative of hydrolysed wexy esize-sterch	е

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	CN code	TARIC	Description	Raie of autonomous duty (%
282	ex35069100	*10	Adhesive based on an aqueous dispersion of a mixture of dimerimed romin and a copolymer of athylene and vinyl acetate (EVA)	8
285	ax35079000	¥65	Asparaginase	8
286	ex35679666	\$70	Enzymmtic preparation based on thermolysine	θ
287	ex35079000	*80	L-Lactata: oxygen-2-oxidoreductase, non-decerboxylating	θ
288	ax37013060	¥18	Letterpress printing plates, consisting of a metal substrate covered with a photopolymer layer containing by weight 15% or more but not more than 48% of 2-hydroxysthyl methacrylete, of a total thickness of 0.67mm or more but not exceeding 0.77mm	8
289	=x37019900	*10	Plate of quartz or of glass, covered with a film of chromium and coaled with a photo-mensitive or electron-mensitive remin, for the menufacture of masks for the goods of heading No8541 or 8542 (m)	θ
291	38052800		Pine oil	1.7
292	■×38082080	*18	Fungicide in the form of m powder, containing by weight 65% or more but not more then 75% of hymexazole (180), not put up for retail sale, for the pelleting of seeds (a)	θ
293	Bx38084090	*10	1-Dodecylguanidine hydrochloride, in the for∎ of a solution in isopropanol and water, containing by weight 40% or less of 1-dodecylguanidine hydrochloride	θ
294	sx38099100	*18	Mixture of 5-ethyl-2-methyl-2-oxo-1,3,22 <sup>5</sup> -dioxaphosphoran-5-ylmet hyl methyl methylphosphonmte and bis(5-ethyl-2-methyl-2-oxo-1,3,22 <sup>5</sup> -dioxaphosphoran-5-y lmethyl) methylphosphonmte	θ
285	8x38859200	#10	Paper snti-fading agent, consisting of a mixture of wagnesium trisilicate and monosodium salt of 2,2'-methylenebis(4,6-di- <i>lart</i> -butylphenyl) phosphate	θ
296	ex38112168	¥10	Salts of dinonylnaphthalenesulphonic acid, in the form of a solution in mineral oils	θ
298	ex38123080	¥10	Tetrasluminium nonamagnesium dicarbonate hexacosahydroxide haplahydrate, coatad with a surface∽active agent	0
299	ex38123080	¥20	Mixture containing predo≋inantly bis(2,2,6,6-tatramethyl-1-octyloxy-4-piperidyl) sebacate	θ
300	ex38123080	<b>\$</b> 30	Compound stabilimers containing by weight 15% or more but not more than 48% of modium perchlorate and not more than 78% of 2-(2-methoxyethoxy)ethanol	8
301	ex38151200	¥10	Catalyst, in the form of granules or rings of a diameter of 3mm or more but not exceeding 10mm, consisting of silver on an aluminium-oxide support and containing by weight 8% or more but not more than 20% of silver	θ
382	ex38151200	*20	Catalyst consisting of palladium and rhenium, fixed on a support of active carbon, in the form of powder, containing: - 0,5% or more but not more than 1,5% by weight of palladium, - 3% or more but not more than 5% by weight of rhenium and - 0,1 mole% or more but not more than 1 mole% of alkaline metals,	
			for use in the manufacture of tetrahydrofuran (m)	θ
384	ax38151900	¥03	Catalyst, consisting of chromium trioxide or dichromium trioxide fixed on a silicon-dioxide support, of a pors-volume, as determined by the nitrogen-absorption method, of 2cm <sup>3</sup> /g	

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	CN code	TARIC	Description	Rate of autonomous duty (%)
305	ex38151988	#11	Catalyst consisting of chrosius oxides and titanius dioxide fixed on a support of silicon dioxide, aluminius oxide or aluminius phosphate	θ
306	ex38151900	¥13	Catalyst consisting of titanius tetrachloride supported on magnesius dichloride, in the form of a suspension in minarel oil or in hexane, for use in the manufacture of polypropylene (a)	8
307	ex38151900	*14	Catalyst, in the form of spheres of a dismater of 4,2mm or more but not exceeding 9mm, consisting of a mixture of oxides of molybdenum, tungsten, vanedium, copper and mirontium, on a support of milicon dioxide and/or mluminium oxide, for use in the manufacture of acrylic acid (m)	8
388	ex38151988	¥15	Catalyst consisting of organo-metallic compounds of titanium, magnesium and aluminium on a support of silicon dioxide, in the form of a suspension in tetrahydrofuran	θ
369	ex38151900	#16	Catalyst consisting of dichrosius trioxide, fixed on a support of alusinius oxide	θ
310	ex38159000	¥15	Catalyst, in the form of rodists of a dimmater of 4mm or more but not exceeding 8mm, consisting of a mixturm of oxides containing by weight more than 96% of oxides of molybdenum, vanadium, nickel and antimony, for use in the manufacture of acrylic acid (m)	θ
311	ex38159000	¥20	Catalyst, in powder form, consisting of a mixture of titanium trichloride and aluminium chloride, containing by weight: - 20% or more but not more than 30% of titanium and	
312	ex38159000	¥25	- 55% or more but not more than 72% of chlorine Catalyst, in the form of rodlets of a dimenter of 4mm or more but not exceeding 6mm, consisting of a mixture of oxides containing by weight more than 96% of oxides of molybdenum, bisauth, nickel, iron and milicon, for use in the menufacture of acrytetdahyde (m)	θ 6
313	ex38159000	\$35	Catalyst, in the form of a suspension in oil, consisting of titanium trichloride and aluminium trichloride, containing by weight (on an oil-free basis): - 15% or more but not more than 30% of titanium and - 40% or more but not more than 72% of chloring	θ
315	ex38159060	<b>#</b> 55	Catalyst, in the form of rodlats of a length of 5mm or more but not exceeding 8mm, consisting of a mixture of oxides of iron, molybdenum and bismuth, for use in the manufacture of mcrylic mcid (m)	θ
316	ex38159060	¥78	Catalyst containing titanium trichlorids, in the form of m suspension in hexame or heptame containing by weight, in the hexame- or heptame-free material, 9% or more but not more than 38% of titanium	θ
317	ex38159668	<b>#</b> 75	Reaction initiator, consisting of a mixture of N,N,N',N'-tstramethyl-2,2'-oxybis(athylamine) and dipropylene glycols	θ
318	ex38159000	¥80	Catalyst, in the form of rodlets, consisting of an acid aluminomilicate (zeolita): - with a mole-ratio of silicon dioxide : dimluminium trioxide of not lease than 500 : 1 and - containing by weight 0,2% or more but not more than 0,8% of platinum	θ
319	ex38159888	₿86	Catalyst based on a mordanite zmolite, in the form of granules, for use in the manufacture of mixtures of methylamines containing by weight 50% or more of dimethylamine (m)	8
320	ex38159888	*87	Catalyst, consisting of a mixture of (2-hydroxypropyl)trimethylammonium formate and dipropylene glycols	θ

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	CN code	TARIC	Description	Rate of autonomous duty
322	ex38188010	*10	Silicon discs, with phosphorus diffused into one side, of a thickness not exceeding 310 micrometres, for use in the senufacture of semiconductor devices of heading No8541 (a)	θ
321	ax38180010	¥28	Mafer of monocrystalling silicon, with a layer of silicon oxide covered with a layer of deposited silicon, with a dismeter of more than 98mm but not exceeding 202mm.	θ
323	●x38220000	*18	Lyophilized extract of the blood cells of <i>Limulus</i> polyphemus (Limulum amoebocyte lymate)	θ
324	ex38220000	*28	Polyethylene terephthalate strip, costed with several layers of reagents of differing type and a surface layer of titanium dioxide or barium sulphate, for the monufacture of analysis cartridges for biochemical tests (a)	θ
325	■x38231910	•91	Mixture of fatty acids containing by weight: - 2% or more but not more than 6% of hexanoic acid, - 53% or more but not more than 60% of octanoic acid, - 34% or more but not more than 42% of decanoic acid and - not more than 2% of dodecanoic acid	θ
326	ex38249015	¥10	Acid eluminosilicate (artificial zeolite of the Y type) in the sodium form, containing by weight not more than 11% of sodium evaluated as modium oxide, in the form of rodlets	9
328	ex38249668	•82	Intermediate products of the antibiotics manufacturing process obtained from the fermentation of <i>Micromonospora purpurea</i> , whather or not dried	θ
329	8x38249868	¥83	Cholic acid and 3∉,12∉-dihydroxy-5β-cholan-24-oic acid (deoxycholic acid), crude	θ
338	ex38249668	¥04	Products obtained by the #-athylation of siscaycin (INN)	θ
332	ax38249868	*86	Intermediate products of the antibiotics manufacturing process obtained from the fermentation of <i>Micromonospora inyoansis</i> , whether or not dried	θ
333	#x38249868	*07	Residues of menufecture containing by weight 40% or more of 11β,17,20,21-tetrahydroxy-6-methylpregna-1,4-dien-3-one-21-ace tate	θ
334	Bx38249098	¥81	Colloidal dianti∎ony pentaoxide	θ
335	ex38249898	<b>#</b> 02	Mixture of nitromethane and 1,2-epoxybutane	β
361	ex38249698	*83	Grains or granules, consisting of a mixture of dialuminium trioxide and zirconium dioxide, containing by weight: - 78% or more but not more than 78% of dialuminium trioxide and - 19% or more but not more than 26% of zirconium dioxide	5.2
336	ax38249898	<b>#84</b>	Crude lithium hypochlorite	θ
337	ex38249898	¥85	Mixed oxides of barium, titanium and other metals, in the form of powder, containing by weight: - 5% or more of barium and - 15% or more of titanium,	
			for use as dielectric materials in the manufacture of multilayer caramic capacitors (a)	θ
339	sx38249090	¥67	Preperation, in the form of powder, containing by weight 75% or more of zinc bis[3,5-bis(1-phenylethyl)saticylate]	θ
340	ax38249898	•08	Film consisting of the oxides of barium, calcium and either titanium or zirconium, mixed with binding materials	8
342	ex38249690	*11	Preperation consisting essentially of alkaline asphalt sulphonate, of: - a specific gravity of 0,9 or ∎ore but not exceeding 1,5 and	
			- ∎ solubility in water of 7θ% by weight or ∎ore	θ

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	CN code	TARIC	Description	Rais of sutonomous duty (X)
343	ex38249898	÷12	Anti-corrosion preparations consisting of salts of dinonylmaphthalenesulphonic acid, sither: - on a support of sineral wax, whether or not sodified chasically,	· · · · · · · · · · · · · · · · · · ·
			or - in the form of a solution in an organic solvant	θ
344	ax38249998	+13	Calcined bauxile (refrectory grade)	θ
345	ex38249090	₹14	Magnetisable iron oxide, in the form of powder, containing by weight: - 30% or more but not more than 38% of bivalent iron in relation to the total iron and - 1% or more but not more than 4% of cobalt	θ
346	ax38249898	¥15	Spent catalyst, in the form of rodlets of dismeter of 1mm or more but not exceeding 3mm, containing a mixture of sulphides of tungsten and of nicket on a support of zeolite, containing by weight not more than 10% of tungsten and not more than 10% of nicket, for regeneration as a catalyst for hydrocerbon-cracking (m)	θ
347	ex38249898	*16	Nixture containing by weight: - 7% or more but not more than 9% of 2-methyl-1,3-phenylene diimocyanata, - 31% or more but not more than 34% of 4-methyl-1,3-phenylene diimocyanata, - 18% or more but not more than 13% of 2,4'-methylenediphenyl diimocyanata, - 48% or more but not more than 49% of 4,4'-methylenediphenyl diimocyanata	θ
349	ex38249090	<del>*</del> 18	Mixture of magnesium bromide 2-oxoperhydromzepin-1-ide and s-cmprolactem	θ
350	ex38249098	<b>#</b> 19	Mixture of disodium N-benzyloxycerbonyl-L-espertate and sodium chloridm, in the form of a solution in water	θ
51	&x38249898	•21	Disodium 9,10-dihydro-9,10-dioxosnthracene-2,7-disulphonate, containing by weight 10% or more but not more than 20% of sodium sulphate	θ
352	ex38249898	<b>\$</b> 22	Eutectic alloy wholly of potassium and sodium, containing by weight 77% or more but not more than 79% of potassium	θ
353	ex38249898	#23	Bland of taraphthaloyl dichlorida and isophthaloyl dichlorida	θ
354	ex38249898	¥25	Acid-hydrolysed cessin, containing by weight: - 8% or more but not more than 11% of nitrogen and - 18% or more but not more than 28% of modium chloride, for the manufacture of prepared culture media for development of micro-organisms (m)	θ
355	ex38249898	₹26	Preparation consisting by weight of 90% or more of 3a,4,7,7m-tetrahydro-4,7-methanoindenm (dicyclopentadienm), m synthetic rubber and - mither an aluminium-alkyl compound - or an organic complex of tungstan	θ
356	ex38249899	\$27	Nixture of tris[2-chloro-1-(chloromethyl)ethyl] phosphats and oligomers of methylphosphonic acid and phosphoric acid with athane-1,2-diol	e
357	ex38249090	\$28	Mixture of tris[2-chloro-1-(chlorosethyl)ethyl] phosphete and oligomers of 2-chlorosthyl phosphete with stheme-1,2-diol	θ
358	ex38249090	\$29	Mixture of sucrose esters, derived from the esterification of sucrose with industrial stearic acid	θ
359	ex38249898	*31	Preparations consisting predominantly of phosphabicyclononanes and P-alkyl derivatives thereof, in the form of a solution in 4-tert-butyltoluane	θ

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	CN code	TARIC	Description	Rate of autonomous duty (%)
368	ax38249898	\$32	Lithium tantalate wafers, undoped	8
362	**38249898	*35	Preparation consisting predominantly of sthylene glycol and N,N-dimethylformamide or sthylene glycol and y-butyrolactone, for the menufacture of electrolylic capacitors (m)	8
363	ax38249898	*36	Preparation consisting predominantly of y-butyrolactone and quaternary assonius salts, for the asnufacture of slectrolytic capacitors (s)	8
364	ex38249898	#37	2,4,7,9-Tetramethyldec-5-yn-4,7-diol, hydroxyethylaiad	8
365	ex38249898	\$38	Copper zinc ferrite, in the form of granules of a size not exceeding 128 micrometres, costed with a silicone resin	8
366	ax38249098	\$39	Styrens oligoser	θ
367	ax38249090	+41	Preparation consisting of e-(4-silyloxycarbonylbanzoyl)-w-silyloxypoly[oxy(2-s sthylsthylana)oxyteraphthaloyl] and sither disilyl-2,2'-oxydisthyl dicarbonate or disilyl isophthalate	θ
406	ex38249698	\$47	Mixture containing by waight 40% or more but not more than 50% of 2-hydroxyathyl methacrylate and 40% or more but not more than 50% of glycerol ester of boric acid	θ
90 bis	ax38249898	*48	Azelaic acid of a purity by weight of 75% or more but not axceeding 85%	θ
369	ax39012000	*18	Polysthylens, in one of the forms mentioned in note 6(b) to Chapter 39, of a specific gravity of 8,945 or more but not exceeding 8,985, for the manufacture of films for typewriter ribbon or mimilar ribbon (m)	θ
370	ex39012000	¥20	Polysihylens, containing by weight 35% or more but not more than 45% of mice	θ
373	ax39019000	<b>\$</b> 92	Ionomer resin consisting of a salt of a copolymer of ethylene with methacrylic acid	4
376	ax39019888	<b>#</b> 97	Copolymer of athylens, vinyl acetate and carbon monoxide, for use as a plasticizer in the manufacture of roof sheats (a)	θ .
377	ax39829888	<b>#</b> 92	Polymers of 4-methylpent-1-ene	θ
379	■×39029000 ■×39039000	#97 #68	A-B Block copolymer of polystyrene and an athylane-propylane copolymer, containing by weight 40% or lass of styrene, in one of the forms mentioned in note 6(b) to Chapter 39	θ
388	ex39631966	\$28	Polystyrene of a molecular weight not exceeding 5000	θ -
382	ex39838868	*20	Copolymer, entirely of styrene with maleic enhydride, or entirely of styrene with mateic anhydride and an acrylic monomer, whether or not containing a styrene-butadiene block copolymer, in one of the forms mentioned in note 6(b) to Chapter 39, for the manufacture of sheetings for head-liners for cars (a)	θ
383	ax 39639966	¥25	Copolymer, entiraly of styrene with malaic anhydrida, or entiraly of styrene with malaic anhydride and an acrylic monomer, also partially esterified, of an average molecular weight not exceeding 3000, in one of the forms mentioned in note 6(b) to Chapter 39	θ
385	ex39839888	\$40	Copolymer of styrene with 2-ethylhexyl acrylate or with n-butyl acrylate, containing: - 10 moleX or more but not more than 16 moleX of acrylate, - 0,2mg/kg or less of sodium and - 0,1mg/kg or less of calcium	θ
386	ex39039000	¥78	Copolymer of styrene, butyl acrylate and acrylic acid, containing by weight 92(±1)% of styrene, 7(±1)% of	

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	CN code	TARIC	Description	Rate of sutonomous duty (X)
387	ex39039000 ex39119090	\$80 \$89	Copolymer of e-methylistyrene and styrene, having a motioning point exceeding 113°C	8
389	ex39044080	*91	Copolymer of vinyl chloridm with vinyl memtate and vinyl alcohol, containing by weight: - 87% or more but not more than 92% of vinyl chloridm, - 2% or more but not more than 9% of vinyl acetate and - 1% or more but not more than 8% of vinyl alcohol,	
			in one of the forms mentioned in note 6 (m) or (b) to Chapter 39	8
398	Ex39044000	*92	Copolymer of vinyl chloride, vinyl scatate, hydroxypropyl acrylate and maleic acid, containing by weight 80% or more but not more than 83% of vinyl chloride, 1,8% or more but not more than 2% of hydroxy groups and 0,25% or more but not more than 0,38% of carboxyl groups	θ
392	ex39645000	€92	Copolymer of vinylidene chloride with vinyl chloride, containing by weight 79,5% or more of vinylidene chloride, in one of the forms mentioned in note 6 (m) or (b) to Chapter 39, for the menufacture of fibres, monofilement or strip (m)	θ
393	ex39846198	¥10	Mixture of polyletrafluoroathylene and mics, in one of the forms mentioned in note 6 (b) to Chapter 39	8
395	ex39046960	<b>#</b> 91	Copolymer of ethylane with chlorotrifluoroethylane and hexafluoro(2-methylpropane), in one of the forms mentioned in note 6(b) to Chapter 39	θ
396	ex39846988	<b>*</b> 92	Copolymer of tetrafluoroethylene and trifluoro(trifluoromethoxy)ethylene	θ
398	ex39046900	¥95	Copolymer of ethylene with chlorotrifluoroethylene, in one of the forms mentioned in note 6(b) to Chapter 39	0
394	#x39846988	<b>#</b> 96	Copolymer of ethylens and tetrafluoromthylans	θ
78bis	ex39859188	<b>#</b> 91	Copolymer of N-vinylcaprolaciam, N-vinyl-2-pyrrolidone and dimethylaminoethyl methacrylate	9
400	ex39059100 ex32082010	#92 #28	Copolymer of vinylpyrrolidone and dimethylaminoethyl methecrylate, partially quaternized by dimthyl sulphate, in the form of a solution in mthanol	θ
484	ex39059900	\$94	Polyvinyl acetate phthalate	θ
401	ex39859988	<b>#</b> 95	Polymer of vinylpyrrolidone and dimethylaminosthyl methacrylata, containing by wmight 97% or more but not more than 99% of vinylpyrrolidone, in the form of a solution in water	θ
482	8x39059980	\$96	Hexadecylated or aicosylated polyvinylpyrrolidone	θ
405	ex39061000	<b>#19</b>	Polymethyl methacrylate, in the form of expansible beads containing 2-methylpentane as blowing agent	θ
413	ex39869888	¥70	Polymerization product of acrylic acid with small quantities of a polyunsaturated monomer, for the manufacture of medicaments of heading No 3003 or 3004 (m)	θ
414	ax39869888	*80	Polymerization product of acrylic acid with small quantities of a polyunmaturated monomer, for usm as a stabilizer in emulsions or dispersions with a pH of more than 13 (m)	6
415	ex39072019	\$10	Poly(ethylene oxide)	θ
416	ex39872898	#15	Bis{2-[#-hydroxy-poly(ethyleneoxy)]ethyl} hydroxymethylphosphonmte	θ
417	ex39072090	\$20	Poly(oxypropylana) having alkoxysilyl and-groups	θ ,
418	e×39072090	≢40	Poly[oxy-1,4-phanylanaisopropylidana-1,4-phanylanaoxy-(2-hydrox ytrimethylana)], of an average molecular weight of more than 20000, in one of the forms mentioned in note 8(b) to Chapter	

	CN code	TARIC	Description	Rate of autonomous dut
419	sx39072090	*68	e-4-Hydroxybutyi-w-hydroxypoly(oxytetremethylene), containing less then img/kg of halogen and less then img/kg of matal, and of a colour not exceeding 20 units on the Hazen scale	θ
428	ex39872898	\$78	Hosopoly, w. of 1-chloro-2,3-epoxypropane (epichlorohydrin)	0
422	ex39073000	¥28	Epoxydm remin in the form of powder, containing by weight 44% or more but not more than 55% of quartz and 0,5% or more but not more than 1% of diantimony trioxide, for the conting of film capacitors (m)	θ
423	ax39079190	*10	Diallyl phthalata prepolymer, in the form of powder	θ
425	ex39079910 ex39079990	*10 *10	Poly(oxy-1,4-phenylenecarbonyl), in the form of powder	θ
427	ex39079910	*30	Liquid crystal copolyaster with a malting point of not less than 278°C, whether or not containing fillers	θ
428	mx39889889	*10	Poly(isinosethytene-1,3-phenylenesethylensisinosdipoyl), in one of the forms sentioned in note 8(b) to Chapter 39	8
429	ex39894888	¥10	Polycondensation product of phenol with formaldehyde, in the form of hollow mpherems of m dimmeter of less than 150 micrometrem	θ
430	ex39119010	\$28	Poly(oxy-1,4-phenylenesulfonyl-1,4-phenyleneoxy-4,4'-biphenylen e)	8
431	ex39119818	¥48	Polymer of dextrose, sorbitol and citric acid, containing by weight 98% or more of dextrose	θ
437	ex39119898	*85	Copolymer of dibutyl malasta and N-vinyl-2-pyrrolidone, in one of the forms mentioned in note 6 (a) of Chapter 39	θ
438	Ex39119090	*87	Copolymer of vinyltoluene and «-methylstyrene	θ
434	ex39119090 ex32089010	*91 *30	Copolymer of melaic acid and methyl vinyl ether, monoesterified with ethyl and/or isopropyl and/or butyl groups, in the form of a solution in ethanol, athanol and butanol, isopropanol or isopropanol and butanol	8
435	ex39119698	¥92	Mixed calcium and sodium salt of a copolymer of maleic acid and methyl vinyl ether, having a calcium content of 9% or more but not more than 16% by weight	0
436	ex39119090	<b>#</b> 93	Copolymer of maleic acid and methyl vinyl ether	θ
448	ex39121100	¥18	Non-plasticized cellulose triscetate, in the form of flakes, for the manufacture of cellulose triscetate yarn (a)	β
441	ex39123918	≥10	Ethylcellulose, not plasticized	θ
443	ex39123998	●10	Cetlulose, both hydroxyethylated and ethylated, insoluble in water	θ
445	Bx39123990	\$48	Cellulose, both hydroxyethylated and alkylated with alkyl chain-langths of 3 or more carbon atoms	θ
446	ex39139680	#30	Chondroitinsulphuric acid, sodium salt	θ
448	ex39173231	*92	Insulating tubing (heat-shrinkable tubing) of athylene polymers, whether or not internally coated or covered with a thermoplastic adhesive, for use in nuclear plants (a)	θ
449	Bx39173239	¥20	Pipe consisting of a block copolymer of polyletrafluoroethylene and polyperfluoroalkoxytrifluoroethylene, having a length of not more than 578mm, a dimester of not more than 58mm and a wall-thickness of not less than 38 and not more than 118 micrometers	θ
458	ex39199810	₹18	Sheped sheet of plastic, with an adhesive layer containing polyisobutylene and pactin, for the senufacture of colostomy bags (a)	8

	CN code	TARIC	Description	Rais of autonomous duty (%)
451	ex39199631 ex39266968	\$10 \$80	Reflecting laminated sheating, metallized, not conlaining glass balls or pyramidal patterns, consisting of one sheat of polyester and at least another sheat of polyester or other plastic material and costed on one side with an adhesive, whether or not protected by a release sheat, in rolls, each roll of a width of 158cm or more and a gross weight of 75kg or	
			nora	θ
452	sx39199631	\$48	Reflecting polyester sheeting embossed in a regular pyramidat	
	ex39206210	*40	pattern, for the manufacture of safety stickers and badges,	
	ex39206290 ex39206300	#20 #30	safety clothing and accessories thereof, or of school setchels, bags or similar containers (a)	
	8x39286988	*3 <del>0</del>		θ
453	ex39199861	\$92	Polyvinyl chloride sheeting, of a thickness of lass than iss.	
	ex39199869	*92	coated with an adhesive in which are esbedded glass balls of a diameter not exceeding 180 sicrosetres	θ
454	ex39199061 ex39199069	*93 *93	Adhesive film consisting of a base of a copolymer of ethylene and vinyl acetate (EVA) of a thickness of 120 micrometres or more and an adhesive part of acrylic type of a thickness of 10 micrometres or more, for the protection of the surface of silicon discs (s)	θ
457	ex39281822	<b>*</b> 95	Film of polymthylene, of a thickness of 28 micrometres or more but not exceeding 45 micrometres, containing calcium carbonate	
			in the mass, for the manufacture of mapkins for babies or of	
			sanitary towals or of tampons or of disposable surgical gowns	•
		<u> </u>	(a)	θ
458	ex39201022	*96	Film of a thickness not exceeding 8,20mm, of a blend of	
	ex39201080	<b>#</b> 95	polyethylene and a copolymer of ethylene with oct-1-ene, embossed in a regular rhomboidel pattern, for coating both sides	
			of a layer of unvulcanized rubbar (a)	θ
459	ex39201040	<b>*</b> 91	Synthatic paper pulp, in the form of moist sheats, made from unconnected finaly-branched polymthylene fibrils, whether or not blended with cellulose fibres in a quantity not exceeding 15%, containing polyvinyl alcohol dissolved in water as the moistening agent	θ
		<u>+</u>		
456	ex39201040	<b>₽</b> 92	Laminated sheet or strip consisting of a film composed of a blend of a copolymer of sthylene with vinyl acetate and a modified athylene-propylene-slastomer (EPM) or a modified athylene-propylene-diene elastomer (EPDM), costed or covered on both sides with a film of a copolymer of sthylene with vinyl acetate	6
				-
468	ex39202090	<b>₽</b> 91	Synthetic paper pulp, in the form of moist sheets, made from unconnected finely-branched polypropylene fibrils, whether or not blended with cellulose fibres in a quantity not exceeding 15%, containing polyvinyl alcohol dissolved in water as the moistening agent	θ
461	ex39203000	<b>≢</b> 28	Laminated sheet or strip, consisting of a film of a thickness	
401	£¥39203000	•20	of 188 micrometres or sorip, consisting of a fite of a internesties, composed of a blend of a thermoplastic alastomer (TPE) of styreme-butadiane-styreme (888) with polyethyleme or polypropyleme, costed or covered on both sides with a film of polypropyleme of a thickness not exceeding 28 micrometres	θ
462	ex39204211	<b>*</b> 92	Reflecting sheeting, consisting solely of a single layer of	
102	Bx39204291	*92 *92	polyvinyl chlorida, wholly exbossed on one side in a regular pyramidal pattern	θ
463	Ex39204291	<b>#93</b>	Sheeting of polyvinyl chloride, stabilized against ultraviolet rays, without any holes, even microacopic, of a thickness of 60 micrometres or more but not exceeding 80 micrometres, containing 30 or more but not more than 40 parts of plasticizar to 100 parts of polyvinyl chloride	θ
464	вx39204291	\$94	Polyvinyl chloride sheet, with relief printing, for the	
101	8833209231	*24	rolyvingt chloride sneet, with relief printing, for the senufacture of templates for textile printing (a)	8

	CN code	TARIC	Description	Rate of autonomous duty (%)
465	ex39285188	#10	Polymothyl methacrylate plats, with an antistatic costing, of dimensions of 738x972mm (±1,5mm)	θ
467	ex39206100	*19	Polycerbonele file of a thickness not exceeding 15 micrometres, for the menufacture of file cepecitors (m)	9
471	ex39286218	*10	Polyathylana taraphthalata fila, of a thickness of less than 11 sicromatres, for the manufacture of audiodigital tapes for cassettes (a)	θ
473	ex39286218	\$28	Polysthylens terephislate film, not costed with an adhesive, of a thickness not exceeding 25 micrometres, mither: - only dyed in the mass, or - dyed in the mass and metallized on one mide	θ
475	#x39206218	#45	Film of polysthylane terephthalate only, of a total thickness not exceeding 128 microsetram, consisting of one or two layers each containing a colouring and/or UV-absorbing material throughout the mass, uncosted with an adhesive or any other exterial	θ
476	ex39206210	¥58	Polysthylens terephthalsts fils, of a thickness of 28 micrometres or more but not exceeding 38 micrometres, comted on one mide with milicone, for use in the manufacture of window film (m)	5.6
477	e×39206218	+55	Leminated film of polyethylene terephthelate only, of a total thickness not exceeding 120 micrometres, consisting of one layer which is metallised only and one or two layers each containing a colouring and/or UV-absorbing material throughout the mass, uncoated with an adhesive or any other material	θ
478	e×39206210	¥80	Film of polyethylene terephthelate, comted or covered on one mide or on both mides with a layer of modified polyester, of a total thickness of 7 micrometres or more but not exceeding 11 micrometres, for the manufacture of video tapes with a magnetic layer of metallic pigments and a width of 8mm or of 12,7mm (m)	θ
479	ex39206210	#65	8ingle ply file of polysthylene terephthalate only, of a thickness not exceeding 120 micrometres, which only: - contains a colouring and/or UV-absorbing material throughout the mass and - is metallized on one side, whether or not comted on one or both sides with a vinyl acrylate polymer but having no other comting or adhesive	θ
468	ex39286218	\$78	File of polyethylene terephthelete, of a total thickness not exceeding 120 micrometres, of a width of 100mm or more but not exceeding 115mm, costed on both sides with one or more layers containing different chemicals, for the manufacture of goods of subheading 37012000 (m)	θ
469	ex39206210	¥75	Film of polyethylene terephthelete, on one side metallized and costed with whitm ink and a protective layer and on the other mide costed with a thermomensitive seal layer, of a width of 199mm or more but not exceeding 150mm, for the menufacture of goods of subheading 37812800 (s)	θ
470	ex39206210	<b>*89</b>	Film of polysthylans tarephthelets, costed on one side with a layer of modified polyaster, of a thickness of 20 micrometres (±0,7 micrometre) or of 30 micrometres (±0,9 micrometre), for the menufacture of mudio magnetic tapes of a total thickness of 33 micrometres or more (m)	8
480	ex39206900	#48	Iridescent fils of polysster and polyssthyl sethacrylate	θ
481	ex39286988	¥50	Polycondensation product of terephthalic acid with a mixture of cyclohex-1,4-ylenedisethanol and ethane-1,2-diol, in the form of a film	θ
482	ex39206900	¥60	Film of a copolymer of sthylene terephthalste and sthylene isophthalate, of a thickness not exceeding 2 micrometres	θ

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	CN code	TARIC	Description	Rata of autonomous duty (X)
483	ex39289188	<b>#</b> 91	Polyvinyl butyral film having a graduated coloured band	6
484	■x39269188	¥92	Plasticized fils of polyvinyl butyrsl, containing by weight: - sither 14,5% or more but not more than 17,5% of dihexyl adipate - or 14,5% or more but not more than 28,5% of dibutyl	-
			sebecele	0
489	•x39209950	¥24	Film entirely of polyvingl alcohol, of a thickness not exceeding 1mm and containing by weight: - 2% or less of unhydrolysed acetate groups evaluated as vingl acetate and - 5% or more but not more than 25% of glycerol as plasticizer,	
			for the manufacture of roof-windows (m)	θ
498	ax39289958	\$26	Poly(1-chlorotrifluoromthylmnm) film	9
491	ex39209950	¥27	Film of a mixturm of polyvinglidene fluoride with an acrylic polymer, of a thickness of 40 micrometres or more but not exceeding 60 micrometres	8
492	ax39289958	*28	Film and sheat of a copolymer of sthylens with chlorotrifluorosthylens, of a thickness of 12 micrometres or more but not exceeding 400 micrometres	θ
493	ex39289958	#36	Film entirely of polyvinyl alcohol, of a thickness not axceeding 1mm and of a width of 2,20m or more, with an extension at break, in the transverse direction, of 350% or more	θ
494	ax39209950	<b>*</b> 37	Biaxially-oriented film of polyvinyl alcohol, coated on both sides, of a total thickness of less than 1mm	θ
495	ex39289958	<b>*</b> 38	Iridescent film of polyester, polyethylene and an ' ethylene-vingl acetate copolymer	0
496	ax39209950	¥39	Polytetrafluoroethylene film, non-microporous, in the form of rolls, of a thickness of 0,019mm or more but not exceeding 0,14mm, impermeable to water vapour	θ
498	ex39211998	<b>#</b> 91	Microporous polypropylene file of a thickness not exceeding 30 micrometres	θ
497	ex39211990	<b>#</b> 92	Microporous film consisting of mixtures of cellulose acelate and cellulose nitrate, of a thickness not exceeding 200 micrometres	8
499	ex39219019	¥35	Composite plate of polycarbonate and polybutylene terephthalate, reinforced with glass fibres	θ
500	ex39219019	#45	Composite plate of polysthylene terephthalate or of polybutylene terephthalate, reinforced with glass fibres	8
501	ex39219019	¥50	Multilayer film of a thickness not exceeding 150 micrometers, consisting of a polyaster film coated on one side with polycarbonate remin, metallized on the other side with titanium coated with polycarbonate remin and other layers containing N,N'-diphenyl-N,N'-di-m-tolylbiphenyl-4,4'-ylenediam ine	θ
582	ex39269691	¥28	Reflecting sheating or tape, consisting of a facing-strip of polyvinyt chloride embossed in a regular pyramidal pattern, heat-sealed in peratlel lines or in a grid-pattern to a backing-strip of plastic material, or of knitted or woven fabric covered on one side with plastic material	θ
503	ax48881188	¥10	Blocks or sheels of cellular vulcanised rubber of modified ethylans-propylane-diana (EPDM) blanded with chloroprene, which satisfy the Underwriters Laboratories Flammability Standard UL94WF-1	8

	CN code	TARIC	Description	Rate of autonomous duty (%)
504	Ex40169988	+19	Boft rubbar sealing stoppers for the senufacture of electrolytic capacitors (s)	8
505	41051191 41051199 41051210 41051210 41051290 41051910		Sheep or lash skin lasther, without wool on, tanned or retanned but not further prepared, whether or not split, other than leather of heading No 4108 or 4109	
	41051990			θ
506	41061190 41061200 41061900		Goat or kid skin lesther, without hair on, tanned or retanned but not further prepared, whether or not split, other than leather of heading No 4188 or 4189	θ
507	41071018 41072918 41079018		Lesther of other eniaels, without heir on, not further prepared then tenned, other then lesther of heading No 4188 or 4189	θ
508	ex44160890	*10	Used casks and barrals of osk, whether assambled or not; their staves and heads	θ
509	45011000		Natural cork, raw or simply prepared	θ
510	ex48856898	#18	Overlay paper, of a width of more than 205cm and containing by weight more than 5% of corundum	θ
511	ex48112100	*18	Impregnated paper conted or covered with a pressure-sensitive self-adhesive imper, the whole: - of a tensile of 2700M/m or more but not exceeding 3700M/m in the machine direction (as determined by the DIN 53112 method), - of a stratch factor of 1,5% or more but not exceeding 3,0% in the machine direction (as determined by the DIN 53112 method) and	
			- of adhesivity on stainless steel (as determined by the DIN 30646 method) of SON/m or more but not exceeding 225N/m, at a temperature of 23°C (±3°C) and a relative humidity of SOX (±5%)	θ
512	ex48113900	#10	Kraft paper impregnated with an acrylic polymer with a nominal weight of 85g/m <sup>2</sup>	θ
513	ex48239898	#12	Strips of paper glued to one enother to form a honeycomb of a height not exceeding 13cm, for agricultural purposes (a)	8
514	ex49119900	¥18	Polyester film, partially costed with a magnetic metal layer showing a regular repeating logo or motif, for the manufacture of security threads (m)	θ
515	58828888		Rew silk (not thrown)	θ .
516	ex50040010 ex50040090	\$10 \$10	Varn spun entirely from silk, not put up for retail sale	2.5
517	ex50050010 ex50050090	#10 #10	Y <mark>ern spun entirely from silk waste (n</mark> oil), not put up for retail <b>sale</b>	θ
519	ex54023310 ex54023390	≇10 ≉10	Textured yarn of polyester, single or two ply, measuring per single yern 120 decilex and consisting of 36 filaments or measuring per single yern 167 decitex and consisting of 48 filaments each having a random variation of diameter along its length	9
520	ex54023390	¥28	Textured yern of polyester, measuring per single yern 167 decitex and consisting of 60 filements or measuring per single yern 334 decitex and consisting of 78 filements, having filements both of polyethylene terephthalate and of a polyethylene terephthalate which has been chemically modified to allow it to be dymable with cationic dyestuffs	θ
521	ex54023910	*18	Texturized yern of polypropylene, impregnated with	

	CN code	TARIC	Description	Rate of sutonomous duty (%)
522	ex54824118	\$18	Polyamida yern, not textured, untwisted or with a twist not exceeding 22 turns per metre, of crimpable bicomponent filaments consisting of poly(hexamethylene adipamide) with a copolyamide, for the menufacture of: - knew-length stockings of subheadings 61152011 and 61159330, - women's stockings of subheadings 61152019 and 61159391	
			or - panty home (tights) of subheeding 61151188	
			(.)	•
.,				θ
523	ex54024130 ex54024190	*19 *10	Varn of synthatic taxtile fibres solaly of aroastic polyamides obtained by the polycondensation of s-phanylanadiamine and isophthalic acid	0
524	ex54024310	\$10	Single yern of polyester, measuring 55 decitex and consisting of 36 filements or measuring 83 decitex and consisting of 48 filements, the filements having different thermal contraction factors	θ
525	ex54824999	<b>#10</b>	Yern of polytetrefluoroethylene	· · · · · · · · · · · · · · · · · · ·
	sx54026990	\$28		θ
526	ex54824999	#38	Vern of a copolymer of glycollic acid with lactic acid, for the manufacture of surgical sutures (a)	9
527	ax54824999	≇50 ≇28	Non-textured filement yarn of polyvinyl alcohol	
	вх54025990 вх54026990	*20 *40		θ
528	ex54024999 ex54026990	#60 #10	Yarn wholly of polyglycollic acid	θ
529	ex54024999	ŧ70	Synthatic filament yern, single, containing by weight 85% or more of acrylonitrile, in the form of a wick containing 1000 continuous filaments or more but not more than 25000 continuous filaments, of a weight per metre of 0,12g or more but not exceeding 3,75g and of a length of 100m or more, for the manufacture of carbon-fibre yarn (a)	θ
536	в×54824999	<b>\$88</b>	Polyethylene filement yarn, untwisted, of either 55, 118, 165 or 1768 decitex, for the manufacture of goods of heading No5687 (a)	θ
531	Ex54024999	\$85	Synthetic filsment yarn, single, untwisted, wholly of poly(thio-1,4-phenylene)	0
532	Bx54841898	¥10	Monofilament of polytetrafluoroethylene	θ
533	ex54041090	\$28	Monofilament of poly(1,4-dioxanone)	θ
534	ex54041090	<b>\$</b> 30	Monofilement of a copolymer of 1,3-dioxan-2-one with 1,4-dioxan-2,5-dione, for the manufacture of surgical sutures (m)	8
535	sx54049090	<b>≇</b> 10	Strip of polyletrafluoroethylene, with an extension at break not exceeding 25%	θ
536	ax54077100	¥10	Voven fabrics of polyvinyl ∎lcohol fibres, for ∎achine ⇔sbroidery	θ
537	ex54077100 ex59030099	€28 €18	Woven polytetrafluoroethylene-fibre fabric, costed or covered on one side with a copolymer of tetrafluoroethylene and trifluoroethylene having perfluorinated alkoxy side-chains anding in carboxylic-acid or sulphonic-acid groups in the potassium- or sodium-salt form, whether or not costed on the same side with a metallic inorganic compound	8
538	ex55039010 ex55039090	#10 #30	Ac. 2 = 28d, multicomponent spun fibres with a matrix fibril structure, consisting of emulsion-polymerized polyvinyl alcohol and polyvinyl chloride	θ ,
	ex55039898	<b>\$</b> 10	Textile fibres of polyletrafluoroethylene	8

	CN code	TARIC	Description	Rate of autonomous duty (X
540	ex55039898	\$28	Polyvinyl alcohol fibres, whether or not acetalized	
240	ex56013000	\$10		θ
541	sx55039890	¥40	Fibres wholly of poly(this-1,4-phanylane)	8
542	ex55849888	*10	Cellulose fibre produced by organic solvent spinning (Lyocell)	4
543	ex56031110	\$18	Polyvinyl alcohol nonwovens, in the piece or cut into	
	ex56031190	¥10	rectangles:	
	ex56031218	*10	- of a thickness of 200 micrometres or more but not exceeding	
	ex56031290	*10	288 aicroastres	
	ax56039110	\$18	and	
	ex56039190	¥10	- of a weight of 20g/m <sup>2</sup> or more but not exceeding	
	ex56039210	<b>#10</b>	50g/∎²	
	ex56839298	\$18		. θ
544	ax56831298	#30 #20	Nonwovens of arosstic polysside fibres obtained by	
	ex56031390 ex56031490	*30 *10	polycondensation of s-phanylanadisains and isophthalic acid, in the piece or cut into rectangles	θ
545	ex56039290	\$28	Non-wovens consisting of a selt-blown central layer of a	
	ax56039390	#28	thersoplastic electorer teminated on each side with spunbonded	
			fibres of polypropylene	θ
546	ex56039290	¥48	Nonwovens of polypropylene consisting of a melt-blown central	· · · · · · · · · · · · · · · · · · ·
	ex56839398	¥10	layer, laminated on each side with spun-bonded fibres, of a	
			thickness not exceeding 550 sicrosetres and of a weight not	
			exceeding 88g/m <sup>2</sup> , in the piece or simply cut into	
			rectangular shape, not impregnated	θ
551	ax56039490	¥28	Acrylic fibre rods, having a length of not more than 50cm, for the manufacture of pen tips (m)	θ
547	ex59031090	<b>≢18</b>	Knitled or woven febrics, costed or covered on one side with	
	ex59032090	*10	artificial plastic material in which are embedded microspheres	
	ex59839899	\$28	A A A A A A A A A A A A A A A A A A A	8
	FY99039093	•20		Ū
548	ex59878898	¥10	Textile fabrics, coaled with adhesive in which are embedded	
			spheres of a diameter not exceeding 75 sicrometres, of a weight	
			not exceeding 558g/m <sup>2</sup>	θ
549	ex59111888	\$18	Neadle-punched synthetic-fibre felts on a woven synthetic-fibre	······································
-	-		base not containing polyester, costed or covered on one side	
			with polyistrafluorosthylens film, for the manufacture of	
			filtration products (a)	θ
	F0140000		· · · · · · · · · · · · · · · · · · ·	
228	ex59119898	<b>#18</b>	Yarn and strip of impregnated polytetrafluorosthylene, whether or not oiled or graphited	θ
				v
552	63051010		Sacks and bags, of a kind used for the packing of goods, used,	•
			of jute or of other textile best fibres of heading No 5303	θ
553	ex63059008	<b>#10</b>	Sacks and bags, of a kind used for the packing of goods, used,	
	ex63059000	≢91	of flax or of sisal	
	ex63059000	<b>#</b> 93		θ
554	ex68159998	#10	Nicrospheres:	· · · · · · · · · · · · · · · · · · ·
			- of a diameter of less than 100 micrometres,	
			- of a refractive index of 2,1 or more but not exceeding 2,4	
			and	
			- containing by waight more than 90% of barium and titanium	
			evaluated as barium oxide and titanium dioxide	θ
555	8×69032090	<b>1</b> 8	Yern of continuous ceremic filements, each filement containing	
			by weight:	
			- 12% or morm of diboron trioxidm,	
			- 26% or less of silicon dioxide	
			and - 68% or more of dimluminium trioxide	θ
		, , , , ,		-
556	ax69039080	≢19 • ( 0	Beryllium oxide, of a purity by weight of more than 99%, in	β
	ex69891988	\$40	the form of blanks, bars, blocks or plates	0
557	ex69091200	<b>≇</b> 28	Plate, of dialuminium trioxide and titanium carbide, of	
001				
557			dimensions not axceeding 48x48ss, or of a disseter not exceeding 125ss, for the manufacture of magnetic heads (a)	θ

	CN code	TARIC	Description	Rate of autonomous duty (%)
558	ax59091908	*30	Supports for catalysts, consisting of porous cordiarits or mullite caramic pieces, of an oversll volume not exceeding 651, having, per cm <sup>2</sup> of the cross-section, not less than one continuous channel which may be open at both ends or stopped at one and	θ
559	ax78868898	*10	Glass plate, coated on one side with chromium and/or with a mixture of diindium trioxide and tin dioxide, of dimensions of 328x352mm or more but not exceeding 328x488mm, and of a thickness of 1,1mm (±8,1mm), with a flatness deviation not exceeding 25 micrometres, for the manufacture of liquid crystal displays with active matrix (m)	8
560	ex76888898	¥20	Colour filter, consisting of a glass plate with red, blue and green pixels, having a total thickness of 1,1mm (±0,1mm) and exterior dimensions of 320x352mm or more but not exceeding 320x400mm, for the manufacture of liquid crystal displays with active matrix (m)	8
561	ax76888888	*38	Glass plate, uncostad, of dimensions of 328x352mm or more but not exceeding 328x408mm, and of a thickness of 1,1mm (±8,1mm), with a flatness deviation not exceeding 25 micrometres, for the manufacture of liquid crystal displays with active matrix (a)	θ
562	ex70111090	<b>\$18</b>	Glass lenses with a stippled front refractor or with a front refractor composed of prismatic elements, with an external diameter of more than 121mm but not exceeding 125mm	θ.
583	ex70111090	¥28	Perabolic glass reflectors, with an external diameter of more than 121mm but not exceeding 125mm	θ
564	ex70112808	*18	Glass envelopes for monochrome cathode-ray tubes: - of a diagonal screen-measurement of 3,8cm or more but not exceeding 51cm and	
	·····		- of a nominal mack-dismeter of 13mm, 20mm, 29mm or 37mm	θ
	ex70112000 ex70112000	*48 *58	<ul> <li>Glass face-plate:</li> <li>with a diagonal measurement of 366,4mm (±1,5mm) and of dimensions of 246,4x315,4mm (±1,5mm),</li> <li>with a diagonal measurement of 391mm (±1,5mm) and of dimensions of 261,4x326,8mm (±1,5mm),</li> <li>with a diagonal measurement of 442mm (±1,5mm) and of dimensions of 261,4x326,8mm (±1,5mm),</li> <li>with a diagonal measurement of 442mm (±1,5mm) and of dimensions of 293,4x369,2mm (±1,5mm),</li> <li>with a diagonal measurement of 513,5mm (±1,6mm) and of dimensions of 341,8x440,5mm (±1,6mm),</li> <li>with a diagonal measurement of 544,5mm (±1,6mm) and of dimensions of 358x454mm (±1,6mm),</li> <li>with a diagonal measurement of 549,8mm (±3mm) and of dimensions of 486,5x519mm (±2mm),</li> <li>with a diagonal measurement of 839,3mm (±3mm) and of dimensions of 413,6x527mm (±2mm),</li> <li>with a diagonal measurement of 838,2mm (±1,5mm) and of dimensions of 548,9x895,6mm (±1,5mm),</li> <li>and with a raised adge, for the manufacture of colour cathode-ray tubes (a)</li> </ul>	θ
200	8x70112000	*20	(±1,5mm) and of dimensions of 387,1x628,8mm (±1,5mm)	6
567	ex70112000	•88	<ul> <li>Glass cone:</li> <li>with a diagonal measurement of 365,0mm (±1,5mm) and of dimensions of 243,2x312,8mm (±1,5mm),</li> <li>with a diagonal measurement of 389,6mm (±1,5mm) and of dimensions of 258,5x324,5mm (±1,5mm) or</li> <li>with a diagonal measurement of 439,9mm (±1,5mm) and of dimensions of 290x366,6mm (±1,5mm)</li> </ul>	θ
568	ex70191910	¥10	Varn of 33 tex or a multiple thermof, ±7,5%, obtained from continuous spun-glass filaments of a nominal diameter of 3,5 micrometres or of 4,5 micrometres, in which filaments of a diameter of 3 micrometres or more but not exceeding 5,2	

	CN code	TARIC	Description	Rate of autonomous duty (%)
569	ex70191918	\$38	Vern of 22 tex ±7,5%, obtained from continuous spun-glass filements of a nominal dismeter of 5 micrometres, in which filements of a dismeter of 4,2 micrometres or more but not exceeding 5,8 micrometres predominate	θ
570	ex70191910	¥40	Vern of 33, 34 or 51 tex or a suttiple thermof, ±7,5%, obtained from continuous spun-glass filements of a nominal dismeter of 8 micrometres, in which filements of a dismeter of 5,1 micrometres or more but not exceeding 8,9 micrometres predominate	θ
572	sx70193200	¥18	Non-woven product of non-textile glass fibre, for the	
	ex78193918 ex78193998	≢10 ≢10	sanufacture of sir-filters or of sir-filtration products (a)	8
573	ex70199010	*11	Non-textile glass fibres in which fibres of a dissalar of lass than 3,5 sicrometres predominate	8
574	ex71841888	¥18	Piszo-electric quertz, not set or sounted, in the form of non-doped slices of synthetic e-quertz monocrystel	0
575	71861888	¥19	Silver, in the form of powder	θ
576	ex71162090	#18	Disc of silicon on sapphire	θ
76bis	72825888		Farro-silico-chrosius	 -θ
	······································			
577	72029300		Ferroniobium	θ
77bis	ex72829919	¥28	Ferro-phosphorus, containing by weight 15% or more of phosphorus, for the manufacture of refined phosphoric iron or steel (m)	θ
578	ex72851888	*10	Magnetisable iron alloy, in the form of granules, containing by weight: - 88% or more but not more than 91% of iron and - 4% or less of cobmit	θ
579	ex73063029	*91	Non-alloy steel precision tube, welded and cold finished, of an external diameter exceeding 160mm and a wall thickness exceeding 2mm	θ
581	ex74102100	*10	Sheet or plate of polytetrafluoroethylene, with eluminium oxide or titanium dioxide as a filler or reinforced with glass-fibre fabric, leminated on both sides with copper foil, or sheet of polyimide, leminated on one side or on both sides with copper foil	θ
582	76828819		Waste of sluminium, other (including factory rejects)	θ
584	ex76169990	≇40	Discs of eluminium elloy, costed or covered on both sides with a nickel-phosphorus leyer, having a total thickness not exceeding 3,82mm	8
585	ex79050000	<b>#</b> 10	Plate of an alloy of zinc, ground and polished on one surface and coated with an apoxide resin on the other surface, of rectangular or square shape, of a length of 300am or more but not exceeding 2000am and of a width of 300am or more but not exceeding 1000am, and containing: - 10ag/kg or less of iron, - 10ag/kg or less of iron, - 700ag/kg or more but not more than 900ag/kg of aluminium and - 500mg/kg or more but not more than 900ag/kg of megnesium,	
			for the manufacture of mensitised printing plates (a)	θ
586	ex81019900	₹10	Disc (target) with deposition material, of tungsten or an alloy containing by weight 98% of tungsten and 18% of titanium, - containing 188microgramms/kg or lass of modium and - mounted on m copper support,	
			for use in the menufecture of goods of heeding No8542 by sputtering (s)	θ

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	CN code	TARIC	Description	Rate of mutonomous duty (%)
587	ax81839898	*10	Welded tube solely of tantalum, or solely of an alloy of tantalum with tungsten containing by weight 2,5% or less of tungsten	θ
875is	ex81841188	*30	Unwrought asgnesius, of a purity by weight of 99,95% or more, in the form of ingots	θ
588	nx81049000	*10	Ground and polished magnesium sheats, of dimensions not exceeding 1500x2000mm, costed on one side with an apoxy resin insensitive to light	θ
589	ex81081010	\$18	Titanium sponge	θ.
590	81681690		Weste end screp of titenium	θ
591	ex\$1989898	*92	Disc (target) with deposition meterial, of titanium, - containing 50micrograms/kg or lass of sodium and - mounted on a copper support, for use in the menufacture of goods of heading No8542 by	
			sputtering (a)	θ
	ex81100011	*10	Antimony in the form of ingots	θ
593	ex81110011	\$10	Electrolytic mangamese of a purity by weight of 99,7% or more	θ
594	ex81121118 ex81121998	*10 *10	Beryllium, of a purity by weight of 94% or more, in the form of blocks or bars, plates and sheets	θ
595	ex81129930	¥10	Alloy of niobium (columbium) and titanium, in the form of bars and rods	8
596	82024000		Chain saw blades	1.7
597	ex84189930	*91	Velded cooling micro-elements, of an alloy of aluminium, for the menufacture of condensers (a)	θ
598	ex84198995	¥10	Immersion-lube (coils) bundles, consisting of an assembly of plastic tubes terminating at each end in a honeycomb-structure (and-fitting) surrounded by a pipe-connector	θ
599	ex84219988	¥91	Parts of equipment, for the purification of water by reverse osmosis, consisting of a bundle of hollow fibres of artificial plastic material with permeable walls, embedded in a block of artificial plastic material at one end and passing through a block of artificial plastic material at the other end, whether or not housed in a cylinder	8
660	sx84219960 sx59119698	≇92 ≢30	Parts of squipsent for the purification of water by reverse osmosis, consisting assentially of plastic-based membranes, supported internally by woven or non-woven textile materials which are wound round a perforated tube, and exclosed in a cylindrical plastic casing of a wall-thickness not exceeding 4mm, whether or not housed in a cylinder of a wall-thickness of Sam or more	θ
691	ex84219988	\$93	Components of separators for the separation or purification of gases from gas mixtures, consisting of a bundle of permeable hollow fibres enclosed within a container, whether or not perforated, of an overall length of 300mm or more but not exceeding 3700mm and a dismater not exceeding 500mm	9
682	ax84219988	•95	Parts of equipment for the filtration of magnetic dispersions, consisting essentially of nylon-6 fibres, enclosed in a plastic casing of a dismeter of 70mm (±2mm) and a length of 520mm (±5mm)	0
683	ex84399910 ex84399990	*19 *18	Suction-roll shalls, not drilled, in the form of alloy-steel tubes, of a langth of 5287mm or more and an external dismater of 754mm or more, for use in machinary for making paper or paperboard (a)	θ
684	ex84559888	<b>*</b> 10	Helical turn device for cold-rolling mill	θ

	CN code	TARIC	Description	Rete of autonomous duty ()
2	ex84716898	*10	Input unit (so-called "touchpad"), the exterior dimensions of which do not exceed 50 x 62 mm, capable of matrix scanning and detection, consisting of 2 layers of measurement electrodes, a printed circuit, a capacitive matrix, 2 integrated circuits, discrete components and a connector, for use in the manufacture of products falling within heading 8471 (a)	9
3	ax84716090	¥28	Pointing device (so-called "trackball"), consisting of printed circuit on which are mounted an optical encoder in the form of a monolithic integrated circuit and a housing comprising a ball and a ratminer ring, for use in the manufacture of products falling within subheading 84713000 (a)	8
4	ex84717851	<b>≇10</b>	Drive-unit for rewriteble optical phase change dis <u>k</u> s	8
5	ex84717851	\$20	Drive-unit for segneto-optical dis <u>k</u> s	θ
6	ex84717851 ex85219888	₹38 ₹91	Drive-unit, comprising a printed circuit on which are mounted integrated circuits providing drive and signal processing functions for reading optical CD-ROM discs, not capable of recording	8
11	ex84717053	\$10	<u>Hard disk drive</u> , capable of perallel data-transfer vis 1, 4, 5 or 6 channels at, respectively, a rate per second of 3,014 aegabytes, 12,05 aegabytes, 15,07 aegabytes or 18,08 aegabytes, comprising 8 magnetic disks of the 8 inch type with a total storage capacity, unformatted, not exceeding 1000,2 magabytes and incorporating s storage=module=drive_interface, for use in the manufacture of cardiodisgnostic apparatus (s)	8
12	ex84717053	¥20	<u>Hard disk drive</u> of the 8 inch type, capable of parallel data-transfer via 1 channel at a rate per second of 3,041 segabytes, comprising a storage-module-drive_interface and 11 magnetic disks with a total storage capacity, unforsatted, not exceeding 2,5 gigabytes, for use in the manufacture of products falling within subheading <u>84714990 or 84715090</u> (e)	θ
13	ex84717053	¥30	<u>Hard disk drive</u> of the 5,25 inch type, capable of external data-transfer at a rate per second of 7,5 megabytes, having dual channels for simultenessoualy reading and writing with 2 magnetic heads, comprising a dual port interface circuit and 11 magnetic disks with a total storage capacity, unformatted, of 1986 megabytes, for use in the manufacture of products falling within subheading <u>90221400</u> (a)	8
10	ex84717053	¥50	Hard disk drive of the 5,25 inch type, capable of external data-transfer at a rate per second of 10 aegabytes or more but not exceeding 40 megabytes, comprising 14 megnetic disks with a total storage capacity, formatted, of 21 gigabytes or more but not exceeding 26 gigabytes <u>, for use in the senufacture of mass</u> storage systems (a)	θ
15	ex84717859	¥10	Floppy-dis <u>k</u> storage units	θ
16	ex84717060	<b>#10</b>	Twin real drive-unit of the 8 mm cartridge type, for use in the manufacture of magnetic tape storage units (m)	θ
17	ex84717060	₹28	Driva-unit, incorporating a recording drum, for use in the menufacture of digital audio tape storage units (m)	8
18	Ex84717868	<b>#</b> 30	Magnetic tape storage unit for_certridges	θ
19	Bx84719888	*18	Optical reader for reading alphanumeric dol-matrix printing characters and converting them into electrical signals, comprising a read head containing an optical detector, an emplifier, a focusing lans and two leaps, linked by one or two flat cables to a central module the dimensions of which do not exceed 200 x 220 mm, comprising a printed circuit board on which are mounted a sicroprocessor, an image recognition circuit and an analogue-to-digital converter	9
32	ex84733018	¥15	Processor, consisting of: - 15 monolithic integrated circuits, comprising an marithmetic-logic unit (ALU) of 32 bits, a halfword marithmetic-logic unit (ALU), a halfword multiplier, a floating point unit, a fixed point unit, a storage control unit, a storage interface circuit and 18 static random-access memories (S-RAMs) with a total storage capacity of 5760 Kbits, - decoupling capacitors and cooling plates,	

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CN code	TARIC	Description	Rais of sutonosous duty (%)
		the whole mounted on a multilayer caramic substrate the exterior dimensions of which do not exceed 65 x 65 mm, with not more than 824 connections and bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		1867559 1867820	
x		or .	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
20 •x84733010	¥16	Processor, consisting of: - <u>4 or</u> 8 monolithic integrated circuits, comprising <u>1 or</u> 2 central processing units (CPUs) each with a static rendem-access cache memory (8-Cache-RAM) with a storage capacity of 128 Kbits, <u>1 or</u> 2 floating/fixed point units and <u>2 or</u> 4 static rendem-access cache memories (8-Cache-RAMs) with a total storage capacity of <u>1.5 or</u> 3 Mbits, - decoupling capacitors, the whole mounted on a multilayer ceramic substrate the exterior dimensions of which do not exceed 65 x 65 mm, with not more then 736 connections and bearing: - an identification marking conmisting of or including (one of) <u>the following combination(m)</u> :	
		48H9588 48H9582	
		10	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	0
33 ex84733010	¥28	Processor of BCL technology, consisting of not more than 336 monolithic integrated circuits, each comprising not more than 15000 programmable logic arrays, mounted on one or both sides of a multiple printed circuit, contained in a housing attached to a cooling plate or enclosed between two cooling plates, the overall exterior dimensions of which do not exceed 148 x 560 x 594 am and bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		001B-3035-H002 52-203619 52-203621	
		or - other identification markings relating to devices complying with the abovementioned description	θ
34 ex84733818	¥25	<pre>with the abovementioned description Processor, consisting of: - 12 monolithic integrated circuits, comprising 2 central processing units (CPUs) with an integer/floating point unit, 2 cache controllers, memory management and tag units (CMTUs) and 8 static random-access memories (S-RAMs) with a total storage capacity of 4 Mbits, - decoupling capacitors and cooling plates,</pre>	•
		the whole mounted on a multilayer caramic substrate the exterior dimensions of which do not exceed 84 x 147 mm, with not more than 100 connections and bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(m):	
		RT 6626K RT 6236K	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
35 ex84733010	<b>#38</b>	Component forming the erithmetic/logic mlement of a central processing unit (CPU), comprising not more than 9 printed circuit boards, the dimensions of which do not exceed 298 x 310 mm, on each of which are mounted not more than 121 ECL gate arrays or ECL random access memories (ECL-RAMms) and combinations thereof, contained in a framework the dimensions of which do not exceed 501 x 508 x 611 mm which serves as a housing and interconnector for the printed circuit boards, and bearing: - an identification marking consisting of or including (one of)	·,

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			Description	Rate of autonomous duty (X)
			the following combination(s):	
•			CO1B 2675 E 500 CO1B 2675 H 501 CO1B 2675 H 503 CO1B 2675 H 500 CO1B 2675 H 502 CO1B 2675 H 504	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8 .
36	ex84733010	¥35	Processing system, consisting of: - not more than 121 wonolithic integrated circuits not contained in a housing (chips), - a ceremic substrate, the whole enclosed between a metallic beseplate and a metallic plate incorporating not more than 121 cooling pistons filled with liquid	θ
38	ex84733818	¥58	Assembly for disc storage units of Winchester technology, comprising a 2- or 4-channet read/write monolithic integrated circuit for magnetic head signals mounted with discrete components on a flaxible printed circuit	8
39	ex84733818	¥55	Flash electrically arasable, programmable, rand only memory (Flash-E <sup>2</sup> PROM), consisting of 2 monolithic integrated circuits contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			28 F 032SA	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
28	Ex84733018	¥65	Nicroprocessor, in the form of a monolithic integrated circuit contained in a housing on which are mounted at teast one of the following components: - a decoupling capacitor, - a ventilator with a cooling element, - a control circuit, in the form of a monolithic integrated circuit	θ
41	ex84733010	<b>₹</b> 78	Microprocessor of C-NOS technology, with a processing capacity of 32 bits, coosprising a bus controllar and a semory controllar, in the form of a monolithic integrated circuit, contained in a housing the exterior dimensions of which do not exceed 48 x 48 mm, and with decoupling capacitors, and bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			390 Z 50	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
29	ex84733010	₹75	Microprocessor module, only consisting of 7 monolithic integrated circuits consisting of: - a microprocessor unit associated with a cache memory with a storage capacity of 64 Kbits, - a floating point unit, - a microprocessor interface unit, - 4 memory control units associated with 4 cache memories with a total storage capacity of 2 Mbits the whole contained in a housing with decoupling capacitors	8
30	ex84733618	*88	Microprocessor with a processing capacity of 32 bits, only consisting of 2 monolithic integrated circuits contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			80521EX	
			00021EA 0F	
			· · ·	

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bis	ex84733010 ex84733090 ex84733090 ex84733090	*85 *03 *55	<pre>with the abovementioned description Microprocessor module comprising 8 monolithic integrated circuits conmisting of: - a fixed point unit, - a floating point unit, - an instruction cache memory unit, - a memory control unit, - 4 data cache memories, the whole contained in a housing with decoupling capacitors Parts and accessories excepted the following products: - data storage memobiles (Head/Disc/Assemblies, - thin file megnetic heads Data storage memobiles (Head/Disc/Assembly) for herd_disk_ drives, with a data transfer rate per second of 3,9 or 4,2 megabytes, comprising read/write heads and 9 or 11 magnetic discs with an axternal dismeter not exceeding 24,2 cm (9,5 inch) with a total storage capacity, formatted, of 2838 or 8514 megabytes, the whole incorporated in a single hermatically</pre>	θ θ θ
bis	ex84733898 ex84733898	<b>#83</b>	circuits consisting of: - a fixed point unit, - a floating point unit, - a floating point unit, - a memory control unit, - 4 data cache memories, the whole contained in a housing with decoupling capacitors Parts and accessories excepted the following products: - data storage memobiles (Head/Disc/Assemblies, - thin file megnetic heads Data storage memobiles (Head/Disc/Assembly) for herd_disk <u>drives</u> , with a data transfer rate per second of 3,9 or 4,2 megabytes, comprising read/write heads and 9 or 11 megnetic discs with an axternal dismeter not exceeding 24,2 cm (9,5 inch) with a total storage capacity, formatted, of 2838 or 8514 megabytes, the whole incorporated in a single hermatically	
	ex84733898		<ul> <li>4 data cache semories, the whole contained in a housing with decoupling capacitors</li> <li>Parts and accessories excepted the following products: <ul> <li>data storage assemblies (Head/Disc/Assemblies,</li> <li>thin file segnatic heads</li> </ul> </li> <li>Data storage assembly (Head/Disk/Assembly) for herd_disk drives, with a data transfer rate per second of 3,9 or 4,2 segabytes, comprising read/write heads and 9 or 11 segnetic discs with an axternal dismeter not exceeding 24,2 cm (9,5 inch) with a total storage capacity, formatted, of 2838 or 8514 megabytes, the whole incorporated in a single hermatically</li> </ul>	
	ex84733898		- data storage assemblies (Head/Disc/Assemblies, - thin file megnetic heads Data storage assembly (Head/Disk/Assembly) for herd disk <u>drives</u> , with a data transfer rate per second of 3,9 or 4,2 megabytes, comprising read/write heads and 9 or 11 megnetic discs with an axternal dismeter not exceeding 24,2 cm (9,5 inch) with a total storage capacity, forestted, of 2838 or 8514 megabytes, the whole incorporated in a single hermatically	θ
54 (		*55	drives, with a data transfer rate per second of 3,9 or 4,2 megabytes, comprising read/write heads and 9 or 11 magnetic discs with an external disseter not exceeding 24,2 cm (9,5 inch) with a total storage copacity, forestted, of 2838 or 8514 megabytes, the whole incorporated in a single hermatically	
	ex84733898		sealed housing	θ
55 a		¥69	Data storage assembly (Head/Disk/Assembly) for hard_disk drives of the 9 inch type, with a data transfer rate per second of 2,77 aegebytes, comprising read/write heads and 7 aegnetic discs with a total storage capacity, formatted, of 1216 or 1506 megebytes, operating with a supply voltage of 128 V and of 228 V or more but not exceeding 240 V, the whole incorporated in a single hermatically sould housing	8
57 e	ex84733090	*78	Deta storage assembly (Head/Disc/Assembly) for <u>hard</u> disk <u>drives</u> of the 10,8 inch type, with a data transfer rate per second of 3,9 magabytes, comprising 16 read/write heads and 9 magnetic discs with a total storage capacity, formatted, of 17 gigabytes, the whole incorporated in a single hermetically sealed housing	θ
60 e	ex84734090	*18	Thermal printer heads of thick- or thin-film technology, consisting of a printed circuit with at least one capacitor contained in a metal support with connector, printer element and heat sink, supplied with the appropriate support and transport roll	θ
61 e	₽x84734090	<b>\$</b> 85	Thereal printer head of thin-file technology, the exterior dimensions of which do not exceed 18 x 90 x 275 mm, consisting of: - a printed circuit on a ceramic substrate fitted with monolithic integrated circuits and 2880 heater elements, - a printed circuit fitted with monolithic integrated circuits, capacitors, resistors and connectors, - a thereistor and - 1 or 2 cooling plates	θ
62 e	ex84831890	¥10	Integrally forged and roughly shaped generator and turbine shafts of a weight exceeding 215 tonnes	θ
65 e	ex85011099	#54	DC motor, brumhlass, with an external diameter not exceeding 25,4 mm, m rated speed of 2260 (±15 %) or 5420 (±15 %) rpm, a supply voltage of 1,5 or 3 V	θ
67 e	ex85011099	¥59	DC stepping motor, with an angle of step of 1,8" (±0,09"), a holding torque of 0,156 Nm or more, a coupling flange the exterior dimensions of which do not exceed 43 x 43 mm, a chuck of a dimenter of 4 mm (±0,1 mm), a two-phase winding and an output not exceeding 5 W	θ
72 e	ax85011099	<b>*</b> 73	DC motor, whether or not mounted on a baseplate, for use in the manufacture of products falling within subheading 84717853 (a)	θ
75 e	ex85011099	<b>*</b> 77	DC motor, with brushes, with a typical running torque of 0,004 Nm (±0,001 Nm), with a coupling flange of a diameter of 32 mm (±0,5 mm) and a chuck of a diameter of 2 mm (±0,004 mm), with an internal rotor, a threa-phase winding, a rated speed of 2800	

	CN code	TARIC	Description	Rate of autonomous duty (%)
72bis	ex85011099	#78	DC motor, <u>whether or not mounted on a baseplate,</u> for use in the manufacture of <u>products falling within subheading</u> 85279891 (a)	8
76	ex85024090	*10	<u>Rotary converter</u> , with a ferrite core, having coils with 2 or 6 windings and a disaster of 0,1 mm, connected to a flexible printed circuit	8
77	ax85030899	#31	Stemped collector of a <u>n</u> electric motor, having an external diameter not exceeding 18 mm	8
58bis	ex85841891	*10	<u>Single desegnetization coil with not sore than 96 windings,</u> with cables and connectors	8
78	■x85044899	¥10	Direct current to direct current converter, with an input voltage range of 100 V or more but not exceeding 390 V, contained in a housing	8
79	sx85045090	¥10	Inductor with a variable inductance not exceeding 62 mH	θ
80	ax85045090	¥28	Multileyer monolithic inductors, contained in a housing of the SMD (Surface mounted device) type the exterior dimensions of which do not exceed 1.8 x 3.4 mm, for use in the manufacture of <u>products falling within subheading 85171100.</u> 85252891 or 85279891 (m)	θ
81	85049011		Ferrite cores	θ
82	ex85051180	#31	Ferrite magnet having a remanance of 455 mT (±15 mT)	θ
83	ex85059010	<b>#</b> 91	Solenoid with a plunger, operating at a nominal supply voltage of 24 V at a nominal DC of 0,08 A, for use in the manufacture of products falling within heading No 8517 (a)	θ
85	ex85065090	¥20	Unit consisting of not more than 2 lithium batteries embedded in a socket for integrated circuits (battery-buffered socket), with not more than 32 connections and incorporating a control circuit	θ
93	ex85073091 ex85078091	≇20 ≇10	Rectangular accumulator, with a length not exceeding 67,1 mm, a width not exceeding 18 mm and a thickness not exceeding 18,6 mm, for use in the manufacture of rechargeable batteries <u>of</u> portable phones (a)	θ
106	■x85169000	*31	Dual diode, consisting of a power rectifying diode connected with a transformer protector diode through a wire, <u>with a peak</u> <u>revers power rate of 2 J or more,</u> for use in the manufacturm of products falling within subheading 85165000 (a)	θ
107	ex85175090 <u>ex85178090</u>	≇1θ <u>≇3θ</u>	Transmitter, capable of converting electrical signals into light pulses, operating at a nominal wavelength of 820 nm, comprising a light-mmitting diode (LED), contained in a <u>plastic</u> housing with 8 connections and bearing: - an identification marking consisting of or including (one of) the following combination(s): <u>HFBR 1412</u> <u>HFBR 1414</u>	
			or - other identification markings relating to devices complying with the abovementioned description	θ
108	ex85175090 ex85178090	≇28 <u>≢48</u>	Receive unit, capable of converting light pulses into electrical signals, operating at a nominal wavelength of 820 nm, comprising a photodiode <u>and</u> an amplifier, contained in a <u>plastic</u> housing with 8 connections and bearing: - an identification marking conmisting of or including (one of) the following combination(s):	
			HFBR 2412 HFBR 2414 HFBR 2416	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8

	CN code	TARIC	Description	Rate of autonomous duty (%)
	ex85175090 ex85178090	<b>830</b> <u>810</u>	Transmitter, capable of converting electrical signals into Light pulses, operating at a nominal wavelength of 850 nm, comprising a light-maitting diode (LED), a current switch, an input buffer and a distortion/componention circuit, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			DH-231-TA	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
	ex85175090 ex85178090	\$40 <u>\$28</u>	Paceive unit, capable of converting light pulses into alactrical signals, operating at a nominal wavelength of 850 nm, comprising a photodiode, 2 decision circuits, an amplifier and an integrator, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			DN-231-RA	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
113	ex85179011	≇01	Modulator/demodulator of C-NO8 technology (C-NO8-Nodem), for full duplex data-transfer at a rate of 28880 bits per second and for half duplex transfer of image telegraphy (facsimile) at a rate of 14400 bits per second, consisting of 2 or more monolithic integrated circuits, at least one of which for digital signal processing (D8P) and an other for analogue functions, mounted on a printed circuit, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			RC 192DP RC 248DP RC 288DP RC 192DPL RC 246DPL 2C 288DP <u>L</u>	
			or	· · ·
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
14 1	ex85179011	¥02	Modulator/demodulator of C-MOB technology (C-MOB-Modem), only for half duplex transfer of data or image telegraphy (facsimile) at a rate not exceeding 2400 bits per second, only consisting of 2 monolithic integrated circuits, one of which for digital mignal processing (DBP) and the other for analogue functions, mounted on a printed circuit, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			RC 24BKJ	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
115	ex85179011	<b>€03</b>	Modulator/demodulator of C-M08 technology (C-M08-Nodem), for full duplex data-transfer at a rate not exceeding <u>9600</u> bits per second, only consisting of 2 monolithic integrated circuits, one of which for digital mignal processing (DSP) and the other for enalogue functions, mounted on a printed circuit, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(m):	
			RC 2324DPL	
			or	
			<ul> <li>other/identification markings relating to devices complying with the abovementioned description</li> </ul>	θ

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	CN code	TARIC	Description	Rate of sutonomous duty
116	■x85179011	₹84	Nodulator/demodulator of C-M08 technology (C-M08-Modem), only for half duplex transfer of image telegraphy (faceimile) at a rate not exceeding 9600 bits per second, only consisting of 2 monolithic integrated circuits, one of which for digital signal processing (DSP) and the other for analogue functions, mounted on a pri sed circuit, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			R 96DFX R 96EFX R 96MFX	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
117	ex85179811	*85	Modulator/demodulator of C-M08 technology (C-M08-Modem), for full duplex data-transfer at a rate not exceeding 14400 bits per second and for helf duplex transfer of image telegraphy (facsimile) at a rate not exceeding 14400 bits per second, only consisting of 2 or 3 monotithic integrated circuits, 1 or 2 of which for digital mignal processing (DSP) and an other for analogue functions, mounted on a printed circuit, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			RC 144ACF RC 144DPI RC 9624 RC 96V24	
			<u>RC 144AFT</u> RC 9323 <u>RC 96DPL</u>	
			or - other identification markings relating to devices complying with the abovementioned description	θ
111	ex85179011	¥86	Modulator/demodulator of C-MOS technology (C-MOS-Modem), for half duplex transfer of image telegraphy (faceimile) at a rate not exceeding 9600 bits per second, comprising a compression/decompression circuit for voice mignals, only consisting of 2 monolithic integrated circuits, one of which for digital mignal processing (DSP) and the other for analogue functions, mounted on more printed circuit, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			RFX 96V12	
			0 r	
	2 		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
118	ex85179082	¥19	Assembly for telephonic apparatus comprising a microphone, a protecting circuit and a four-way connecting socket, mounted on a printed circuit the dimensions of which do not exceed 22 x 40 mm	θ.
119	∎x85179082	¥28	16 x 16- or 32 x 32-bit differential crosspoint switch of gallium mrsenide (GaAs) maniconductor material, capable of switching at a data rate per second of at least 800 Mbits, in the form of a monolithic integrated circuit contained in m housing combined with decoupling capacitors, the whole mounted on a substrate the exterior dimensions of which do not exceed 35 x 35 mm, with not more than 196 connections and bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			TQ 8816 TQ 8832	
			or	
			- other identification markings relating to devices complying	

	CN code	TARIC	Description	Rate of autonomous duty (%)
120	ex85179082	¥30	Assembly consisting of a laser diode operating at a nominal wavelength of 780 nm, a photodiode and a lens, contained in a housing with a diameter of not more than 9 mm and a height of not more than 20 mm, with not more than 3 connections and bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			FU-8118LD-W2 LW-7115	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
122	ex85179882	¥50	Assembly comprising light-mmitting diodes (LEDs)	θ
123	ex85179088	¥18	Asseably consisting of a laser dieds operating at a nominal wavelength of 980 mm, a photodieds, a thermistor and a cooling plate, contained in a housing with an optical fibre cable connection and bearing: - an identification marking consisting of or including (one of) the following combination(s): QLM98478	
			or	
			<ul> <li>other identification serkings relating to devices complying with the abovementioned description</li> </ul>	θ
124	ex85179888	\$20	Parts, for use in the menufacture of products falling within subheading 85172100 (m)	θ
126	Ex85182998	¥10	Loudspeaker having a power of 5 W and an impedance of 4 ohm, with a diameter not exceed <u>ing</u> 50 mm, for use in the menufacture of portable phones (m)	θ
127	ex85183090	<b>\$</b> 10	Headphone and earphone for hearing sids, contained in a housing the exterior disensions of which, excluding connecting points, do not exceed 5 x 6 x 8 ss	θ
128	ex85189000	<b>\$</b> 91	Integrally cold-upsetted steal cormplate, in the form of a disc on one side provided with a cylinder, for use in the manufacture of loudspeakers (a)	θ
129	ex85229091	¥91	Optical unit consisting of a laser diode with one photodiode, emitting light of a nominal wavelength of 780 nm, contained in a housing with a dimmeter of not more than 10 mm and a height of not more than 9 mm, with not more than 10 connections and bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			LDGU LT 022	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
130	ex85229691	∎92	Electronic assembly for a laser read-head of a compact disc player, comprising: - a flaxible printed circuit, - a photo-detector, in the form of a monolithic integrated circuit, contained in a housing, - not sore than 2 connectors, - not sore than 1 transistor, - not sore than 3 variable and 4 fixed resistors, - not sore than 5 capacitors, the whole mounted on a support	θ
131	ex85229098	*31	Thin-file recording and reproducing device, having at least 9 parallel channels for digital signals and at least 2 channels for analogue signals, to which a non-asgnetic cereatic substrate is fixed, the whole rounded at one side, for use in the manufacture of asgnetic heads for digital sound recording and digital/analogue sound reproducing apparatus of the	
			cassette-type (a)	θ

	CN code	TARIC	Description	Raie of autono∎ous duiy (
132	ex85229698	*32	Sound reproducing assembly, consisting of a compact disc mechanism, comprising an optical reading system and 3 DC motors, for use in the manufacture of products falling within subheading 85272178 (m)	9
133	ex85229898	*33	Assembly consisting of a driver circuit, a tacho-mensor and a brushlass DC motor, with a typical running torque of 0,0044 Na (±0,001 Nm), a shaft of a dimension of 3,523 mm (±0,002 mm), an external rotor of a dimension of 69 mm (±0,3 mm), a three-phase winding, a rated speed of 2600 (±16 %) rpm and a supply voltage of 14 V (±18 %)	θ
134	■x85229898	\$34	Cassette-deck sub-assembly for sound recording and reproducing apparatus, for use in the senufacture of telephone answering machines (s)	θ
135	■x85229898	\$35	Sound reproducing assesbly, comprising a tape deck mechanism of the cammette type, comprising a DC motor, for use in the manufacture of products falling within hemding 8519 (m)	θ
136	ax85229898	*36	Roll for magnetic tape guiding and winding, for use in the manufacture of products falling within heading No 8521 or 8522 (m)	8
137	ex85229898	*37	Magnetic head for erasing video tapes, for use in the manufacture of products falling within heading No 8521 or 8522 (a)	θ
138	ex85229898	ŧ38	Read-head assembly, comprising a laser read-head, 2 motors, a flexible printed circuit, the whole mounted on a plastic support, for use in the manufacture of <u>products falling within</u> subheading 85199912 or 85199918 (a)	θ
139	ex85231200	¥10	Magnetic tape, with a thickness not exceeding 18 µm and a width of 8,2?4 (±8,013 mm), on reets, not mounted in a cartridge	9
140	ex85232019	¥40	Rigid magnetic discs, prelubricated, oxide type, with a coercivity of 300 Os or more, not mounted in a cartridge	0
144	ex85282208	¥10	<ul> <li>Video monitor comprising:</li> <li>a flat screen monochrome cathode-ray tube with a diagonal measurement of the screen not exceeding 110 mm and equipped with a deflector yoke, and</li> <li>a printed circuit on which are mounted a deflection unit, a video-amplifier and a transformer,</li> <li>the whole mounted on a chassis, for the menufacture of video entry-phones, video telephones or surveillance apparatus (a)</li> </ul>	θ
152	ex85291070	<b>\$</b> 10	Ceramic filter package comprising 2 ceramic filters and 1 ceramic resonator for a frequency of 10,7 MHz (±30 kHz), contained in a housing	8
146	sx85291979	¥15	Cersmic filter for a centre frequency of 10,7 MHz, with a bandwidth not axceeding 330 kHz at 3 dB and not exceeding 950 kHz at 20 dB, contained in a housing	θ
153	∎x85291078	¥20	Cers∎ic filters for frequencies of 4,5 MHz or ∎ore but not exceeding 6,6 MHz contained in a housing	θ
147	ex85291070	₿25	Cersmic filter for a centra frequency of 450 kHz or more but not axceeding 470 kHz, with a bandwidth not exceeding 13 kHz at 3 dB, contained in a housing	θ
154	ex85291070	¥30	Cersmic filter for a frequency of 450 kHz, with a bandwidth not exceeding 18 kHz at 10 dB, contained in a housing	θ
155	æx85291078	<b>*4</b> 0	Radio frequency (RF) signal isolator for frequencies of 948 MHz or more but not exceeding 1453 GHz, having an insertion loss not exceeding 0,7 dB, contained in a housing	θ
157	Bx85291878	¥75	Bandpass filter, excluding surface acoustic wave filters, for a centre fraquency of 485 or 1212 MHz, with an insertion loss not exceeding 3 dB, contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	

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	CN code	TARIC	Description	Rete of eutonomous duty (X)
			<ul> <li>other identification markings ratating to devices complying with the abovementioned description</li> </ul>	θ.
158	#x85299681	#31	<u>Dual d</u> esagnetisation coil with not sore than 96 windings, with cables and connectors	θ
159	ex85299881	*32	Assembly comprising a lens unit, having a focal langth of 3,6 ma, an interline charge-coupled image sensor having 291000 photomensitive calls, and integrated circuits, the whole mounted on a printed circuit	θ
160	ex85299681	¥34	Assembly conmisting of a lens unit, having an adjustable focal langth of 5 mm or more but not exceeding 89 mm and comprising a zoom encoder, a stepping motor unit, a zoom motor unit, an iris motor unit and a photo interrupter	8
161	ex85299081	₿35	Video recording and reproducing asseably, comprising a tape deck mechanism of the cassatte type, comprising a DC motor, for use in the manufacture of products falling within heading 8525 (m)	8
162	ex85299881	¥36	Assembly consisting of a monochrone cathode-rmy tube with a diagonal measurement of the screen of 185 mm or more but not exceeding 230 mm and a conceve focus lens mounted on a liquid-filled cooling armature, for use in the manufacture of television projection equipment (m)	θ
163	ex85299081 ex85299089	≇37 ≇31	Filter, consisting of 2 piezo-electric crystals each with a frequency of 21 MHz or more but not exceeding 30 MHz and seperately mounted on a bracket, with not more than 7 connections	θ
165	ex85312030	<b>*</b> 10	Dot matrix display consisting of a line of 8 characters, mach character composed of 35 light-maitting diodem (LEDs), comprising electronic components for interface and drive functions, contained in a housing the exterior dimensions of which do not exceed 20 x 43 mm, with not more than 28 connections and bearing: - an identification marking consisting of or including (one of) the following combination(m):	
			HDSP 2107 HDSP 2112 PD8P 2110 PDSP 2112 HDSP 2111 HDSP 2113 PDSP 2111 PDSP 2113 or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
166	ex85312030	<b>\$</b> 20	Digital displays, consisting of a printed circuit board of a size not exceeding 35 x 90 am with a single line of characters, not less than 3 in number, comprising light-emitting diodes (LEDs) made from gallium-based semiconductor materials mounted thermon. Each character is composed of up to 8 segments with or without a decimal point and the line of characters has a protective cover of plastic	θ
167	ex85312051	\$10	Liquid crystal colour display (LCD) with an active matrix and 480 x 640 or 600 x 800 pixels, consisting of a layer of liquid crystals between two glass sheets or plates, comprising electronic components providing drive and/or control functions, for use in the manufacture of products falling within subheading 84713000 (m)	θ
168	ex85312851	≇20	Liquid crystal colour display (LCD) with an active matrix and 768 x 1824 or 988 x 1152 pixels, consisting of a layer of liquid crystals between two glass sheats or plates, comprising electronic components providing drive and/or control functions	θ
169	ex85312851	≢30	Liquid crystal colour display (LCD) with an active matrix and 1824 x 1288 pixels, consisting of a layer of liquid crystals between two glass sheets or plates, mounted on a printed circuit comprising electronic components providing drive	

	CN code	TARIC	Description	Rate of autonomous duty (%)
170	ex85312859	€2 <b>0</b>	Liquid crystal monochrome display (LCD) with an active matrix and 900 x 1152 pixals, consisting of a layer of liquid crystals between two glass shaets or plates, comprising electronic components providing drive and/or control functions	θ
171	ex85312080	¥10	Liquid crystal display (LCD) with a passive matrix, comprising alactronic components providing drive mnd/or control functions	θ
172	ax85318898	*18	Direct current plassa display	θ
173	ex85318898	¥20	Transducer, capable of producing a sound level of 85 <u>or 87 dB</u> at a frequency of 2700 or 3200 Hz	θ
174	ex85318898	*38	Vacuum fluoremeent display, consisting of a memory refresh circuit, a character generator, a DC/DC converter and electronic components providing drive and/or control functions	θ
2655	ax853188998	*40	Indicator lamp, consisting of 2 light-smitting diodes wade from aluminium-gallium-aramnic (AlGaAs) or gallium-phosphor ( <u>GaP)</u> semiconductor material, having a rectangular base, contained in a housing of the SMD (Surface mounted device) type and having a lens	θ
984	∎×85318090 ±×85425000	*50 *06	Indicator lamp, consisting of 4 light-mmilting diodes made from silicon-carbid (SiC) semiconductor material, operating at a nominal wavelength of 481, 560 or 630 nm, contained in a housing	θ
175	ex85319018	<b>●</b> 91	Backlight unit, comprising a lampholder with a cathode tube, a reflaction wheet and a diffuse substrate, the exterior dimensions of which do not exceed 7 x 230 x 300 mm, for use in the manufacture of liquid crystal displays (LCD) (a)	θ
177	B×85322200	*95	Aluminium electrolytic capacitors, with a fixed nominal capacity not exceeding 478 µF and an operating voltage not exceeding 50 V, operating within a temperature range of ~40°C to +85°C, having m dimmeter not exceeding 8 mm and a <u>heigth</u> not exceeding <u>6</u> mm	θ
178	ex85322288	<b>\$</b> 96	Aluminium eletrolytic capacitors, with a fixed nominal capacity of 2,2 µF and an operating voltage of 385 V, operating within a temperature range of -48°C to +85°C	θ
179	ex85322200	<b>#</b> 97	Aluminium eletrolytic capacitor, with a fixed nominal capacity not exceeding 3,3 F and an nominal operating voltage of 2,5 or 5,5 V, operating within a temperature range of -25°C to +85°C	θ
176	в×85322200	¥98	Atuminium electrolytic capacitors, with a nominal capacity of 0,1 µF or more but not exceeding 1000 µF and an operating voltage of 4 V or more but not exceeding 50 V, operating within a temperature range of -40°C to +105°C, contained in a housing of the BMD (Surface mounted device) type	θ
189	ex85322300	<b>₩</b> 91	One layer ceremic dielectric capacitor, with a fixed nominal capacity of 1 pF or more but not exceeding 1 µF and an nominal operating voltage not exceeding 50 V, operating within a temperature range of -25°C to +85°C	θ
181	Bx85322499	#31	Multilayer cersmic dielectric capacitor, contained in a housing of the SMD (Surface mounted device) type the exterior dimensions of which do not exceed 0,55 x 0,55 x 1,05 mm	θ
183	ex85322900	*31	Capacitor with 2 dialectric meterials, one in ceramic, the other in apoxy remin, having an initial capacitance of 500 pF (±30 %) and a dismipation factor not exceeding 2,5 %	θ
184	BX85329888	<b>*</b> 32	Anode or cathode, for use in the asnufacture of slusinius electrolytic capacitors (s)	θ
185	ex85331000	<b>#92</b>	Fixed carbon composition resistor, with an operating voltage not exceeding 358 V and a dissipation rate not exceeding 8,5 V	θ
186	ex85332100	*31	Fixed thick file resistor, with a resistance of 18 Ohm or more but not exceeding 2,2 NOhm, a dissipation rate not exceeding 0,063 W, contained in a housing of the SMD (Surface mounted device) type the exterior dimensions of which do not exceed 0,4 x 0,55 x 1,85 mm	θ

	CN code	TARIC	Description	Rate of autonomous duty (X)
187	ex85340011 ex85340019	*91 *91	Single-face printed circuit the dimensions of which do not exceed 30 x 30 mm, for the menufacture of products falling within Chapter 81 <u>(a)</u>	8
188	ex85340011	<b>*</b> 92	Multiple printed circuit, consisting of 24 layers, including 5 layers with buried vias of bismeleimide triazine, the exterior dimensions of which do not exceed 64 x 85 cm	θ
189	ex85348811	<b>\$9</b> 3	Multiple printed circuit, with connectors, and in an aluminium casing	θ
198	ex85340019	<b>*</b> 92	Single-face printed circuits, each with not more than 268 conductive leads, on a plastic tape with sprocket holes on both edges and having a width of not more than 48 mm and a thickness of not more than 8,26 mm	θ
191	ax85340019	ŧ94	Printed circuit, consisting of 29 or 31 conductor elements fixed on a flexible plastic film, for use in the manufacture of magnetic heads for digital sound recording and digital/analogue sound reproducing apparatus of the cassatte-type (a)	θ
192	ax85340019	¥95	Printed circuit, consisting of conductor elements fixed on a flexible plastic film, with a trace width of 0,005 mm or more but not exceeding 3,5 mm and a trace pitch of 0,005 mm or more but not exceeding 0,305 mm, for use in the manufacture of electronic calculating machines (a)	θ
193	ex85340019	¥96	Printed circuit on an aluminium oxide support, only with gold plated conductor alements of thick film technology, for use in the manufacture of products falling within mubheading 85424858 (a)	θ
194	ex85340090	¥93	Printed circuit on one or both sides of a carasic substrate, consisting of conductor elements, contacts and resistors, incorporating connections isolated in vitrified layers, the dimensions of which do not exceed 45 x 45 mm, with not more than 550 connections	θ
195	Ex85364110 Ex85364198 Ex85364988	*91 *91 *91	Thermal relays contained in a hermetically sealed glass cartridge not exceeding 35 mm in length excluding wires, with a maximum leakage rate of 10 <sup>-8</sup> cm <sup>3</sup> Hermac at one bar in the temperature range 0 to 160°C, to be incorporated into compressors for refrigerating equipment <u>(a)</u>	θ
198	ex85365011	#31	Switch of the printed circuit mount type, operating at a force of 4,9 N (±0,9 N), contained in a housing	θ
199	Ex85365898	<b>1</b> 93	Switch unit for coaxial cable, comprising 3 mlectromagnetic switches, with a switching time not exceeding 50 ms and an actuating current not exceeding 500 mA at a voltage of 12 V	θ
288	€x85365890	194	Airbag sensor, capable of maintaining a multching current of 28 A after 3 make/break at a voltage of 26 V, with an insulation resistance of 108 Mohm or more at a continuous voltage of 500 V and a contact closed resistance not exceeding 150 mohm at a current of 2 A ( $\pm$ 8,5 A) for a period of 2 mm ( $\pm$ 1 mm), contained in a housing the exterior dimensions of which do not exceed 17 x 22 x 32 mm	θ
201	Bx85369085	\$91	Etastomeric connectors, consisting of conductor mlaments comted $\times$ )th gold and fixed on a substrate of rubbar	θ.
282	ex85369085	\$\$2	Hatallic stamped frame with connections	8
284	ex85365096	¥91	Part of an electrothermal fuse, consisting of a tin costed copper wire attached to a cylindrical casing, the exterior dimensions of which do not exceed 5 x 48 mm	θ
205	ex85401111	<b>\$</b> 91	Color cathode-ray tube with a slot mask, equipped with stactron guns placed side by side (in-line technology) and with a diagonal measurement of the screen of 12 cm or more but not exceeding 26 cm	θ
206	ex85401113	<b>*</b> 91	Colour cathode-ray tube with a slit mask, having a distance between stripes of the same colour of less than 0,42 mm and a diagonal measurement of the screen of 49 cm, for use in the manufacture of professional video monitors including security and medical monitor applications (m)	θ

	CN code	TARIC	Description	Rate of autonomous duty
207	ex85461191	#31	Colour cathode-ray tube with a screan width/height ratio of 16/9 and a diagonal assurament of the screan of 39,8 cm (±0,3 cm)	θ
289	ex85401288	*81	Flat screen monochrome cathode-ray tube with a diagonal measurement of the screen of 100 mm or more but not exceeding 155 mm and an anode voltage of 5 kV or more but not exceeding 32 kV	θ
210	ex85401200	*82	Monochrome cathods-ray tube with a diagonal assaurement of the acraem of 250 am or more but not exceeding 320 am and an anode voltage of 18 kV or more but not exceeding 22 kV	θ
288	ex85481288	\$83	Monochrome cathode-ray tube, with a diagonal measurement of the screen of 150 mm or more but not exceeding 182 mm, a neck diamater of less than 30 mm and an anode voltage of 25 kV or more but not exceeding 32 kV	θ
211	в×85402090	*91	Photomultiplier consisting of a photocsthode tube with 9 dynodes, for light of a wavelength of 160 nm or more but not exceeding 930 nm, of a dismeter not exceeding 14 mm and a height not exceeding 94 mm	θ
212	ex85404000 ex85406000	#31 #31	Colour cathode-ray tube with a dot mask, equipped with 3 electron guns placed side by side (in-line technology) or 1 gun with 3 rays, with a diagonal measurment of the screen of more than 72 cm and a distance of less than 0,5 mm between dots of the same colour	θ
213	ex85404000 ex85406000	*32 <u>*32</u>	Colour cathods-ray tube with a dot mask, equipped with 3 electron guns placed side by side (in-line technology) or 1 gun with 3 rays, having a diagonal measurement of the screen not exceeding 72 cm	θ
214	ex85404000	*33	Colour calhoda-ray tube with a slit mask, having a distance between stripes of the same colour of less than 0,35 mm and a diagonal measurement of the acrean not exceeding 53 cm	θ
215	e x 8 5 4 0 4 0 0 0	*34	Colour cathoda-ray tube with a slit mask, having a distance between stripes of the same colour of less than 0,39 mm and a diagonal measurement of the screen of 33 cm or more but not exceeding 38 cm	θ
216	ex85465600 ex8546600	#31 <u>#33</u>	Flat screen monochroms cathods-ray tube, with a diagonal measurement of the screen of 142 as or more but not exceeding 190 mm, a luminescence of 300 lumen or more but not exceeding 2000 lumen, a resolution of 0,06 as or more but not exceeding 0,1 mm, phosphor types P1 or P22 or P53 or P55 or P56, an anode voltage of more than 34 kV, a focus voltage of more than 7 kV and a cathode current of 3 mA or more	θ
217	ex85485888 ex85486888	#32 #34	Monochrone cathoda-ray tube with a diagonal measurement of the screen of <u>178</u> we or more but not exceeding <u>528</u> we <u>and a</u> <u>neck diameter not exceeding 21 mm</u>	θ
218	ex85468911	*91	Displays in the form of a tube consisting of a glass housing mounted on a board the dimensions of which do not exceed 300 x 350 am excluding leads. The tube contains one or more rows of characters or lines mranged in rows, each character or line consisting of fluorescent or phosphorescent elements. These meaners are mounted on a metallised base which is covered with fluorescent substances or phosphorescent salts which give off light when bombarded with electrons	θ
219	ex85469188	*91	Deflector yoke for cethode-ray tubes with an operating frequency of 31258 Hz or sore but not exceeding 64000 Hz, incorporating a quedripolar asgnet	8
228	e×85469100	192	Blit mask, consisting of vertical slits with a distance between slits of 8,74 mm (±8,12 mm) and a diagonal dimension of either 61,5 cm (±8,5 cm) or 71 cm (±8,5 cm) or 79,5 cm (±8,5 cm)	θ
221	ex85409100	<b>#</b> 93	Electron gun for the production of monochrome cathode-ray tubes with a diagonal measurement of the acreen of 7,6 cm or more but not exceeding 38,5 cm <u>(a)</u>	8

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	CN code	TARIC	Description	Rate of autonomous duty (X)
222	ex85469188	•94	Deflector yoke for colour cathode-ray tubes, with an operating frequency of 15625 or 31258 Hz, comprising two 2-pole ring magnets, two 4-pole ring magnets and two 8-pole ring magnets	θ
223	ex85489188	*96	Assembly for cathods-ray tubes with 2 or more but not more than 6 coils, a platic support and a metal fixing ring, for the adjustment of display sharpness and/or convergence	θ
224	ax85469166	*98	Frame of molybdenum chrome staml, for use in the manufacture of cathode-ray tubes (m)	0
225	ax85489988	•91	Anods, cathods or output part, or an assembly comprising these components (magnetron core tube), for the manufacture of magnetrons of subheading <u>85487188 (m)</u>	0
229	ex85411891	*18	Silicon power reclifier diodes of planer lechnology, with a recovery line of less than 100 ns, a maximum recurring reverse vollage of 200 V, and average forward current of 2,5 A or more, contained in a housing	0
230	ex85411891	¥28	Silicon power rectifier diode, with a reverse pask voltage not exceeding 1500 V and an average output current of 5 A or more but not exceeding 8 A, contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			PG151515	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	0 <sub>.</sub>
231	ex85411091	#38	Zener diode for overvoltage suppression, having a voltage of 24 V or more but not exceeding 38 V and with a dissipation rate of 5 W, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			2101DE	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
232	ex85411891	*48	Voltage rectifier diode, with a reverse peak voltage of 6, 8, 10, 12 or 14 kV, an average forward current of 5 mA and a reverse current of 2 µA, contained in a housing	. 0
227	ex85411091	≇50	Power rectifier diode, with a reverse peak voltage not exceeding 66 V and a forward current not exceeding <u>3,2</u> A, contained in a housing bearing: - an identification <u>warking consisting of or including (one of)</u> the following combination(s):	
			21D086 <u>EC280S86</u>	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
236	ax85411899	¥30	Current regulative diode, providing a stabilized current laval not exceeding 18 mA at a voltage of 18 V	θ
237	ax85411899	€49	Diode, with a forward current not exceeding 1 A, a resistance not exceeding 1,5 Oha, a total capacitance not exceeding 0,3 pF and a braakdown voltage of 200 V or more	θ
238	ex85412190	¥10	High electron mobility transistor (HEMT), for fraquencies of 2 GHz or more but not exceeding 20 GHz, with a dissipation rate not exceeding 180 mW, contained in a housing with a disester not	. ,

	CN code	TARIC	Description	Rate of autonomous duty (X
239	ex85412198	€28	Field-effect transistor (FET) for frequencies of 2 GHz or more but not exceeding 18 GHz, with a dissipation rate not exceeding 225 mW, contained in a housing with a disseter not exceeding 3 mm, with not more than 4 connections	θ
248	ex85412910	¥10	Wafar, not yet cut into chips, consisting of field-affect transistors (FETs) of the P-channel typs, having a drain-to-source breakdown-voltage of -30 V or more, operating with a continuous drain-current not exceeding 10 A, a drain-to-source resistance not exceeding 0,2 ohs, and with a dissipation rate not exceeding 60 W, for use in the sanufacture of goods of subheading \$5424898 (s)	θ
242	8x85412928	¥18	Field-effect transistor (FET), for frequencies of 2 GHz or more but not exceeding 10 GHz, with a dissipation rate not exceeding 8,5 V, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s): ATF 44181 ATF 46181 or	
			- other identification markings relating to devices complying with the abovementioned description	θ
243	ex85412920	¥15	Field-effect transistor (FET) of the N-channel type, having a drain-to-source breakdown-voltage of 450 V or more, operating with a continuous drain-current not exceeding 18 A, a drain-to-source resistance not exceeding 0,4 ohs, and with a dissipation rate not exceeding 80 V, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			26K1916 or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
244	ex85412920	¥28	Field-sffect transistor (FET) of the P-channel type, having a drain-to-source breakdown-voltage of -200 V, operating with a continuous drain-current not exceeding -1,8 A, a drain-to-source resistance not exceeding 3 ohs, and with a dissipation rate not exceeding 20 V, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			IRF 9618	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
245	ex85412928	¥25	Field-effect transistor (FET) of the N-channel type, having a drain-to-source breakdown-voltage of 500 V or more, operating with a continuous drain current not exceeding 1 A, a drain-to-source remistance not exceeding 5 Ohm and with a dissipation rate not exceeding 40 V, contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(w):	• •
			MTDINSOE	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
246	ex85412920	\$38	Field-effect transistor (FET) of the N-channel type, having a drain-to-source breakdown-voltage of 600 V or more, operating with a continuous drain-current not exceeding 6,2 A, a drain-to-source resistance not exceeding 1,2 ohs, and with a dissipation rate not exceeding 125 W, contained in a housing bearing:	
			- an identification marking consisting of or including (one of)	

CN code	TARIC	Description	Rate of autonomous duly (%)
		the following combination(s):	,
		IRFBC40	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
247 •x85412920	¥35	Field-effect transistor (FET) of the N-channel type, having a drain-to-source breakdown-voltage of 55 V or more, operating with a drain-to-source current of 0,0 A or more but not exceeding 3 A, a drain-to-source remistance not exceeding 1,5 ohs, and with a dissipation rate not exceeding 38 V, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s): 10038EDA	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
248 ex85412920	●48	Field-effect transistor (FET) of the P-channel type, having a drain-to-source breakdown-voltage of <u>-20</u> , -30, -60 or -100 V, operating with a continuous drain-current <u>og -9,6 A or more but</u> not exceeding <u>5,3</u> A, a drain-to-source resistance not exceeding 0,28 ohm, and with a dissipation rate not exceeding 125 V, contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		IRF 9540 IRFU 9024 MMSF3P03HD <u>NDS 9430</u>	
		- other identification markings relating to devices complying with the abovementioned description	θ
248 ex85412828	¥50	Field-effect transistor (FET) of the N-channel type, having a drain-to-source breakdown-voltage of 30 V or more, operating with a continuous drain-current not exceeding <u>25</u> A, a drain-to-source resistance not exceeding 0,05 ohm, and with a dissipation rate not exceeding 50 W, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		MMSF5N03HD <u>NDP 603AL</u> SMU30N03 N <u>DB 603AL</u> SMD30N03	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
250 ex85412920	¥68	Field-effect transistor (FET) of the M-channel type, having a drain-to-source breakdown-voltage 60 V or more, operating with a continuous drain-current not exceeding 8,5 A, a drain-to-source remistance not exceeding 8,3 oha, and with a dissipation rate not exceeding 30 V, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		IRFD 014 IRFR 014 IRLR 014 IRFR 010 IRFU 014 IRLU 014	
		8 F	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
251 ex85412920	¥78	Field-effect transistor (FET) of the N-channel type, having a drain-to-source breakdown-voltage of 60 V or more, operating with a continuous drain current not exceeding 35 A, a drain-to-source resistance not exceeding 0,1 Oha and with a dissipation rate not exceeding 125 V, contained in a housing- bearing:	

	CN code	TARIC	Description	Rate of autonomous duty
			the following combination(s):	
			5181FK (IRCZ24) 51816K	
			01	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
252	ex85412920	\$75	Field-affect transistor (FET) of the P-channel type, having a drain-to-source breakdown-voltage of -258 V, operating with a continuous drain-current not exceeding -8 A, a drain-to-source resistance not exceeding 1 ohe, and with a dissipation rate not exceeding 38 W, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			28J367	
			٥r	
			- other identification markings relating to devices complying with the abovementioned description	θ
253	ex85412920	*88	Field-effect transistor (FET) of the P-channel type, having a drain-to-source breakdown-voltage of -30 V or more, operating with a continuous drain-current not exceeding 10 A, a drain-to-source resistance not exceeding 0,2 ohs, and with a dissipation rate not exceeding 60 V, contained in a housing bearing: - an identification marking consisting of or including (one of)	
			the following combination(s):	
			RFD16P63L RFD16P63LSM RFP16P63L	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
255	ex85412930	<b>≇</b> 10	Insulmated gate bipoter transistor (1687), with a collector-amitter current not exceeding 28 A, an emitter-collector brackdown-voltage of 320 V or more, a single <u>power supply of +5 V</u> and with a dissipation rate not exceeding 150 W, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			5401CM	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
257	ex85412988	*18	Transistor with a power of 150 W or more at a voltage of 160 V or more and with a cut-off frequency of 20 MHz or more, contained in a housing the exterior dimensions of which do not exceed 22 x 37 mm, with not more than 3 connections and bearing: - an identification marking conmisting of or including (one of) the following combination(m):	
			2 8A 1176 2 8A 1494 2 8C 2921 2 8A 1215 2 8C 2774 2 8C 3858	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
258	ex85412988	¥29	Transistor with thereat overload protection, having a collector-mailter operating voltage not exceeding 42 V,	<u>,                                     </u>

	CN code	TARIC	Description	Rate of autono∎ous duty (X)
259	ex85412980	#30	Transistor with an output power not exceeding 30 W at a voltage of 12,5 V, contained in a housing with not sore than 8 connections	8
260	■x85412988	\$48	Transistor, having a dissipation rate not exceeding 258 W, a collector-smitter breakdown voltage of <u>8</u> 0 V or more and a peak collector current not exceeding 48 A, contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			28C3675 28C3886A 28C4152 <u>C3852A</u> 28C3781 28C3997 28C4288	
			9 <b>7</b>	
			<ul> <li>other identification sarkings relating to devices complying with the abovementioned description</li> </ul>	θ
261	ex85412888	€58	Field-effect transistor (FET) of gallium ersenide (GaAs) semiconductor material, operating at a frequency of 2 GHz or more but not exceeding 18 GHz, contained in a housing bearing: - an identificat <u>ion marking consisting of or including (onm of)</u> the following combination(s):	
			NE76084 NE8604	
			or - other identification warkings relating to devices complying with the abovementioned description	θ
263	ex85413898	¥10	Disc, with a braskover voltage of 77 V or sors but not exceeding 270 V and a state current not exceeding 1 A, contained in a housing	e
264	8x85413898	\$28	Disc, with a breakover voltage of 65 V or more and a capacitance of 200 pF, contained in a housing	θ
267	Bx85414819	<b>\$</b> 10	Light-mmitting diods, operating at a nominal wavelength of <u>567</u> <u>nm or more but not exceeding</u> 718 <u>nm</u> , in the form of a monolithic integrated circuit not contained in a housing (chip), for the mmufacture of optocouplers <u>or of products falling</u> within subheading 85171188 or 85252891 (a)	θ
268	ex85414819	<b>#</b> 28	Light-emitting diods, having a square base with an edge length not exceeding 8,2 mm, having a lens	θ
269	ex85414019	¥30	Light-emitting diode of Transparent Substrate (TS) technology, made from mluminium-gallium-mrseni <u>d</u> (AlGaAs) semiconductor materimt, having a tuminous intensity of 1,4 candela or more at 20 mA	θ
270	ex85414819	848	Light-emitting diods (LED), contained in a housing of the SMD (Surface mounted device) type	θ
266	ex85414019	¥50	Light-smitting diods, made from silicon-carbid (SiC) semiconductor material, operating at a nominal wavelength of 481 nm	8
272	ex85414693	¥91	Photocouple, comprising a phototransistor with a collector current not exceeding 20 mA and a collector-emitter breakdown voltage of 30 V or more, and a light-emitting diode with a reverse current not exceeding 100 µA at a reverse voltage of 5 V, contained in a housing	θ
275	ax85416000	<b>*</b> 91	Piezo-electric crystal oscillating at a frequency of 32768 Hz, with at least one of the following characteristics: - contained in a housing of the SMD (Surface mounted device) type,	
			<u>- contained</u> in a cylindrical housing of a length not exceeding 8,2 am and a diameter not exceeding 3,2 am	θ
276	sx85416000	<b>#</b> 92	Polerised ceramic piezo-electric crystal oscillating in a fraquency range of 500 kHz or more but not exceeding 12500 kHz, contained in a housing the exterior dimensions of which do	

	CN code	TARIC	Description	Rate of autonomous duty
277	ax85416000	<b>*</b> 94	Piezo-electric crystel, excluding surface shoustic wave filters, oscillating at centre frequency of 458 kHz or sore but not exceeding 1843 NHz	θ
278	ex85416000	<b>\$</b> 95	Cerssic filter and resonator elesants for frequencies not exceeding 35 MHz, ands of polarised piezocersaic, only equipped with electrodes or electrode patterns	0
279	ex85419000 ex85429080	#19 #20	Housing or cerasic substrate, with connections	8
281	ex85421301	<b>#</b> 01	Wafer, not yet cut into chips, consisting only of sicrocontrollers or sicrocomputers of C-MOB technology, with a processing capacity of 8 bits, providing serve control functions, comprising a read only seeory, non-programmable (ROM) with a storage capacity of 128 Kbits, 2 random-access memories (RAMs) with a total storage capacity of 3 Kbits and a timer unit, for use in the manufacture of goods of subheading <u>85421363</u> contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			PD 78134	
	`	•	or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	θ
282	ex85421301	¥62	Wefer, not yet cut into chips, consisting only of microcontrollers or microcomputers of C-MOS technology, with m processing capacity of 18 bits, comprising m read only memory, non-programmable (ROM) with m storage capacity of 48 Kbits, m read only memory, non-programmable (ROM) with m storage capacity of 16 Kbits and m rendom-access memory (RAM) with m storage capacity of 4 Kbits, for use in the menufacture of goods of subheading <u>85421365</u> contained in m housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			77025	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	θ
283	ex85421361	163	Wafer, not yet cut into chips, consisting only of microcontrollers or microcomputers of C-MO8 or M-MOS (including H-MOS) technology, with a processing capacity of 16 bits, comprising a read only memory, non-programmable (ROM) with a storage capacity of 518 x 13 bits, a read only memory, non-programmable (ROM) with a storage capacity of 512 x 23 bits and a random-access memory (RAM) with a storage capacity of 2 Kbits, for use in the manufacture of goods of subheading <u>85421365</u> contained in a housing bearing: - an identification marking conmisting of or including (one of) the following combination(s):	
			7720 77020	
			or	
			- other identification markings relating to devices complying with the abovementioned description (m)	θ
284a	ex85421301	¥84	Wefer, not yet cut into chips, <u>only for use</u> in the menufecture of goods of subheeding <u>85421322 to</u> 85421361, <u>85421382 or 85421384</u> (m)	8
286	ex85421301	106	Wefer, not yet cut into chips, consisting only of microcontrollers or microcomputers with a processing capacity of 16 bits, comprising a read only memory, non-programmable (ROM) or a programmable, non-memoral, read only memory (PROM) or an UV grassble, programmable, read only memory (EPROM) with a storage capacity not exceeding 258 Kbits and one or more rendom-access memories (RAMs) with a total storage capacity not exceeding 12 Kbits, for use in the menufacture of goods of subheading <u>85421365</u> contained in a housing bearing: - an identification merking consisting of or including (one of)	

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	TARIC	Description	Rate of autonomous duty (%)
		the following combination(s):	,
		78C11 78C14 78CP14 78C12 78C18 8XC186KT	
		07	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	θ
287 mx85421381	<b>₿</b> 87	Wafer, not yet cut into chips, consisting only of display controllers and character generators (DCCG), for liquid-crystal dot-matrix display systems, for use in the manufacture of goods of subheading <u>85421378</u> contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		7228 7229	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	8
289 ex85421381	*09	Wafer, not yet cut into chips, consisting only of microcontrollers or microcomputers of C-MOS technology, with a processing capacity of 8 bits, comprising a data memory with a storage capacity of 4 Kbits or more but not exceeding 8 Kbits, a programme memory with a storage capacity of 64 Kbits or more but not exceeding 488 Kbits and either a buffer memory or a display random access memory (RAM) with a storage capacity not exceeding 512 bits, for use in the menufacture of goods of subheading 85421363 contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		78011 78014 78044 78053 78056 78063 78012 78042 78045 78054 78058 78064 78013 78043 78052 78055 78062 or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	θ
288 ex85421361	<b>#</b> 12	Wefer, not yet cut into chips, consisting only of control <u>or</u> <u>drive</u> circuits, for use in the menufecture of liquid crystel devices (LCD) <u>eodules</u> (a)	θ
293 ex85421385	¥02	Driver circuit for liquid crystal displays (LCDs) of C-MOS technology, in the form of a monolithic integrated circuit not contained in m housing (microchip), for use in the manufacture of: - liquid crystal displays (LCDs), or	
		- assemblies destined for LCDs (a)	θ
294 ex85421305	<b>₿₿</b> 3	Bus control circuit of C-MOS technology, in the form of m monolithic integrated circuit not contained in m housing (chip), for use in the manufacture of goods of subheading <u>BS421378</u> contained in m housing bearing: - mn identification marking consisting of or including (one of) the following combination(s):	
		<u>86H5685</u> 5267386 63F4074 6961785 2782654 <u>83F4857</u> <u>63F4178</u> <u>81889851</u> 5267385 <b>63F487</b> 3 63F4378	
		or - other identification markings relating to devices complying with the abovementioned description (a)	θ.
	<b>#</b> 85	Memory control circuit of C-MO8 technology, in the form of a monolithic integrated circuit not contained in a housing (chip),	

CN code	TARIC	Description	Rais of suionosous duty (
		3267567 5868191 8184891 8188985	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description (m)</li> </ul>	θ
297 mx85421385	•86	Triple digital-to-analogue video converter with 3 random-access semories (RAMDACs) of C-MO8 technology, in the form of a monolithic integrated circuit not contained in a housing (chip), for use in the sanufacture of goods of subheading <u>85421398</u> contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		RG8525 RG8530 (8187135) RG8528 RG8561 (8186987)	
		07	
		- other identification markings relating to devices complying	
		with the abovesentioned description (a)	8
298 ex85421305	<b>#</b> 07	Bus interface and control circuit of C-NOS technology, in the form of a monolithic integrated circuit not contained in a housing (chip), for use in the manufacture of goods of subheading <u>85421370</u> contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		2782454 4260929 6162276 818487 <b>9 8184095</b> 4260928 5168187 7163184 8184893 <b>8184188</b>	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description (m)</li> </ul>	θ
299 ex85421385	¥08	Data/address buffer circuit of C-MOS technology, in the form of a monotithic integrated circuit not contained in a housing (chip), for use in the manufacture of goods of mubhamding 85421399 contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		2782653 8198694	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description (m)</li> </ul>	θ
301 ex85421305	<b>#10</b>	Control circuit of C-MOS technology, providing local area network and memory control, in the form of a monolithic integrated circuit not contained in a housing (chip), for use in the manufacture of goods of subheading <u>85421370</u> contained in a housing bearing:	
		<ul> <li>an identification marking consisting of or including (one of) the following combination(s):</li> </ul>	
		85F7196	
		or - other identification markings relating to devices complying with the abovementioned description (m)	θ
302 ex85421305	*11	Interface and control circuit of C-MO8 technology, providing scan control and clock control, in the form of a monolithic integrated circuit not contained in a housing (chip), for use in the manufacture of goods of subheading <u>85421378</u> contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		8668155	
		or .	

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	CN code	TARIC	Description	Rate of autonomous duty (%)
303	ex85421385	<b>€</b> 12	Data or image compression <u>and/or</u> decompression circuit of C-NOS technology, in the form of a monolithic integrated circuit not contained in a housing (chip), for use in the manufacture of goods of subheading 85421372 or 85421399 contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(a):	
			26H3898 3H6414 NPEGCD1 NPEGSD1 NPEGSE1	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	θ
384	ex85421385	¥13	Graphic control circuit of C-NO8 technology, in the form of a monolithic integrated circuit not contained in a housing (chip), for use in the menufacture of goods of subheading 85421370 contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(a):	
			5168286 8862562 8862734	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	θ
284d	ex85421385	<b>#</b> 15	<u>Monolithic integrated circuit not contained in a housing</u> (chip), only for use in the senufacture of goods of subheading 85421322 to 85421361, 85421382 or	
	ex85421311	<b>#</b> 01	85421384 (m) Dynamic random-access memory of N-MOS (including H-MOS)	θ
			<pre>technology (N/H-NO8 D-RAN) with a storage capacity of 64 Kbits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):</pre>	
			KN 4164 NN 4264 THS 4164 THS 4416	
			or - other identification markings relating to devices complying with the abovementioned description	θ
387	ex85421311	¥02	Dynamic random-access memory of N-MOS (including H-MOS) technology (N/H-MOS D-RAM), with a storage capacity of 256 Kbits and an access time not exceeding 150 ns, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			HB 50562 KN 41257 NB 81464 PD 41256 THS 4256 HN 50256 N5N 4256 N8N 4256 PD 41464 THS 4464 HN 50464 N5N 4464 N8N 4464 THN 41256 KN 41256 NB 81256 PD 41254 THN 41464	
			٥r	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
308	ex85421311	*03	Dynamic random-access memory of C-MOS technology (C-MOS D-RAM), with a storage capacity of 258 Kbits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			53 C 256 53 C 466 MB 81 C 466 TC 51832 53 C 258 HM 85256 P 51 C 256 53 C 464 MB 81 C 258 P 51 C 259	
			or	
			- other identification markings relating to devices complying	

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	CN code	TARIC	Description	Rate of autonomous duty
309	ex85421311	\$84	Dual port dynamic random-accass memory (D-RAM), with data registers and a serial read output control, with a storage capacity of 256 Kbits, in the form of a monolithic integrated circuit contained in a housing bearing: - an iden'ification marking consisting of or including (one of) the formawing combination(s):	
			N5M 4 C 264 NB 81461 PD 41264 TNS 4461	
			or	
			<ul> <li>other identification serkings relating to devices complying with the abovementioned description</li> </ul>	θ
319	mx85421311	¥85	Dual or triple port dynamic random-access memory (D-PAM), with data registers and a serial read output control, with a storage capacity exceeding 258 Kbit but not exceeding 1 Mbit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			N5M 442256 NT 42 C 4256 NT 43 C 8128 TC 528128 NB 81 C 4251 NT 43 C 4257 TC 524256 TC 528128 NSM 54C864 NT 43 C 4258 TC 524257 TNS 44 C 251	
			or	
			- other identification markings relating to devices complying with the abovementioned description	θ
311	ex85421311	₹86	Dynamic random-access memory of C-MOS technology (C-MOS D-RAM), with a storage capacity of 64 K x 16 bit and an access time not exceeding 100 ns, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			<u>Eic611168A</u> TC511664BFT	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
312	ex85421311	\$67	Pseudo-static random-accass memory of C-MOS technology (C-MOS PS-RAM), with a storage capacity of 4 Mbits, comprising a timing pulse generator and a refresh control circuit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification merking consisting of or including (one of) the following combination(s):	
			HN 658512 HN 65V8512 LHPV127N <u>TC 51V8512</u>	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> <li>These devices are for the manufacture of portable computers,</li> <li>capable of operating without an external source of power (a)</li> </ul>	θ
313	ex85421311	¥68	Dynamic random-access memory of C-MOS technology (C-MOS D-RAM), with a storage capacity acceeding 1 Mbit but not more than 4 Mbits and an access time not acceeding 35 ns, comprising one or more static random-access cache memories (S-Cache-RAMMS), in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking commisting of or including (one of) the following combination(s):	
			DM 2200 DM 2202 DM 2203 DM 2212 DM 2213 DM 2233	
			or	
			- other identification markings relating to devices complying	

(	CN code	TARIC	Description	Rate of sulonomous duty (X)
314 (	ex85421311	<b>8</b> 89	Dynamic random-accase assory of C-MO8 technology (C-MO8 D-PAN), with a storage capacity of 2 Mbits and an accase time not exceeding 80 ns, in the form of a monotithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			V53C8256	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	6
315	ex85421311	●10	Dynamic random-accass memory of C-MOS technology (C-MOS D-RAM), with a storage capacity of 512 K x 8 bits and an accass time not exceeding 100 ns, operating with a supply voltage of 3,3 V (±8,3 V), in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			HM51W4888 (7461387) (7866821)	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
305a	ex85421311	¥12	Synchronous dynamic random-accass memory of C-MOS technology (C-MOS mynchronous D-RAM), with a storage capacity of 4 Mbits, operating with a supply voltage of 3,3 V (±0,3 V), in the form of a monolithic integrated circuit contained in a housing bearing:	
			<ul> <li>- an identification marking consisting of or including (one of) the following combination(s):</li> </ul>	
			MB 81141620	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
317	ex85421313	¥ 0 1	Dynamic random-access memory of C-MOS technology (C-MOS D-RAM), with a storage capacity of 256 K x 18 bits and an access time not accessing 80 ns, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			PD 424280	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	10
305b	ex85421313	¥03	Synchronous dynamic random-access memory of C-MOS technology (C-MOS synchronous D-RAM), with a storage capacity of 8 Mbits, operating with a supply voltage of 3,3 V (±0,3 V), in the form of a monolithic integrated circuit contained in a housing basering: - an identification marking convisting of or including (one of)	
			the following combination(m):	
			MB 81183220	
			or - other identification markings relating to devices complying with the abovementioned description	8
318	ex85421315	₿02	Sunchronous dynamic random-access memory of C-MOS technology (C-MOS mynchronous D-RAM), with a storage capacity of 64 Mbits, operating with a supply voltage of 3,3 V (±0,3 V), in the form of a monolithic integrated circuit contained in a housing bearing:	
			<ul> <li>an identification marking consisting of or including (one of) the following combination(m):</li> </ul>	

	CN code	TARIC	Description	Rate of autonomous duty (%
			MB 81164840	, ,
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
8bis	85421353		Other memories	
	85421425 85421949			9
391	85421361 85421442 85421962		Nicrocontroller or microcomputer with m processing capacity not exceeding 4 bits	·····
				8
394	ex85421363	+01	Microcontroller or microcomputer of N-MOS (including H-MOS) tachnology, with a processing capacity of 8 bits, having paripheral interface functions, comprising a random-access memory (RAM) with a storage capacity not exceeding 2 Kbits, a read only memory, non-programmable (ROM), a programmable, non-arasmable, read only memory (PRDN) or a UV arasmable, programmable, read only memory (EPRON) with a storage capacity of 16 Kbits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			8842 8742	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
395	ex85421363	¥82	Microcontroller or microcomputer of N-MOS (including H-MOS) technology, with a processing capacity of 8 bits, comprising <u>a</u> <u>data memory in the form of a static random access memory (S-RAM)</u> and a programme memory, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			MC 68785 MC 68 <u>85</u>	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	6
396	ex85421363	•63	Microcontroller or microcomputer of C-MOS technology, with a processing capacity of 8 bits, having a register-to-register architecture, comprising a static random-access memory (S-RAM) with a storage capacity of not more than 12 Kbits and at least a read only memory, non-programmable (ROM) or a programmable, non-marasable, read only memory (PROM) or an UV-erasable, programmable, read only memory (EPROM) or an electrically erasable, programmable, read only memory (E <sup>2</sup> PROM), with a storage capacity of not more than 256 Kbits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			3700010         3700250         3700732         73085           3700032         3700256         3700756         73080           3700050         3700310         3700758         73095           3700052         3700332         3700810         730161           3700055         3700332         3700810         730161           3700055         3700350         3700850         MC 68H00501           3700058         3700352         3740036         MC 68H00508           3700150         3700356         73041         3700156           3700156         3700358         73042         37042	
			or	
			- other identification markings relating to devices complying	

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	CN code	TARIC	Description	Rais of autonomous duty (X
397	ex85421363	•84	Microcontroller or microcomputer of C-MOB technology, with a processing capacity of 8 bits, for text data decoding and display, coaprising a read only memory, non-programmable (ROM) with a storage capacity of 8 Kbits, a read only memory, non-programmable (ROM) with 120 character fonts and a random-access memory (RAM) with a storage capacity not exceeding 2304 bits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(marking):	
			CF 72387	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
398	ex85421363	¥05	Microcontroller or microcomputer of C-MO8 technology, with a processing capacity of 8 bits, providing vartical deflection functions for a cathode-ray tube, comprising 2 arithmetic-logic units (ALUs), 4 read only memories, non-programmable (ROMs) with a total storage capacity of 11,7 Kbits, 2 rendom-access memories (RAMs) with a total storage capacity of 1 Kbit, an analogue-to-digital converter and 2 digital-to-analogue converters, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking commisting of or including (one of) the following combination(mathematical):	
			CXD 2018	
			or - other identification markings relating to devices complying with the abovementioned description	θ
399	Bx85421363	<b>\$</b> 86	Microcontroller or microcomputer of C-MO8 technology, with a processing capacity of 8 bits, providing kayboard control functions, comprising a read only memory, non-programmable (ROM) with a storage capacity of 2 Kbits, random-access memorias (RAMs) with a total storage capacity of 2 Kbits, a real-time clock, address registers and input/output buffers, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking conmisting of or including (one of) the following combination(s):	
			820113	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
400	ex85421363	<b>≇</b> ₿7	Microcontroller or microcomputer of C-MOS technology, with a processing capacity of 8 bits, providing remote control functions, comprising a read only memory, non-programmable (RDM) with a storage capacity not exceeding 126 Kbits and a random-access memory (RAM) with a storage capacity not exceeding 4 Kbits, in the form of a monolithic intergrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			NN 187164 PCA 84C222 PCA 84C822 PCA 84C122 PCA 84C422	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ,
401	ex85421363	¥08	Microcontroller or microcomputer of C-NO8 technology, with m processing capacity of 8 bits, providing voice message storage, comprising a read only memory, non-programmable (ROM) with m storage capacity of 128 Kbits, an UV-arasable, programmable, read only memory (EPROM) interface circuit, m random-access memory (RAM) interface circuit and m communication interface circuit, in the form of m monolithic integrated circuit	

CN code	TARIC	Description	Rate of autonosous duty
		contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> <u>the following combination(s):</u>	
		D6365	
		0 Г	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
482 Bx85421363	€09 	Microcontroller or microcomputer of C-MOS technology, with a processing capacity of 8 bits, providing communication and control functions in local operating natworks (LONs), comprising three 8-bit central processing units (CPUs), a static random-access memory (8-RAM) with a storage capacity not exceeding 18 Kbits and an electrically areaable, programmable, read only memory (E <sup>2</sup> PROM) with a storage capacity of 4 Kbits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		NC 143120 NC 143150	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
404 ex85421363	*11	Microcontroller or microcomputer of C-MOS technology, with a processing capacity of 8 bits, comprising a random-access memory (RAM) with a storage capacity of 2 or 8 Kbits, an electrically measable, programmable, read only memory (E <sup>2</sup> PROM) with a storage capacity of 4 Kbits and an 8-channel analogue-to-digital converter, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		NC 68HC11A1 SC 415111FU SC 415016FU TMP 68HC11A1 NC 68HC11F SC 415112FU SC 805666FN	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
405 ex85421363	¥12	Microcontroller or microcomputer of C-MOS technology, with a processing capacity of 8 bits, comprising a 16-bit digital signal processor, a random-access memory (RAM) with a storage capacity of 4 Kbits or more but not exceeding 16 Kbits and having the function of programme memory, 2 random-access memories (RAMs) with a total storage capacity of 2 Kbits or more but not exceeding 8 Kbits and 256 registers, in the form of a monolithic intergrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s): Z 86294 Z 86295 Z 86C95	
		2 80234 2 80235 2 88035 0r	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
406 ex85421363	<b>€</b> 13	Nicrocontroller or microcomputer of C-MOS technology, with m processing capacity of 8 bits, providing floppy disc storage unit or keyboard control functions, comprising an 8-bit configuration register, m random-access memory (RAM) with m storage capacity of 16 Kbits and having the function of programme memory, m random-access memory (RAM) with a storage capacity of 2 Kbits and m real-time clock, in the form of m	
		<pre>monolithic integrated circuit contained in a housing bearing:     an identification marking consisting of or including (one of)     the following combination(s):</pre>	

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CN co	ode	TARIC	Description	Rate of sutonomou	s duly (X)
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	"
407 ex854	421363	¥14	Microcontroller or microcomputer of C-NO8 technology, with a processing capacity of 8 bits, comprising 5 data memories with a total storage capacity not exceeding 180512 bits, a programme memory with a storage capacity of 21 Kbit, a keyboard controller, a video synchronization controller and 1 or 2 universal asynchronous receiver/transmitter (UARTs), in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination():		
			the following combination(s):		
			10		
			<ul> <li>other identification serkings relating to devices complying with the abovementioned description</li> </ul>	8	
408 ex854	421363	¥15	Microcontroller or microcomputer of C-NOS technology, with a processing capacity of 8 bits, comprising a data memory, a programme memory and a display control or drive circuit, in the form of a monolithic intergrated circuit contained in a housing bearing: - an identification marking conmisting of or including (one of) the following combination(m):		
			83C751         CXP         85228         M         3817         PD         75316           83C752         CXP         85232         M         38283E4         TMP         87CC26F           87C750         CXP         85346         M         38203M2         TMP         87CH20F           87C751         CXP         85452         M         38207E8         TMP         87CK70AF           87C752         CXP         85466         M         38207N8         TMP         87CK70AF           CXP         82316         M         37500M5         M         3825         CXP         82320         M         37500M8         MB         88098         X		
			or		
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	
409 ex854	421363	¥16	Microcontroller or microcomputer of C-NO8 technology, with a processing capacity of 8 bits, comprising m data mamory with a storage capacity not exceeding 9 Kbits, a programme amory with a storage capacity not exceeding 258 Kbits, a serial synchronous communication interface consisting of an 8-bit serial shift register with serial data input, serial data output and serial shift clock, and in the form of a monolithic intergrated circuit contained in a housing bearing: - an identification marking commisting of or including (one of) the following combination(s):		
			COP 828 COP 881C COP 888CG MB 89152 Cop 848 cop 884CF cop 888EG MB 899657A Cop 888C cop 888CF MB 89145 MB 89W147		
			٥٢		
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	
410 ex854	421363	<b>* 1</b> 7	Hicrocontroller or microcomputer of C-MO8-technology, with a processing capacity of 8 bits, comprising a read only memory, non-programmeble (ROM) with a storage capacity of 18,5 Kbits and a random-access memory (RAM) with a storage capacity of 1 Kbit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) to following combination(s):		
			76032KC		
			or		
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8	

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	CN code	TARIC	Description	Rate of autonomous duty (%)
411	ex85421363	¥18	Microcontroller or microcomputer of C-M08 or N-M08 (including H-M08) technology, with a processing capacity of 8 bits, comprising one or more data memories with a total storage capacity not exceeding <u>12</u> Kbits and a program memory with a storage capacity of 32 Kbits or more but not exceeding <u>480</u> Kbits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			SA41       87C504       L 39       MC68HC11A8         SB11       87C51       N 3745088       MC68HC705;8         76C75T       87C52       N 3745088       MN 1871215         7742       87C54       N 3806386       PCA 84C640         77C82       87C58       M 3806386       PCA 84C840         80C152       87L51       M 3806788       PCA 84C841         80C51       Am 78C412       N 380778       PCA 84C841         80C52       AT 89C51       M 580747       PD 78014         80C55       C 1900       M50747       PD 78064         83C51       C 3806       M50958       PD 78134         83C51       C 40       MC 143120       TMP 81P642         8751       CXD 80724       MC 143150       TMP 91P642         87C955       CXP 80524       MC68HC65;8       TMP 91P642	
			or - other identification markings relating to devices complying with the abovementioned description	θ
413	Bx85421363	*20	Nicrocontroller or microcomputer of C-MOS technology, with a processing capacity of 8 bits, comprising a read only memory, non-programmable (ROM) with a storage capacity of 256, 328 or 384 Kbits and a rendom-access memory (RAM) with a storage capacity of 18496, 11888, 28736 or 21768 bits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s): CXP 87132 CXP 87248 NN 1883228 CXP 87148 CXP 87248 NN 1884828	
			or - other identification markings relating to devices complying with the abovementioned description	θ
414	∎x85421363	<b>₽</b> 21	Microcontroller or microcomputer of C-MOS technology, with m processing capacity of 8 bits, comprising a random-access memory (RAM) with a storage capacity not exceeding 16 Kbits, a read only memory, non-programmable (ROM) or a programmable, non-erassable, read only memory (PROM) or an UV erasable, programmable, read only memory (EPROM), with a storage capacity not exceeding 384 Kbits, an electrically erasable programmable, read only memory (E <sup>2</sup> PROM) with a storage capacity not exceeding 6 Kbits and an 8-channel analogue-to-digital converter, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			NC 88HC11 NC 68HC711	
			or - other identification markings relating to devices complying with the abovementioned description	e
415	ex85421365	<b>#</b> 81	Microcontroller or microcomputer of C-MOS technology, with m processing capacity of 18 bits, capable of modulator/demodulator (modem) signal processing, comprising a data memory with a storage capacity 4 Kbits and a programme memory with a storage capacity of 256 Kbits, in the form of m monolithic integrated circuit contained in m housing bearing: - an identification marking consisting of or including (one of) the following combination(s): 8C 11066 8C 11077 SC 11088	

	CN code	TARIC	Description	Rate of autonomous duty (X
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
416	ex85421365	€82	Microcontroller or microcomputer of C-MOS technology, with a processing capacity of 16 bits, comprising a data memory with a storage capacity of 32 Kbits, one or more programme memories with a total storage capacity not exceeding 240 Kbits and a 14-bit external bus, in the form of a monotithic integrated circuit contained in a housing bearing: - an identification marking commisting of or including (one of) the following combination(s):	
			AD8P 2171 AD8P 2178	
			or - other identification markings relating to devices complying	
			with the abovesentioned description	θ
417	Bx85421365	•03	Microcontroller or microcomputer of C-MOB technology, with a processing capacity of 16 bits, comprising an arithmatic-logic shifter, a data memory with a storage capacity of 8 Kbits and a programme memory with a storage capacity of 96 Kbits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion_marking consisting of or including (one of)</u> the following combination(s):	
			ADSP 2164	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
418	ex85421365	384	Microcontroller or microcomputer of C-MO8 technology, with m processing capacity of 16 bits, comprising m random-access memory (RAM) having the function of data and programme memory and with a storage capacity of 8 Kbits, an audio interface, m video interface and a descremblar circuit, in the form of m monolithic integrated circuit contained in m housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			CL 9118	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
419	Bx85421365	∎05	Microcontroller or microcomputer of N-MO8 technology (including H-MOS), with a processing capacity of 16 bits, comprising at Least one read only memory, non-programmable (ROM) with a storage capacity of 518 x 13 bits or an UV aramshle, programmable, read only memory (EPROM) with a storage capacity of 512 x 13 bits, a random-access memory (RAM) with a storage capacity of 2 Kbits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(mathematics):	
			PD 7728 PD 77 P 28	
			or	
			<ul> <li>other identification sarkings relating to devices cosplying with the abovementioned description</li> </ul>	θ
421	ex85421365	<b>₽</b> 07	Microcontroller or microcomputer of C-MOS technology, with m processing capacity of 16 bits and a 16-bit address-bus and an 8-bit data-bus, comprising a random-access memory (RAM) with a storage capacity of 4 Kbits or more, a read only memory, non-programmable (ROM) or a programmable non-erasable read only memory (PROM) or a UV-erasable, programmable, read only memory (EPROM) with a storage capacity of 128 Kbits or more, in the form of a monolithic integrated circuit contained in a housing bearing:	

CN code	TARIC	Description	Rate of sutono∎ous duty (X
		the following combination(s):	,
		MB 89715 NB 89P715 NB 89W715	
	/	or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
427 Bx85421365	•13	Nicrocontroller or microcomputer of C-MO8 technology, with a processing capacity of 18 bits, comprising of a read only memory, non-programmable (ROM) with a storage capacity of 64 Kbits, a rendom-access memory (RAM) with a storage capacity of 32 Kbits and a static random-access cache memory (8-Dache-RAM) with a storage capacity of 15 x 13 bits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		D8P16A	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
420a ex85421365	¥21	Microcontroller or microcomputer, with a processing capacity of 18 bits, comprising a <u>date memory</u> , a programme memory <u>and</u> <u>with</u> a digital-to-analogue converter and <u>/or</u> an <u>analogue-to-digital converter</u> , in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) <u>the following combination(s):</u>	
		21msp5285-52         83C198         HD 6473308CP         N 37702 M4           78C11         8796         ICS 1700         N 37702 N6L           78C12         87C196         N 37702 E2         N 37702 N0B           78C14         ADSP 21msp58         N 37702 E4         M 37710 EFL           78CP146         ADSP 21msp59         M 37702 E8         M 37751E6           8396         H8/532         M 37702 M2         MC 68HC16           8397         HD 6435368         M 37702 M3B         MC 58HC16	
		or - other identification merkings relating to devices complying	
		with the above entioned description	θ
424a ex85421365	<b>₩</b> 22	Microcontroller or microcomputer of C-MOS technology, with a processing capacity of <u>18</u> bits, <u>providing local area network</u> <u>control</u> , comprising a data memory and a programme memory, in the form of a monolithic intergrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		<u>8MC 83C825</u> TMS 8370C03 TMS 8370C73	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
132a ex85421365	₿23	Microcontroller or microcomputer of C-MOS technology, with a processing capacity of 18 bits, comprising a data memory with a storage capacity not exceeding 16 Kbits <u>and</u> a programme memory with a storage capacity not exceeding 48 Kbits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(m):	
		AD8P         2101         AD8P         2105         DSP         56116           AD8P         2102B8-50         AD8P         2111         PD         77P25           AD8P         2103         AD8P         2115	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ

CN code	TARIC	Description	Rate of autonomous duty (X)
134 ex85421367	•01	Microcontroller or microcomputer of C-M08 technology, with m processing capacity of 19 bits, providing mudio functions and transmit/receive functions of a digital cordless talecommunication system, in the form of m monolithic integrated circuit contained in m housing bearing: - an identification marking conmisting of or including (one of) the following combination(m):	
		AM 79C428 8C 14488 / 8C 14481 8C 14428 8C 14468 or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
435 ex85421367	¥02	Microcontroller or microcomputer of N-MO8 (including H-MO8) technology, with a processing capacity of 32 bits, comprising 24 registers of 32 bits and a random-access memory (RAM) with a storage capacity of 2 Kbits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		HGC 6127	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
137 m×85421367	<b>₽</b> 04	Microcontroller or microcomputer with a processing capacity of 32 bits and a 16-bit data-bus, comprising random-access memories (RAMs) with a total storage capacity not exceeding 450 Kbits, one or more read only memories, non-programsble (ROMs) or one or more UV erasable, programsable, read only memories (EPROMs) with a total storage capacity not exceeding 768 Kbits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		320 10 320 C 15 320 C 50 320 E 15 320 11 320 C 17 320 C 51 320 E 17 320 C 10 320 C 25 320 C 53 TMS 320C59	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
438 ex85421367	¥05	Microcontroller or microcomputer of C-MOS technology, with m processing capacity of 32 bits, comprising a rand only memory, non-programmable (ROM) with m storage capacity of 4 Mbits, m random-access memory (RAM) with a storage capacity of 1 Mbit, a display control and drive circuit, an interrupt controller, a keyboard controller, m memory mapping control circuit and a clock generator, in the form of m monotithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		SC 414181FG16	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
139 ax85421367	¥06	Microcontroller or microcomputer with m processing capacity of 32 bits, comprising one or more random-access memoriem (RAMs) with a total storage capacity not exceeding 48 Kbits, a read	
		only memory, non-programmable (ROM) with a storage capacity not exceeding 128 Kbits and a floating point arithmatic unit with a capacity of 32 bits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	

CN code	TARIC	Description	Rate of sutonomous duty (
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
440 ex85421367	¥67	Microcontroller or sicrocomputer of C-MO8 technology, with a processing capacity of 32 bits, comprising one or more random-access assories (RAMs) with a total storage capacity of 64 Kbits and a read only assory, non-programsable (ROM) with a storage capacity not exceeding 128 Kbits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		328 C 38 328 C 48 D8P 3287	
	-	or	
		<ul> <li>other identification sarkings relating to devices complying with the abovementioned description</li> </ul>	θ
441 Bx85421367	*68	Microcontroller or microcomputer of C-MO8 technology, with a processing capacity of 32 bits, consisting of a system integration module (SIM), a random-access memory (RAM), a time processor unit (TPU) and 2 merial interface <u>circuits</u> , in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking conmisting of or including (one of) the following combination(s):	
		NC 68332 <u>NC 68336</u>	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
442 вx85421367	*89	Microcontroller or microcomputer of C-MOS technology, with a processing capacity of 32 bits, having the function of audio-data processing, comprising a multipliar/sccumulator (MAC) of 52 bits, 2 dynamic random-access memories (D-RAMs) with a total storage capacity of 12 Kbits and 2 static random-access memories (8-RAMs) with a total storage capacity of 14 Kbits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(m):	
		THC 57888 THC 57881	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
443 ex85421367	*10	Microcontroller or microcomputer of C-MOS technology, with a processing capacity of 28 bits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		VY 27015	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
444 вx85421369	*61	Microcontroller or microcomputer of C-MOB technology, with a processing capacity of more than 32 bits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		ADBP 21860 C8 4920 D8P 56001 D8P 96002 ADBP 21861 D8P 1616 D8P 56002 TMS 3200500 ADBP 21862 D8P 56000 D8P 56166 TMS 3200548	
		or	
		- other identification markings relating to devices complying	

CN code	TARIC	Description	Rate of autonom	ous duty (X)
		with the abovementioned description	θ	٣
451 Bx85421378	¥01	Printer control circuit of C-MOS technology, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):		
		<u>17x6-0301</u> 79R3710 TMX 35C438 <u>17y6-0001</u> 79R3740		
		or		
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	
452 ex85421370	¥82	Display controller or character generator for liquid crystel displays (LCDs), light-emitting diodes (LEDs) or fluorescent displays, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):		
		D 16382 ECN 2182 HD 81838 PD 16311		
		D 16306 ECN 2112 NC 141540 TC 9240F		
		or		
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	
453 ex85421378 ex85421971	#83 #82	Disc storage unit controller, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):		
		0391343       CL SH260       MB 89311         1454-001       CL SH265       ONTI 505         600621       CL SH350       OTI 018         6008       CL SH360       OTI 033         6008       CL SH361       PD 7261         61156-001       CL SH362       PD 7262         61157-001       DP 8473       WD 1010         7467202       FDC 37C665       WD 16C92         82077       FDC 37C666       WD 37C65         8980       FE 2100       WD 57C65         ADS 10C00       G 70360-33       WD 42C22         AIC 610 L       HDC 9224       WD 5011         AIC 6180       HDL 33AHQ120       WD 76C20         AIC 8265       HG 62604L02F       Z 86 C 99         CL SH256       L 1 A 0519       97		
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	
454 ex85421370 ex85421971	# 6 4 # 6 3	Control and/or management circuit for memories (including buffers), in the form of a monotithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):		
		0404 $1872$ $82$ $C$ $302$ $L1A4599$ $1RJ3-0001$ $82$ $C$ $325$ NC $68440$ $1TU9-0301$ $82$ $C$ $392$ NC $68450$ $390$ $Z$ $55$ A $38202$ NC $68851$ $68451$ $CV7C684$ NS $32082$ $82367$ $CV7C685$ NS $32382$ $82357$ $CV82C597$ T $9496$ $82359$ $CV82C692$ THCT $4502$ $82385$ $GC$ $183$ VC $2730-0001C$ $82424$ TXHD $68456$ VL $4502$ $82495$ HDL $33A115-006X$ WD $1015$ $82495$ XPHDL $33A115-006X$ WD $12$ $82664$ HDL $3N118-0040$ WD $12$ $C$ $82$ $C$ $102$ $H6$ $628079L25F$ $WD$ $83$ $C 580$ $82$ $C$ $223$ HT $113$ WD $83$ $C 583$		

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CN code	TARIC	Description	Rate of autono∎ous duty (
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
455 Ex85421370	¥05	Serial and/or parallal communication controllar, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		82850         HDL         324187-08HQ         8CN         68582           82         C         665         HDL         324189-08HQ         8CN         68852           82         C         666         HDL         31119HQ119         WD         76C38           82         C         667         NC         2652         Z         80         C         30           84         8701A         NC         68652         Z         85         C         30           CL-CD180         PD         72801         Z         85         C         35           CV7C965         8CN         2652          85         C         35	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
456 ex85421370 .	<b>#66</b>	Digital line interface control circuit of C-MO8 technology, capable of controlling the data flow between a system interface circuit, a subscriber line interface circuit (8LIC) and a microprocessor interface circuit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		TP 3128	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
458 ex85421370	≇08	Control circuit of C-MOS technology, operating at 12 MHz, comprising a programmable interval timer, a clockgenerator, two direct ammory access controllars and a memory mapper, in the form of a monolithic integrated circuit contained in a housing bearing:	
		<ul> <li>- an identification serking consisting of or including (one of) the following combination(s):</li> </ul>	
		82231	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
459 ex85421370	<b>8</b> 89	Control circuit of C-MO8 technology, for the management of asynchronous cycles of a 32-bit central processing unit (CPU), of a direct memory access (DMA) circuit and of a multimester bus, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		82 C 321	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
460 ex85421370	<b>≇</b> 10	Control circuit or control and management circuit, comprising 2 direct memory access (DMA) controllers and 2 interrupt controllers, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(m):	
		823608L 82C491 HT 101 SX 82C206 82C593 VL 82 C 480 82C316 GC 101 8X VL 82 C 486	

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CN code	TARIC	Description	Rais of sutonomous duty (X)
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	9
461 ex85421378	*11	Control circuit of C-MOB technology, for controlling and interfacing signals between a central processing unit (CPU), memory and input/output interfaces, comprising circuits for refreshing dynamic rendom-access memories (DRAMs), for decoding of addresses, for generating clock signals and monitoring data transfer interrupt signals, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		344 8 3602	
		or	
		<ul> <li>other identification sarkings relating to devices complying with the abovementioned description</li> </ul>	θ
462 ex85421378	¥12	Control circuit of C-MOS technology, for a microcontroller, a microcomputer or a microprocessor with a processing capacity of 16 or 32 bits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		82C311 TACT 828411	
		or	
		- other identification markings relating to devices complying with the above entioned description	θ
463 ex85421370	*13	Timing control unit (TCU) with two-phase cycle for central processing unit (CPU) and memory menagement unit (MMU), in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		NS 32281 NS 32 C 201	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
464 ex85421370	¥14	Control circuit of C-MO8 technology, capable of driving 25 Lamps or a 7-segment light-emitting diode (LED) display, having a drive voltage of 4,5 V or more but not exceeding 6 V, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		NC 14489	
		or	
		- other identification markings relating to devices complying with the abovementioned description	θ
465 ex85421378	<b>*15</b>	Circuit for connecting/disconnecting buses, of C-MOS lechnology, in the form of a monotithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		MCC8142233 MCC8142234 MCC8142235	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	9

	•	CN code	TARIC	Description	Rate of autonomous duty (%)
_	466	ex85421370	•16	Control and interface circuit of C-NO8 technology, comprising a assory controller, a peripheral controller, a central processing unit (CPU) interface circuit, a numeric processor unit (NPU) interface circuit, a clock generation circuit, a timer and a parity-check circuit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
				HT 15 HT 18 HT 21 HT 22	
				07	
				<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	9
-	467	Bx85421378	*17	<pre>Interface or interface and control circuit of C-MO8 technology, with at least one of the following functions: - a) for signals between a peripheral disc assory unit and a central processing unit (CPU), - b) for controlling data consumication between a system bus interface and peripheral units, comprising a system interface gate, a microprocessor gate and a direct assory access (DMA) gate, - c) for interfacing and controlling the data sequence between an automatic data-processing machine and a disc storage unit, - d) for read/write data between a digital-audio-tape storage unit and a microprocessor, in the form of a monolithic integrated circuit contained in a</pre>	
				housing bearing: - an identificat <u>ion marking conmisting of or including (one of)</u> the following combination(m):	
			•	a)0331374       a)08 3384         a)0880960       a)WD 11 C 00-17         a)08801002       a)WD 14 C 00-17         a)20011       a)WD 61 C 40         a)AIC 560 L       b)1TU1-0301         a)DP 8466       b)1TU2-0301         a)M 5213       b)1TV3-0301         a)M 5215       b)1TV4-0302         a)OMTI 5090 (OMTI 20509)       b)1TV4-0302         a)D8 32383       c)32C260         a)O8 32384       c)AIC 6060         a)O8 32383       d)1XK2-0301	
				or - other identification markings relating to devices complying	
-	468	ex85421370	¥18	with the abovementioned description Control and interface circuit of C-MOS technology, capable of receiving, processing and transmitting subscriber data in a digital network, cosprising a line interface unit, a autiplaxer, a data link controller, a sicroprocessor interface and an oscillator, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	J
				AN 79C30A AN 79C32A QNV 453	
				or - other identification markings relating to devices complying with the abovementioned description	θ
-	470	ex85421378	\$28	Control and interface circuit for central processing unit (CPU) of C-MOS technology, comprising a control unit for the refresheant of memories, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(m): FE 3010	
				or	

CN c	ode	TARIC	Description	Raie of autonom	ous duty (X)
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	,
471 sx85421378	421370	₽21	Control and interface circuit of C-MOS technology, comprising 48 mA drivers, registers, an 18- or 32-bit direct memory access (DMA) interface, an 8- or 32-bit microprocessor bus and a parity generator and checker, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking commisting of or including (one of) the following combination(m):		
			AN53C974 NCR 53C94 NCR 53C95 NCR 53C96		
			or		
			<ul> <li>other identification markings retating to devices complying with the abovementioned description</li> </ul>	θ	
472 ex85	421370	•22	Interface and control circuit of C-MO8 technology, comprising 2 universal asynchronous receiver/transmitters (UARTs), a parallal-date port, a hard-disc interface and a floppy-disc controller, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):		
			37C665 37C666 82C711 TACT 88511		
			10		
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	
473 ex85	421370	¥23	Dual or octal universal asynchronous receiver/transmitter (Dual or octal UART), in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):		
			1T01-0202 PC 87310 8CC 2698		
			or		
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	
474 sx85	421370	<b>₽</b> 24	Circuit for data transfer between a microprocessor and memory cards of a thickness of 3 mm or more, of C-HOS technology, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):		
			NB 86301		
			or		
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	
475 px85	421378	¥25	Programmable asynchronous communication element circuit of C-MOS technology, for the asynchronous transmission and reception of data, comprising a FIFO (first in, first out) read/write memory and at least one serial input/output channel and a bi-directional parallel channel, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):		
			160551 160552		
			or		,
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	

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	CN code	TARIC	Description	Rate of autonomous duty (
476	Bx85421378	¥26	Programmable interval timer/counter of C-MOS technology, in the form of a monolithic integrated circuit contained in m housing bearing:	X
			<ul> <li>an identification marking consisting of or including (one of) the f llowing combination(s);</li> </ul>	
			82054	
			10	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
477	ex85421378	\$27	Computing unit of C-MO8 technology, without an internal programme sequencer for the multiplication or processing of fixed and floating point numbers, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(m):	
			ADSP 3218 ADSP 3228	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
478	ex85421370	<b>\$</b> 28	Multiplier or multiplier/accumulator (NAC) of C-MOS technology, in the form of a monolithic integrated circuit contained in a housing bearing:	
			<ul> <li>an identification marking consisting of or including (one of) the following combination(s):</li> </ul>	
			ADSP 1008-A CY7C516 <u>LMU112</u> Cy7C510 Cy7C517	
			0 F	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
479	ex85421370	≇29	Message handler circuit based on gate arrays of C-NOS technology, providing multi-channel communication over a bidirectional bus, comprising a microprocessor interface circuit, a voice/data receiver and transmitter, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking commisting of or including (one of) the following combination(s):	
			QMV 253	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
481	ex85421370	€31	Digital signal synthesiser based on standard calls of C-MOS technology, comprising 32 independent programmable channels, a clock generator, an input/output decoder, a microprocessor with a processing capacity of 8 bits, 2 timers, an interrupt controller, 2 digital-to-analogue converters and an analogue-to-digital converter, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			VV 86243	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
483	ex85421370	¥33	Audio signal processing circuit of C-MO8 technology, providing sound effects generation, comprising one or more random-access memories (RAMs) and a microprocessor interface, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	

CN code	TARIC	Description	Rate of autonomous duty (%)
		C8 8985 C8 9283 <u>N 85846</u>	•
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
485 sx85421370 sx85421971	*35 *08	Data-buffer or data/address-buffer circuit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		110016203         \$2C601         FB         2020         VL         82         C         332           82663         82C602         6C         102         NT         102	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	6
486 ∍x85421370	*36	Interface and control circuit of C-MOS technology, comprising a digital-to-analogue and analogue-to-digital converter, a digital signal modulator, a serial bus, a 16-bit interface circuit and an 1/4-bit counter, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		C8P 1088	
		or	
		<ul> <li>other identification sarkings relating to devices complying with the abovementioned description</li> </ul>	θ
487 ex85421370	<b>\$</b> 37	Data detection and phase correction circuit of C-MOS technology, comprising a clock frequency correction circuit, status and control registers and a microprocessor interface, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		118014903	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
488 ex85421370	<b>*</b> 38	Data compression circuit of C-MOS technology, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	4.,,,,,,,
		118817183	
		or	
		<ul> <li>other identification sarkings relating to devices complying with the abovementioned description</li> </ul>	θ
489 mx85421370	*39	16-bit audio signal control circuit of C-MOS technology, comprising a bus interface, a sound generator, an universal asynchronous receiver/transmitter circuit (UART) and a microprocessor interface, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		OTI 605	
		or	
		<ul> <li>other identification sarkings relating to devices complying with the abovementioned description</li> </ul>	θ

	CN code	TARIC	Description				Rate of autonomous duty (%)
490	ex85421370	¥48	in the form of a housing bearing - an identificm	∎ monotithic in≀ :	tegrated cin	t of C-MOS technology, rcuit containad in a or including (ona of)	
			110016404				
			or				
				ication merking mentioned desc		to devices complying	θ
491	ex85421378	#41			·	form of m monolithic	
			integrated circ - an identifica	uit contained in	n m housing nsisting of		
			2782376		B2 C 591	HT 216	
			2782654 6961785		82 C 597 82 C 599	HT 321 L1A 4601	
			82383	82 C 288	<u>82 C 691</u>	NSM 6307	
			82304 82386		<u>82 C 693</u> 82 C 8018	<u>r 4228</u> r 4230	
			82308	82 C 362 8	82 C 802G	TACT 83443	
			82309 82355		82 C 822 82 C 88	VAC 068 Vic 068	
			82358	82 C 465 (	CA 91C014	VIC 64	
			82374EB 82434LX		ET 6000 GC 181	VL 82 C 331 VV 86 C 410	
			or				
				ication markings amentioned desc	· · · · · · · · · · · · · · · · · · ·	to devices complying	θ
			in a housing or	stal display (L( r graphic symbol action controll m monolithic in fixed on m plan	CD) driving La controll ing, tegrated ci stic suppor	ing, rcuit, either containe t, and bearing:	
				l <u>ion marking co</u> n combination(s)		or including (one of)	<u>1</u>
			a)82 C 434 a)82 C 453	Ь)HD 61104T Ь)HD 61105T	Б)WD 90 с)82 С		
			a)86 C 805	b)HD 66106T	c)82 C		
			a)86 C 911	Ь)HD 66107T Ь)LC 7582	c)82 C		
			a)86 C 928 a)AM 8052	b)M 6003	c)82 C · c)82 C ·		
			B)ATI 68800	b)# 6004	c)84 C		
			a)CL-GD542 a)CL-GD543	6)MSM 5259 6)NSM 5298	c)86 C c)86 C		
			a)CRT 9007	b)M8M 5299	c)ATI 2		
			a)CRT 97 C 11 a)M 50452	Ь)NSM 5839 Ь)PCF 8576	c)AVGA1 c)CL-GD	5418	
			a)MB 89321	6)SED 1520	c)CL-GD	5448	
			<pre>mb 89322 m)TVP 9512</pre>	6)8ED 1521 6)8ED 1600	c)60 54 c)HT 20		
			a)V 6363	b)SED 1610	c)HT 28		
			æ)₩D 90 C 10	6A39	c)L 648		
			∎)WD 90 C 11 ∎)WD 90 C 30	Ь)Т 6А40 Ъ)ТМ8 3491	c)LC 74 c) <u>HC 14</u>		
			a)₩D 90 C 31	b)TN8 3492	c)NCR 7	7022	
			a)WD 90 C 33 b)82 C 425	Ь)TM8 57202 Ь)TM8 57206	c)OTI 0 c)PÉGA	67	
			b)CL-GD6410	b)TM8 57287	c)PVGA		
			Ь)COP 472 Ь)H 5050	Ь)TM8 57210 Ь)TM8 57212	c)8C 15 c)TM8 3		
			6)HD 44100	b)TH8 57212	c)WD 90		
						100	
			Ъ)HD 44788 Б)HD 66100	b)V 6117 b)V 6355-DJ	9)85 C	133	
			b)HD 44788		d)82 C	133	

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	CN code	TARIC	Description	Rate of autonomous duty (X)
493	sx85421370	₹43	Error detection and correction circuit of C-NO8 or (including N-NO8) technology, capable of detecting correcting single bit errors and detecting all doul errors, in the form of a monolithic integrated circ in a housing bearing: - an identification marking consisting of or inclu- the following combination(s):	and ble bit cuit contained
			8286 A= 29068 A= 290668	
			or	
			- other identification markings relating to device: with the abovementioned description	s complying θ
494	∎x85421370	\$44	Bus interface circuit, whether or not with bus conf functions, in the form of a monolithic integrated o contained in a housing bearing: - an identificat <u>ion marking consisting of or incluo</u> the following combination(s):	circuit
			03H6300         AIC         6250         Lia         6732           2782351         (9460089)         AIC         7770         NB         86980           53         C         700         Ann         290983         NCR         5380	
			53 C 718         An         29C985         NCR         5381           53 C 728         CL         PD6718         NCR         53 C           82335         CL         PD6728         NCR         53 C	
			82351         CY7C960         PBI           82352         CY7C961         PCF 85474           82353         CY7C964         R_4761 (\$           823658L         E8 688         R_4762 (\$	<u>8X11)</u>
			82375EB         E8P         216         TACT         8454           82378IB         E8P         226         TMS         38036           82423TX         FA8         216         VV         66765           82433LX         FA8         226         VV         66925	
			82C100         FA8         236         VD         33         C         9           82C300         FE         3030         VD         33         C         9           82C596         GC         132         VD         33         C         9           82C611         GC         133         VD         33         C         9	93 95
			B2C836         HDL         334112-00HQ         ND         76         C           89C106         HS         3282         Z         16C32           89C105         L         64853A         Z         86017           9460207         LIA         6396         2         2	
			or - other identification markings relating to devices with the abovecentioned description	s complying θ
495	ex85421370 ex85421971	≇45 ≇10	Interface circuit or control circuit, for a local a (LAN), in the form of a monolithic integrated circu in a housing bearing: - an identification marking consisting of or inclus the following combination(s):	uit containad
			8003         Am         79C930         COM         9026         LXT         901           80C03         Am         79C940         DP         8025         MB         8693           82586         Am         79C950         DP         83251         MB         8693           82588         Am         79C960         DP         83255         8NC         830           82590         Am         79C961         DP         83265         VD         80           82592         Am         79C965         DP         83265         VD         80           83C795         Am         79C965         DP         83265         VD         80         0           84         79C986         DP         8390         VD         83         0           83C795         Am         79C985         DP         83962         VD         83         0           Am         7909         Am         79C985         DP         83962         VD         83         0           Am         79C98         Am         79C985         VD         83         0           Am         79C98         Am         79C987         DP	50 55A C790 C 24 C 503 C 510 C 603
			or	
			- other identification markings relating to device with the abovecentioned description	s complying θ
	ex85421370 ex85421450	₹46 ₹87	Serial interface, capable of implementing the data encoding, decoding and associated control functions area network (LAN), in the form of a sonolithic in circuit contained in a housing bearing: - an identification marking consisting of or inclu- the following combination(s):	s for a local Lagrated
			8882 82501 AM 7991	
			8623 82 C 501 COM 91 C 32	

		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
497 ex85421370	*47	Arithmatic-logic unit (ALU) of C-MOS technology, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		CV2901 CV7C9115 CV7C9117 CV7C9101 CV7C9118 CV7C901	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
498 ex85421378	*48	Adaptive differentiated pulse-code-modulation encoder/decoder of C-NOS technology, comprising a transmit and receive control circuit, a microprocessor bus interface circuit and a parallel port, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		VP 06565 VP 23870 VP 23871	
		or	
		- other identification markings relating to devices complying with the abovementioned description	θ
532 ex85421370	*49	Compact disc player control circuit of C-MOS technology, providing servo-command control, signal synchronisation/demodulation and error correction, comprising a random-access memory (RAM), a digital-to-analogue converter, an analogue-to-digital converter and a microcontroller or microcomputer interface circuit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		TC 9284	
		or	
		<ul> <li>other identification merkings relating to devices complying with the abovementioned description</li> </ul>	θ
499 ax85421372	¥01	Delry circuit of C-MOS technology, comprising one static rendom-access memory (S-RAM) with a storage capacity of 8 Kbits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		M58198P	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
500 ex85421372	<b>₩</b> 82	Control circuit of C-MOS technology, for the firing of printhead pens, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		1142-0001	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ

	CN code	TARIC	Description	Raia of autonomous duty (X)
501	ex85421372	¥03	Interface circuit of C-MO8 tachnology, for a keyboard with a capacitive matrix, capable of matrix acanning and dataction, in the form of a monolithic integrated circuit contained in m housing bearing: - an identification marking conmisting of or including (one of) the following combination(m):	
			22-00958-000	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
502	ex85421372	\$84	Encoder/decoder with filter of C-NOS technology, for frequencies not exceeding 4 <u>k</u> Hz, in the fore of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			QMV 112	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
503	Bx85421372	<b>₿</b> 05	Quadruple encoder/decoder with pulse-code-modulation filters of C-MOS technology, comprising amplifiers for sidetone balance, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
			the following combination(s):	
			QNV 365	
			10	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
504	ex85421372	886	Synchronising circuit combined with a scan and signal distributor of C-MOS technology, comprising a control unit, a contact bounce alimination circuit, a 17-bit shift register and a data output formatting unit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			QNV 222	
			or	
			<ul> <li>other identification marking relating to devices complying with the abovementioned description</li> </ul>	θ
505	ex85421372 ex85421399	≇07 <u>≇01</u>	Data or image compression/decompression circuit of C-NO8 technology, in the form of a monolithic integrated circuit contained in a housing bearing: — an identification marking consisting of or including (one of) — the following combination(m):	
			1XH4-0361 1XY9-0001 CL 450 CL 950 1xxx-0301 74 ACT 8340 CL 550	
			or	
			- other identification markings relating to devices complying with ne abovementioned description	θ
506	Ex85421372	<b>\$</b> 08	Circuit of C-MOS technology, providing synchronisation and discrimination of read-mignals and generation of write mignals, in the form of a monolithic integraled circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
-			the following combination(s):	
•			HG 2255013601	

	CN code	TARIC	Description	Rate of autonomous duty (
			<ul> <li>other identification marking relating to devices complying with the abovementioned description</li> </ul>	θ
508	■x85421376	•01	Audio signal processing circuit based on standard cells of C-MOS tachnology, comprising a read only semory, non-programmable (ROM), a random-access semory (RAM), 4 analogua-to-digital converters, a serial interface, a frequency decimation circuit and a loudspeaker overload protection circuit, in the form of a monotithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			VV 27851	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
509	ex85421376	¥02	Audio digital filter based on standard calls of C-MO8 technology, with 18 channels, each of thes real-time programmable with 28 parameters or more, comprising a multiplier/accumulator (MAC), a timer and 2 random-access memories (RAMs) for the storage of parameters and of temporary processing data, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			VC 5396	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
510	85421382 85421475 85421982		Programmable logic device	θ
	85421384 85421480 85421984		Standard logic circuita	θ
534	ex85421391	•01	Remote control circuit of C-MOS technology, capable of generating 2048 different commands and controlling 32 systems, comprising a keyboard encoder, a keyboard decoder, a parallel to merial converter, a divider, a remat generator and an oscillator, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			5AA 3010	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
535	ex85421391	¥82	8-channel control circuit of C-MOS technology, for maintaining a constant electromagnetic traction force with incorporated diodem and a storage capacity of 8 bits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			UCN 5801	
			or	
			- other identification markings relating to devices complying	0

	CN code	TARIC	Description	Rate of autonomous duty (%)
536	ex85421391	¥03	<u>Controll circuit</u> for <u>Low frequency signals</u> not exceeding 20 <u>kHz</u> , with at least 16 analogue switching elements, <u>in the</u> <u>form of a monolithic integrated circuit contained in a housing</u> bearing: - an identification marking consisting of or including (one of)	
			the following combination(s):	
			TC 9164 N TC 8177 P TC 9184 P	
			or	
			<ul> <li>other identification sarkings relating to devices complying with the abovesentioned description</li> </ul>	8
537	ex85421391	\$84	DC motor control circuit, with at least one of the following caracteristics:	
			<ul> <li><u>a</u>) of C-NO8 technology, comprising a circuit to monitor power supply, a circuit to store and decode addresses and to sultiplex data, an 8-bit digital-to-analogue converter and 5 amplifiers,</li> </ul>	
			- <u>b</u> ) of N-NOS (including H-NOS) technology, comprising s digital 16-bit filter,	
			in the form of a monolithic integrated circuit contained in m	
			housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> <u>the following combination(s):</u>	
			<u>a</u> )6C 27 <u>a</u> )6C 45 <u>b</u> )LM 629	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
538	ex85421391	¥85	Control circuit of C-NOS technology, capable of processing read-signals and of controlling the motor of a compact-disc player, comprising a central processing unit (CPU) interface, an error detection/correction circuit, a read-signal demodulator, a phase locked loop (PLL) circuit and a constant-linear-velocity (CLV) controller, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including. (one of) the following combination(s):	
			CXD 1125 CXD 1138 CXD 1135 CXD 1167 WN 66271	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
539	ex85421391	¥06	Controller for servo-devices of C-MOS technology, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			KM 3782	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
548	вх85421391	*07	Control circuit of C-MOS technology, capable of controlling video-signals of a charge-coupled (CCD) image sensor, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			CXD 2183 CXD 2133	r
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ

	CN code	TARIC	Description	Rate of autonomous duty (x)
541	ex85421391	*88	Audio control circuit of C-NOS technology, capable of 2-channel (stareo) volume control, comprising a multiplexer, 2 amplifiers, a control register and a merial-to-parallel register, in the form of a monolithic integrated circuit contained in a housing bearing:	
			<ul> <li>an identification marking consisting of or including (one of) the following combination(s):</li> </ul>	
			C8 3310	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
542	ex85421391	ŧ89	Control circuit of C-MOS technology, for a microprogramme, in the form of a monolithic integrated circuit contained in a houming bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			CY 2910 CY 7C 910	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
543	ex85421391	¥10	Control circuit, of C-MO8 technology, for monitoring the voltage of random-access memories (RAMs) in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(m):	
			BQ 2201 BQ 2202 BQ 2204 BQ 2502 BQ 2503 DS 1210	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
544	ex85421391	#11	Line decoder/driver of C-MO8 technology, with an output voltage of 30, 35 or 60 V at 500 aA, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			NC 34142 UCN 5816 UCN 5817	
			or .	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
545	ex85421391	¥12	Control circuit of C-M08 technology, capable of managing the reduction of power consumption of a microprocessor or of other peripheral units, in the form of a monotithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			1028 CP	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
546	ex85421391	¥13	Pulme-code-modulation line interface circuit of C-MOS lachnology, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			<u>BT 8953A</u> C8 61575 <u>XR-T5791</u> C8 61574 <u>D8 2153</u> <u>XR-T5793</u>	
			or	
			- other identification markings relating to devices complying	

	CN code	TARIC	Description	Rate of autonomous du	ty (X)
			with the abovementioned description	θ	,
547	ex85421391	#14	Interface circuit of C-MOS technology, for at least one encoder, capable of identifying and measuring direction and displacement via signals of external sensors, comprising at least 3 counters, at least one latch of 16 or 24 bits, at least one multiplexer, at least one 8-bit parallel data buffer, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):		
			THCT 2000 THCT 12016 THCT 12024 THCT 12316		
			or		
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	
548	●x85421391	<b>1</b> 5	Interface circuit for a text data decoder of C-MOS technology, capable of data-slicing, clock regeneration and synchronisation separation, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):		<u>,</u>
			CF 72383 CF 72386		
			07		
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8	
549	ex85421391	*16	Interface and control circuit of C-MOS technology, programmable, for interfacing signals between video-graphic-array (VGA) controllers and cathode-ray tube (CRT) displays, liquid crystal displays (LCDs), light-emitting-diode (LEDs) displays or plasma-displays, capable of simultaneously controlling a CRT-display and a LCD display, comprising a digital-to-analogue video-converter with random-access memory (RAMDAC), in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of)		
			the following combination(s):		
			CL-GD6340 or		
			- other identification markings relating to devices complying		
			with the abovementioned description	θ	
550	ex85421391	<b>ŧ</b> 17	Repeater interface and control circuit of C-MOS technology, comprising 7, 8 or 12 transmission/reception interface ports, an attachment-unit interface (AUI) port and a phase locked loop (PLL) decoder, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):		
			DP 83950 DP 83955		
			07		
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	
551	ex85421391	*18	Line interface circuit of C-MOS technology, capable of transmitting and receiving data at a rate of 25,6 Mbits per second, comprising a FIFO (first in, first out) read/write memory, a 4/S-bit encoder and a S/4-bit decoder, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):		
			TXC 07125		
			or		
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	

	CN code	TARIC	Description	Rate of autonomous duty ()
528	ex85421391	<b>€</b> 19	<pre>8erial interface circuit of C-MO8 technology, comprising 2 serial ports capable of operating at a transfer rate of 28 Mbytes/<u>a</u> and 2 parallel busses, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):</pre>	
			3H5114	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
560	ex85421399	<b>€</b> 03	Universal synchronous receiver/transmitter of C-NOS technology (C-NOS USET), capable of full duplex digital voice and/or data transfer with a speed of 30 Kbits/s or more over a distance of 2 km or a speed of 160 Kbits/s or less over a distance of 1 km, comprising a modulator and data buffers, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			NC 145421 NC 145425 TP 3481 TP 3483 NC 145422 NC 145428 TP 3482	
			or	
			- other identification markings relating to devices complying with the abovementioned description	θ
561	ex85421399	<b>≇</b> 04	<ul> <li>Transmitter/receiver of C-M08 technology, with at least one of the following characteristics:</li> <li>a) capable of connecting (terminating) line rates of <u>1168</u>, <u>8448</u>, <u>34368</u>, <u>53084 or 159252</u> Kbits per second,</li> <li>b) for signate between an encoder/decoder using Manchester code (MED) or an interface unit and a twisted pair cable or a coaxial cable in a local area network (LAN),</li> <li>c) capable of data transfer at a frequency of 1,544 or 2,048 MHz, comprising an equalisar and a clock generator, in the form of a monolithic integrated circuit contained in a housing bearing:</li> <li>an identification marking consisting of or including (one of) the following combination(s):</li> </ul>	, ,
			a)B1         8952         b)83C92         b)NC         145572         c)LXT         311           a)TXC         02050         b)83C94         b)TNS         380C60         a)PN         5343         b)Am         79C98         c)LXT         304           a)PN         5344         b)CV7C971         c)LXT         318         a)C	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
562	ex85421399	≇6S	Dust-tons sulti-frequency (DTNF) receiver of C-MOS technology, capable of decoding DTNF signals to 4-bit binary data, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			N-957	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
563	ex85421399	<b>\$86</b>	Serial/parallal converter of C-MOB technology, capable of driving displays, in the form of a monolithic intergrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(m):	

CN code	TARIC	Description	Rate of autonomous du	ty (x)
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	
564 ex85421399	<b>+</b> 67	Digital-to-analogue and analogue-to-digital converter of C-MOS technology, comprising an analogue modulator capable of oversampling signals at a frequency of 1824 MHz and a filter capable of sampling signals from a digital modulator at a frequency of 512 kHz, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking commisting of or including (one of) the following combination(e):		
		NSP 58C20		
		or		
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	9	
565 ex85421399	*89	Sampling rate converter of C-MOS technology, capable of converting a clock signal with a frequency of 13,5 MHz or more but not exceeding 18 MHz into a clock signal with a frequency of 18 MHz, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(m):		
		CXD 2032		
		or		
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	
566 ex85421399 ex85421499	*10 <u>*01</u>	Disc storage unit data separator (DDS), in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):		
		DP 8465 VN 5352 WD 10 C 20 VN 5351 VN 5353 WD 10 C 21		
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	
567 ex85421399	¥11	Signal processing circuit of C-MOS technology, providing delay of scanning periods for horizontal image lines of a charge-coupled (CCD) image sensor, comprising a clockgenerator, a clamp circuit and a sample and hold circuit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):		
		CXL 1517 NN 38605A NSM 6819MS-K CXL 5564 NN 38618A MSM 6834MS-K		
		٥٢		
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8	
568 mx85421399	\$12	Digital signal synthesiser of C-MOS technology, with at least one of the following characteristics: - a) comprising random-access memories (RAMs) with a total storage capacity of 18 Kbits, with a sampling rate of 22,257 kHz and 44,1 kHz and 2 output channels, - b) comprising 32 or 48 frequency generators, a clock generator and an address generator,		
		in the form of a monolithic integrated circuit contained in m housing bearing: - an identificat <u>ion marking conmisting of or including (one of)</u> the following combination(m):		
		a)344 8 8853 b)VC 2375 b)VC 5385		
		or		
		- other identification markings relating to devices complying		

	CN code	TARIC	Description	Rate of autonomous duty (X
			with the abovementioned description	θ
569	ex85421399	≢13	Signal generator of C-MOS technology, providing synchronous pulse generation for a charged coupled (CCD) image sensor, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			CXD 1030 CXD 1217 LZ 93853 LZ 93843 LZ 95652	
			or	
			- other identification markings relating to devices complying with the abovecentioned description	θ
570	Bx85421399	₿14	Signal processing circuit of C-MOB technology, capable of processing video-signals from a charge-coupled (CCD) image sensor, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			CXA 1810 CXD 2100 CXD 2150	
		•	or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
572	ex85421399	16	Video processing circuit of C-NO8 technology, providing aspect ratio conversion and intertace conversion for luminance/chrominance signets, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			CXD 2035	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
573	ex85421399	<b>1</b> 17	Encoder/decoder of C-MOS technology, capable of encoding, decoding and interfacing serial signals having a rate of 13 Kbits per second and audio signals having a rate of 184 Kbits per second, comprising an analogue-to-digital converter, a digital-to-analogue converter, digital-pulse-code-modulation filters and an echo cancellation circuit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			VP 22828	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
574	ex85421399	•18	Decoder of C-MOB technology, for demodulating and demultiplexing of starmo signals, comprising an interface circuit of a digital-to-analogue converter having an output clock signal of 8,192 or 16,384 MHz, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			CF 78888 <b>CF 7889</b> 1	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ

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	CN code	TARIC	Description	Rate of sutonomous duty (X)
575	ex85421399	ŧ19	Encoder/decoder of C-MOS technology, for the conversion of data into NRZ (Non-Return-to-Zero) format or RLL (Run-Length-Limited) format, in the form of a monotithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			61158 CL-8H118	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
576	ex85421399	*20	Audio decoder of C-MO8 technology, cepable of decoding and desultiplexing audio signals and digital data, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			C8 8411 C8 8412	
			or	
			<ul> <li>other identification merkings relating to devices complying with the abovementioned description</li> </ul>	θ
577	ex85421389	*21	Adaptive differentiated pulse-code-sodulation circuit of C-MOS technology, for encoding/decoding speech and date and capable of full <u>or</u> half duplex date-transfer, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	· · · · · · · · · · · · · · · · · · ·
			BBSP4CH <u>MT 9125</u> SC 11360 B& 8110 <u>MT 9126</u> SC 11362	
			07	
			<ul> <li>other identification merkings relating to devices complying with the abovementioned description</li> </ul>	θ
578	ex85421389	*22	Audio encoder of C-MOS technology, capable of encoding and multiplexing mudio mignals and digital data, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking conmisting of or including (one of)</u> the following combination(s):	
			CS 8401 CS 8402	
			07	
			- other identification markings relating to devices complying with the abovementioned description	θ
579	ex85421399	123	Encoder/decoder of N-MOS (including H-MOS) technology, for the conversion of data into serial or parallel signals, comprising an arithmatic logic unit (ALU) and a read only memory, non-programmable (ROM), in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			TWS 38020 TWS 38021	
			70	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
580	ex85421399	824	Phase-locked loop (PLL) clock circuit of C-MOS technology, capable of synchronisation or sultiplication of frequencies not exceeding 160 MHz, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	,
			74 FCT 3888915 NC 88915 NC 88920	
	· · · ·		74 FCT 88915 NC 88916 NC 88PL117	

	CN code	TARIC	Description	Rate of autonomous duty (
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
581	в×85421399	*26	Clock/calandar circuit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			58274 NC 146818 NN 58174 A V 3023 N 3002 NCCS 146818 V 3021 N 3003 NN 58187 V 3022	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
582	ex85421399	€27	Address generator of C-MO8 technology, for the address generation of a source image and a target image during image manipulation, in the form of a monelithic integrated circuit contained in a housing bearing:	
•			<ul> <li>- an identification marking consisting of or including (one of) the following combination(s):</li> </ul>	
			THC 2382	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
583	ex85421399	¥28	Delineation circuit of C-MO8 technology, capable of extracting and inserting asynchronous transfer mode (ATM) calls from and into a line interface signal, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			TXC 85158	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
584	ex85421399	\$29	Modulator/demodulator of C-NO8 technology (C-NO8-Modem), only for half duplex transfer of image telegraphy (facsimile) at a rate of 300, 2400, 4800, 7200 or 9600 bits per second, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			TC 35128	
			or .	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
585	ex85421399	<b>8</b> 30	Modulator/demodulator of C-MO8 technology (C-MO8-Modem), for full duplex data-transfer at a rate not exceeding 2400 bits per second and for half duplex transfer of image telegraphy (facsimile) at a rate not exceeding 9600 bits per second, in the form of a monolithic integrated circuit contained in m housing bearing: - an identification marking commisting of or including (one of) the following combination(s):	
			SC 11044 SC 11046 SC 11054 SC 11055	
			0 r	
			- other identification markings relating to devices complying	

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CN code	TARIC	Description	Rate of autonomous duty (%)
586 ex85421399 ex85421998	≢31 <u>≢07</u>	Read channel circuit, providing read/write and servo demodulator functions, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(e):	
		32P4730 81C020 <u>CL-8H 3385</u>	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
587 ex85421399	<b>₩</b> 32	Generator of C-NOS technology, for a user-definable cursor, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		Bi431	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	6
588 ax85421399 <u>ex85421499</u> ax85421998	#33 #82 #88	Smoke detector operating in a temperature range of -20 °C or more but not exceeding 80°C, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		NC 14467 NC 14471 C8 235 NC 14468 NC 145010 V 24216	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
589 Bx85421399	¥34	Video-line coab filter of C-NOS technology, capable of digital signal luminance/chrominance separation, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
		the following combination(s):	
		CXD 2024 CXD 2030 <u>NC 141626</u>	
		70	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	0
591 Bx85421399	\$36	Echo and reverberation module, comprising a multipliar/accumulator, two random-access memories (RAMs) and a read only memory, non-programmable (ROM), in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		VC5344 VC5888	
		or	
		<ul> <li>other identification serkings relating to devices complying with the sbovementioned description</li> </ul>	6
592 <b>₽x85421399</b>	¥37	Digitally controlled potentioneter of C-MO8 or N-MO8 (including H-MO8) technology, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		8C 76013 X 9104 X 9313 X 9C103 X 9102 X 9311 X 9503 X 9C104 X 9103 X 9312 X 9C102 X 9C503	
		or	
		- other identification workings relating to devices complying	

	CN code	TARIC	Description	Rate of autonomous duty
	-		with the abovementioned description	0
593	вx85421399	*38	8 x 16-bit differential crosspoint switch of C-NO8 technology, capable of switching at a frequency of 20 NHz, in the form of a monolithic integrated circuit contained in a housing earing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			MT 8816	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
595	ex85421399	≇48	Transmitter/receiver of C-M08 technology, for the reception and transmission of data at a speed of 51,84 or 44,738 Mbits/s, comprising a NRZ (Non-Return-to-Zero) data-format encoder, a decoder, an adaptive equaliser associated with an automatic gain controller, a receive control circuit, an amitter control circuit and a clock recovery circuit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			TXC 82828 TXC 82821	
			0 F	
_			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
596	ex85421399	#41	Video noise reduction circuit of C-MOS technology, comprising inputs for 8-bit chrominance and luminance signels, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			CXD 2036	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
597	ex85421399	142	FM starse sound generator of C-MOS technology, comprising a phase generator, a timer, a registers mray, a bus controller and at least 1 accumulator, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			VNF 262 VNF 289	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
598	ex85421399	\$43	Decoder of C-MOS technology, capable of arror correction, comprising a serial bus and a descrambling circuit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			VES 5453	
			٥٢	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ

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	CN code	TARIC	Description	Rate of autonomous duty (X)
599	ex85421399	844	Demodulator of C-NO8 technology, comprising reception filters, polyphase filters, a clock synchronisation circuit and an automatic gain controllar, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking commisting of or including (one of) the following combination(s):	
			VEB 4133	
			or	
			<ul> <li>other identification earkings relating to devices complying with the abovementioned description</li> </ul>	θ
600	ex85421399	\$45	Infrared transmitter/receiver of C-MOS technology, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
			the following combination(s):	
			C8 8138	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
602	€x85421399	<b>₹4</b> ?	Digital-to-analogue converter of C-MOS technology, with at Least one of the following characteristics: - a) with a capacity of 8 bits, with an output buffer amplifier, a serial interface circuit and at least 12 channels, - b) with a capacity of 8 bits, capable of double buffering 8-bit words, - c) with a capacity of 8 bits, capable of converting serial data input towards 36 output channels, - d) single or triple converter, with at least one random-access manory (RAMDAC), having one or more colour patette registers, - e) with a dynamic sudio range of 90 dB or more, - f) 8- <u>9-</u> or 10-bit video converter, with <u>at least 3</u> channels for the separate conversion of colour signals, - g) with a capacity of 16 bits, capable of converting data in floating point form, comprising a 18-bit digital-to-analogue converter, and a shift register, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(m): a)M 62352P d)ATT 20C497 d)MU 9C9768 e)CS 4328 b)DAC 8030 d)Bt445 d)SC 11482 e)CXD 2564	-
			b)DAC 8831       d)Bt451       d)SC 11483       m)PD 6376         b)DAC 8832       d)Bt458       d)SC 11484       m)TMS 57818         c)NB 883448       d)Bt459       d)SC 11485       f)Bt 857         d)35786616       d)Bt466       d)SC 11487       f)CXD 1178         d)35786611       d)Bt461       d)SC 11489       f)CXD 2367R         d)35786012       d)Bt462       d)SC 15825       f)CXD 2389         d)ATT 28C498       d)Bt467       d)TR 9C1718       g)VAC 513	
			d)ATT 20C402 d)Bl473 d)TVP 3020 d)ATT 20C493 d)Bl475 d)TVP 3030	
			or - other identification merkings relating to devices complying	
	00.00		with the abovesentioned description	θ
603	ex85421399	*48	<ul> <li>Analogue-to-digital converter, with at least one of the following characteristics:</li> <li>a) 8-bit parallel converter of C-MOS technology,</li> <li>b) with a capacity of 18 or 28 bits of C-MOS technology, comprising a synchronisation circuit, 2 modulators, 2 digital filters, a 4-bit digital-to-analogue converter and an amplifier,</li> <li>c) 18-, 18- or 28-bit stereo audio converter of C-MOS technology,</li> <li>d) with a capacity of 18 bits, comprising a digital filter</li> </ul>	
			<ul> <li>with a passband of 45,5 kHz at 3 dB,</li> <li>- e) capable of driving a liquid crystal (LCD) or light smitting diode (LED) display with not more 4 digits,</li> <li>- f) 8-bit video converter of C-MOS technology, comprising B</li> </ul>	

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CN code	TARIC	Description	Rate of autonomous duty (%)
		synchronising clasp circuit, in the form of a monolithic integrated circuit contained in m housing bearing:	
		- an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		a)IDT 75C48       c)C8 5339       e)ICL 7137         a)IDT 75C58       c)C8 5349       e)MAX 130         a)MP 7683       d)DSP 56ADC16       e)MAX 131         a)MP 7684       e)HI 7131       e)MAX 133         b)C8 5516       e)HI 7133       e)MAX 138         b)C8 5520       e)ICL 7106       e)MAX 139         c)C8 5326       e)ICL 7107       e)MAX 136         c)C8 5327       e)ICL 7116       e)MAX 136         c)C8 5328       e)ICL 7117       f)CXD 1176         c)C8 5328       e)ICL 7126       f)CXD 2300         c)C8 5336       e)ICL 7136	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
604 ex85421399	•49	Data segmentation or reasonably circuit of C-MOS technology, providing fragmentation of 16382 packats of 8- or 16-bit words into cells or providing reasonably of these cells in 16382 packets of 8- or 16-bit words, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		TXC 05501 TXC 05601	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
605 ex85421399	¥50	Subscriber line audio-processing circuit (SLAC) of C-NOS technology, comprising 2 digital signal processors, at least 1 analogue-to-digital converter and at least 1 digital-to-analogue converter, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s): Am 7901 Am 7905 Am 79002 Am 79003 Am 79004	
		07	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ.
606 ex85421399	₹51	Signal synthesiser of N-MOS (including H-MOS) technology with a frequency generator, a memory of 15 instrumental tones, a digital-to-analogue converter and a quartz oscillator, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s): VM 2413	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
607 ex85421399	\$52	Video processing circuit of C-MOS technology, having subpicture display (picture-in-picture) functions, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (onm of)</u> the following combination(s):	
		CXD 2031R CXD 2033	
		07	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ.

	TARIC	Description	Rate of autonomous duty (%)
608 ex85421399	•53	Audio decoder of C-NOS technology, capable of decoding and decompressing audio signals at a rate per second not exceeding 15 Mbits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(a):	
		74 ACT 6350 TH8 320AV120	
		or	
		<ul> <li>other identification merkings relating to devices complying with the abovementioned description</li> </ul>	θ
689 ex85421399 ex85421998	<b>\$54</b> ₹21	Clock generator, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		D4661CL         CV 2257         ICD 2828         MK 1448           82 C 402         CV 2201         IC8 1394         MK 1448           AV 9129         CV78091         IC8 2494         M8M 5547           Bt 438         CV78992         IC8 9064         PCLK 1           Bt 439         CV78993         IC8 9181         PCLK 2           CXD 1035         DP 8531         LZ 93F33         8C 11410           CXD 1252         DP 8532         LZ 93F33         8C 11411           CXD 1255         DP 83241         LZ 93N61         8C 11412           CY 2254         ICD 2023         MK 1448         TCK 9002           CY 2255         ICD 2827         NK 1442         VD 90 C 61	
		or - other identification markings relating to devices complying with the abovementioned description	θ
610 ex85421399	\$55	Circuit for the recording and reproduction of speech of C-MOS technology, working at a speed of 8 Kbits/sec or more, with at least one of the following caracteristics: - a) comprising an amplifier and a 18-bit digital-to-analogue converter, - b) comprising a memory interface circuit, an encoding/decoding circuit, a central processing unit (CPU) interface, - c) comprising a 12-bit digitat-to-analogue converter, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		a)T 8668 a)TC 8838 b)TC 88481 c)M5M6388 or or athen identification packing colotion to device compluing	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
553 ex85421399	•56	Dual analogue-to-digital converter and digital receiver of C-NOS technology, cosprising an arror correction and signal decoding circuit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
,		AD 6462	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
554 ex85421399	₹57	Desodulator of C-MO8 technology, capable of receiving and demodulating a data stream with a transfer rate of 38 Mbits/s, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	,
		MDA 8866	

	CN code	TARIC	Description	Rate of autonomous duty (%)
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
28 <b>4</b> b	Bx85421481	<b>#</b> 01	Wafer, not yet cut into chips, <u>only</u> for use in the sanufacture of goods of subheading <u>85421415 to</u> <u>85421442, 85421475 or 85421488</u> (s)	θ
284e	Bx85421485	•01	Monolithic integrated circuit not contained in a housing (chip), only for use in the manufacture of goods of subheading 85421415 to 85421442, 85421475 or 85421480 (a)	8
614	ex85421450	¥01	Error correction and detection unit (ECDU) of bipolar lechnology, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			2966 74 AS 632 74 F 636 74 LS 631 54 AS 632 74 AS 634 74 F 631 DP 8466 54 AS 634 74 AS 6364 74 LS 638	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
615	ex85421450	₿02	Control and/or management circuit for memories (including buffers) of bipoler technology, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			AM 2965 DP 8469 DP 8429 AM 2966 DP 8419 MB 1422 DP 8408 DP 8428 SN 74 S 489	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
616	6x85421450	¥63	Control circuit for disc storage units of bipolar technology, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			A.MPA 1850	
			<ul> <li>other identification merkings relating to devices complying with the abovementioned description</li> </ul>	θ
617	ex85421458	≇⊕4	Controller of bipolar technology, for controlling read/write signals from magnetic heads in disc storage units, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
			<u>the following combination(s):</u> 32 R 2020 R 32 R 510 A 32 R 522	
			32 R 2821 R 32 R 5121	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
618	ex85421450	≇05	Bus interface circuit of bipolar technology, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	· · · · · · · · · · · · · · · · · · ·
			82 A 203 82 A 304 AN 29821 AN 29825 AN 29845 82 A 204 82 A 305 AN 29822 AM 29826 RVT 121 82 A 205 82 A 436 AN 29823 AM 29843 82 A 303 82 A 442 AM 29824 AM 29844	
			or	

CN code	TARIC	Description	Rate of autono∎ous duty (%)
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
619 Bx85421458	106	Analogue-digital sonolithic integrated circuit of bipolar tachnology for interface signals batesen the hard-disc, easory unit and the central processing unit (CPU), contained in a housing bearing:	
		<ul> <li>- an identification sarking consisting of or including (one of) the following combination(s):</li> </ul>	
		AD 581 C	
		or	
		<ul> <li>other identification merkings relating to devices complying with the abovementioned description</li> </ul>	9
630 ex85421450	≇68	Power supply control <u>circuit</u> for a microcontroller or microcomputer, of bipoler technology, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		AN 8369	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
628 Bx85421468	<b>₽</b> 01	Control circuit of TTL technology, for the firing of magnetic print hammers, in the form of a monolithic integrated circuit contmined in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		801379-002 810751-001	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
631 ex85421491	≇01	Control circuit of bipolar tachnology, capable of driving laser diodes or other light-saitting diodes (LEDs), in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		IDA 07318	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
632 ex85421491	\$ <del>6</del> 3	Control circuit of bipolar tachnology, capable of controlling 2 discrete power field-affect transistor (FET) devices, in the form of a monolithic integrated circuit contained in m housing bearing:	
		<ul> <li>- an identification marking consisting of or including (one of) the following combination(s):</li> </ul>	
		27473	
		ar	
		- $\sigma^{ab}$ - identification markings relating to devices complying $\omega$ in the abovementioned description	θ
633 ex85421491	₿₿4	Driver circuit for write signals for magnetic taps storage units, of bipolar technology, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		VT 211	
		10	

CN code	TARIC	Description	Rate of autonomous duty (
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	e
634 ex85421491	<b>#</b> 05	Control circuit of bipolar technology, capable of driving a PNP power transistor, having a S V standby-power-regulation and a 2,5 V power output reference, in the form of a monolithic integrated circuit contained in a housing baaring: - an identification marking consisting of or including (one of) the following combination(s):	
		7815 FB	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
635 ex85421491	¥86	Control circuit of bipoler technology, capable of driving 2 pulse-code-modulation lines at a transfer rate not exceeding 10 Mbits/s, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
•		XRT5675	
		or	
		- other identification markings relating to devices complying	
		with the abovementioned description	θ
636 ex85421491	*07	Interface and control circuit of bipolar technology, for interfacing signals between data processing machines and coaxial cable in a local area network (LAN), in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		AM 7996 DP 8392	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	e
637 Bx85421491	<b>≇</b> 88	Interface circuit for the synchronisation of data flow from a disc storage unit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		DP 8462	
		07	
		- other identification markings relating to devices complying	
		with the abovementioned description	θ
640 ex85421499	¥83	Transmitter of bipolar technology, providing encoding/conversion of parallel data/commands into serial format, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		AN 79168 AN 7968 AN 79865	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
641 ex85421499	¥84	Receiver of bipoler technology, providing decoding/conversion of serial data/comeands into parallel format, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification merking consisting of or including (one of)	
		the following combination(s):	
		AM 79169 AM 7969 AM 79866	

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CN code	TARIC	Description	Rate of autono≡ous duty (%)
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ.
542 ex85421499	∎85	Transmitter or receiver of bipolar lechnology, capable of serial data communication at a rate of 110 Mbits or more but not exceeding 1,4 Gbits per second, in the form of a monotithic integrated circuit contained in a housing basering: - an identification marking consisting of or including (one of) the following combination(m):	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~
		HDMP 1882 HDMP 1884	
		07	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
643 Bx85421499	<b>₽</b> 87	Pulse-code-modulation (PCN) transmitter/receiver of bipolar technology, capable of connecting (terminating) line rates of 2048 or 8448 Mbits per second, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		XRT 5683 XRT 56185	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
644 ex85421499	<b>\$</b> 88	Audio digital-to-analogue converter of bipolar technology, with a dynamic range of 98 dB or more, comprising an internal voltage reference, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		PCN 63P	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
645 ex85421499	¥89	12-bit analogue-to-digital convertar of bipolar tachnology, incorporating a voltage reference and clock, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking conmisting of or including (one of) the following combination(m):	
		AD 574 A	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
646 ex85421499	≇10	9-bit analogue-to-digital converter of bipolar technology, in the form of a monolithic integrated circuit contained in m housing bearing:	
		<ul> <li>- an identification marking conmisting of or including (one of) the following combination(m):</li> </ul>	
		TDC 1049	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
647 ex85421499	<b>#</b> 11	12-bit digital-to-analogue converter of bipolar technology, in the form of a monotithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
		the following combination(m):	
		100 1012	

	CN code	TARIC	Description	Rate of autonomous duty (X
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	6
648	ax85421499	•13	18-bit digital-to-analogue convertar of bipolar tachnology, comprising an internal voltage reference, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	-
			DAC 712	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
649	ax85421499	<b>*14</b>	Programmable amplifier of bipolar technology, for signals on a digital communications bus, in the form of monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			H8 3182	
			n	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
650	ex85421499	<b>*</b> 15	Monolithic integrated circuit (read/write data processor circuit) for the amplification and conversion of read signals and conversion of write signals for disc <u>storage units</u> , contained in a housing bearing: - an identificat <u>ion aarking consisting of or including (one of)</u> the following combination(s):	
			32 P 3800 32 P 3813 32 P 540 32 P 541 61347-802	
			or	
			<ul> <li>other identification warkings relating to devices complying with the abovementioned description</li> </ul>	θ
651	8x85421499	<b>#</b> 16	Demodulator/tone-decoder of bipolar technology for frequency decoding, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			XR 2211	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
652	ex85421499	*17	2-, 4-, 8- or 8-channel read/write signal generator for disc <u>storage units</u> , in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			32 R 117 32 R 501	
			0r	
			<ul> <li>other identification sarkings relating to devices complying with the abovementioned description</li> </ul>	0
653	ex85421499	<b>*</b> 18	Function generator of bipolar technology for the generation of variable wave-forms, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			XR 2286 XR 8838	
			or	
			- other identification markings relating to devices complying	

CN code	TARIC	Description	Raia of autonomous	duty (X)
		with the abovementioned description	8	,
654 ex85421499	¥19	Data-synchroniser for tape-reading units of bipolar technology, in the form of a monolithic integrated circuit contained in a housing bearing:		
		<ul> <li>an identification marking consisting of or including (one of) the following combination(s):</li> </ul>		
		VT 218		
		0 F		
		<ul> <li>other identification markings ratating to devices complying with the abovementioned description</li> </ul>	0	
655 Bx85421499	¥20	Data synchroniser and encoder/decoder of bipoler technology, in the form of a monolithic integrated circuit contained in a housing bearing:		
		<ul> <li>an identification marking consisting of or including (one of) the following combination(s):</li> </ul>		
		32 D 532 32 D 535 32 D 5393		
		or		
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	
656 ex85421499	₹23	Digitise and data-separation circuit of bipolar technology, comprising a phase-locked loop circuit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificati <u>on marking consisting of or including (one of)</u> the following combination(s):		
		SN 28962		
		10		
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	
657 ex85421499	\$24	Differential crosspoint switch of bipolar technology, capable of switching at a data rate per second of 800 Mbits, in the form of a monolithic integrated circuit contained in a housing baseing:		
		bearing: - an identificat <u>ion marking consisting of or including (one of)</u> <u>the_following combination(s):</u>		
		8 2824		
		or		
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ	
658 ex85421499	¥25	Decoder of bipoler technology, for chrominance signel decoding, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of)		
		<u>the following combination(s):</u> NS2725FP		
		or		
		<ul> <li>other identification markings relating to devicem complying with the abovementioned description</li> </ul>	θ	
659 ex85421499	126	Clock distribution circuit of bipolar tachnology, with inputs for transistor-transistor logic (TTL) signals or anittar-coupled logic (ECL) signals and outputs for transistor-transistor logic (TTL) signals, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):		,
		6369269 MC 100H640 MC 100H644 MC 10H641 6460112 MC 100H641 MC 10H640 MC 10H644		
		or		

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CN code	TARIC	Description	Raie of autono∎ous duty (%)
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ.
660 ex85421499	*27	Transmitter/receiver of bipolar technology, for bidirectional differential buses, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(m):	
		D8 36277	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
661 ex85421499	*28	Transmitter/receiver of bipolar technology, capable of converting data into serial or parallel format and serial data transfer at a rate not exceeding 200 megabytes per second, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		MC 1008X1451	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
662 ex85421499	*29	Transmitter/receiver of bipoler technology, capable of data transmission over a twisted-pair cable, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		A= 26L\$38 DP 83220	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
663 ex85421499	¥30	Prescaler of bipolar technology, having an input frequency not exceeding 2,8 GHz and a selectable 32/33, 64/65, 64/128 or 128/128 divide ratio, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(m):	
		NC 12022 NC 12034 NC 12053 SC 12022 NC 12032 NC 12052 NC 12089	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
664 ax85421499	*31	Receiver/transmitter of Schottky technology, for Manchester-coded data, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		TNS 38051 TNS 38053 TN8 38054	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
638 ex85421499	<b>₩</b> 32	Radio frequency (RF) transmitter/receiver, comprising 2 synthesizers each with a voltage controlled oscillator (VCO), 2 mixers and a serial interface circuit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	۴
		AD 6431	

	CN code	TARIC	Description	Rate of autonomous duty (X)
			or	
		_	<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
665	ax85421981	<b>#</b> 61	Wafer, not yet cut into chips, of gallium arsenide (GaAs) semiconductor material, consisting only of clock and data recovery circuits, for use in the manufacture of goods of subhanding <u>85421998</u> contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			GD 16042 GD 16043	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	θ
666	ex85421901	ŧ82	Wafer, not yet cut into chips, of gallium ersenide (GaAs) semiconductor material, consisting only of multiplexer circuits, capable of multiplexing 4 data flows into a single data flow, comprising a phase-tocked loop (PLL) circuit and lamar diode drivers, for use in the manufacture of goods of subheading <u>85421998</u> contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			GD 16854	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	8
667	<b>ex85421901</b>	*83	Wafer, not yet cut into chips, of gallium arsenide (GmAs) semiconductor material, consisting only of transmitter/receivers, providing serial data communication at a rate of 622 Mbits per second, for use in the manufacture of goods of subheading <u>85421998</u> contained in a housing bearing: - an identification marking consisting of or including (onu of) the following combination(s):	
			GD 16864	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	8
668	ex85421981	₹84	Wafer, not yet cut into chips, of gallium arsenide (GaAs) semiconductor material, consisting only of dual buffers for ECL/TTL level signals, for use in the manufacture of goods of subheading <u>85421998</u> contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			GD 18225	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	8
669	ex85421901	\$05	Wafer, not yet cut into chips, of gallium arsenide (GaAs) semiconductor material, consisting only of multiplexers or demultiplexers, providing differential ECL level data input/output at a rate of 622 Mbits per second and TTL input/output signals at a rate of 78 Mbits per second, for use in the manufacture of goods of subheading <u>85421998</u> contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			GD 16131 GD 16132	
			or	
			- other identification markings relating to devices complying	

	CN code	TARIC	Description	Rate of autonomous duty (%
284c	ex85421901	¥12	Wefer, not yet cut into chips, <u>only</u> for use in the manufacture of goods of subheading <u>85421922 to</u> <u>85421962, 85421982 or 85421984</u> (m)	θ
670	ex85421985	¥01	Control and interface circuit of BiNO8 technology, capable of controlling communication between a microprocessor, bus control circuits and a memory control circuit, in the form of a monolithic integrated circuit not contained in a housing (chip), for use in the menufacture of goods of subheading <u>85421971</u> contained in a housing bearing: - an identification marking commisting of or including (one of) the following combination(s):	
			1867432 1 <b>8674</b> 33 5868759 5868781	
			10	
			<ul> <li>other identification serkings relating to devices complying with the abovementioned description (a)</li> </ul>	θ
671	ex85421905	<b>#</b> 82	Bus control circuit of BiM08 technology, in the form of m monolithic integrated circuit not contained in m housing (chip), for use in the menufacture of goods of subheading <u>85421971</u> contained in m housing bearing: - an identification marking consisting of or including (one of) the following combination(m):	
			1667429 1867430 5868755 5866757	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	θ
672	cx85421905	¥83	Nemory control circuit of BiNOS technology, in the form of a monolithic integrated circuit not contained in a housing (chip), for use in the manufacture of goods of subheading <u>85424090</u> contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			1667428 1667463	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	θ
673	ex85421985	₹04	Messurement circuit of gallium ersenidm (GaAs) semiconductor material, capable of measuring signal propagation times on transmission lines, comprising 2 asynchronous counters, 4 comparators, a clock generator and an oscillator, in the form of a monolithic integrated circuit not contained in a housing (chip), for use in the manufacture of goods of subheading <u>85421998</u> contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			GIGA TDR	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (m)</li> </ul>	θ
674	ex85421905	# <del>8</del> 5	Clock and data recovery circuit of gallius arsenide (GaAs) semiconductor material, in the form of a monolithic integrated circuit not contained in a housing (chip), for use in the manufacture of goods of subheading <u>85421998</u> contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			GD 16842 GD 18843	
			or	•
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	θ

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675	ex85421985	¥86	Transition (consists of allies provide (CoAc) and added	
			Transmitter/receiver of gallium arsenide (GaAs) semiconductor material, providing synchronous/asynchronous data communication at a rate per second of 622 Mbits or more but not exceeding 2,5 Gbits, in the form of a monolithic integrated circuit not contained in a housing (chip), for use in the manufacture of goods of subheading <u>85421998</u> contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			GIGA BOA GIGA MATCH	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	8
676	ex85421985	•87	Multiplexer of gallium ersenide (GeAs) semiconductor material, capable of multiplexing 4 date flows into a single date flow, comprising a phase-locked loop (PLL) circuit and laser diode drivers, in the form of a monolithic integrated circuit not contained in a housing (chip), for use in the manufacture of goods of subheading <u>85421998</u> contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			GD 16854	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	8
677	∎x85421985	•68	Divider/detector circuit of gallium arsenide (GaAs) semiconductor material, capable of synthesizing fraquencies in the range of 50 MHz to 1700 MHz, comprising a prescaler, a frequency divider and a phase/frequency detector, in the form of a monolithic integrated circuit not contained in a housing (chip), for use in the manufacture of goods of subheading <u>85421998</u> contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			GIGA FSS	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	θ
284f	ex85421905	¥10	Monolithic integrated circuit not contained in a housing (chip), only for use in the manufacture of goods of subheading 85421922 to 85421962, 85421982 or 85421984 (a)	θ
693	Bx85421972	<b>≇</b> ⊕1	Flow meter interface of BiMOS technology, comprising 16	
			amplifiers, 3 digital-to-analogue converters, an analogua-to-digital converter, filters, a sample and hold circuit, an oscillator, a phase locked loop (PLL) circuit and a serial interface circuit for a microprocessor, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			AD75827	
			0 F	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
694	Bx85421972	*82	Digital-to-analogue and analogue-to-digital converter of BiMO8 technology, comprising sample and hold circuits, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	

	CN code	TARIC	Description	Rate of autonomous duty
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
695	ex85421972	•83	Circuit of BiMOB technology, for the recording and reproduction of data, operating at a rate not exceeding 112 Mbits/sec, comprising an ancoding circuit, a decoding circuit, an analogue-to-digital converter, a digital equatiser filter and a random-access assory (RAM), in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			6460168 (8189294)	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
699	ex85421992	*82	Driver circuit of gallium preenide (GaAs) semiconductor material, for controlling laser diodes or other light-emitting diodes (LEDs), in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) _ the following combination(m):	
			166875 1 <b>66878</b>	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
700	ex85421992	≇04	Subscriber line interface circuit (8LIC) of dielectric isolation technology, with an internal programmed constant line current, comprising a resistor network and an operational amplifier, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(a):	
			HC 5502 HC 5504	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
703	ex85421998	¥01	Analogua-to-digital signal converter, comprising amplifiers, digital-to-analogue and analogua-to-digital converters with a supply voltage of 12 V (±18 %) and a digital serial interface with an asynchronous receiver/transmitter, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			AD 75002	
			or	
			- other identification markings relating to devices complying with the abovementioned description	θ
704	ex85421998	•63	Frequency synthesiser of BiMO8 technology, capable of synchronising and dividing of frequencies, comprising 1 or 2 phase-locked loop circuits and 1 or 2 prescalers with an operating frequency of 10 MHz or more but not exceeding 2,5 GHz, in the form of a sonolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			NB 1501 NB 1502 NB 1509 NB 1511 NB 1518	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ

CN co	de	TARIC	Description	Rate of autono∎ous duty (%)
785 ax854	21998	\$04	Encoder/decoder of BiMO8 technology, providing data conversion and separation and a data transfer rate of 50 Mbits per second, comprising a read pulse detector and a frequency synthesiser/synchroniser, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			HD 153031 RF	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
706 ex854	21998	¥85	Clock recovery circuit, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			DP 83231	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
707 ex854	21998	¥10	Hall effect sensor of BiMOS technology, capable of communicating over a 2-wire bus, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			UCN 3055U UCS 3055U	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
768 ex854	21998	¥11	Transmitter or receiver of gallium arsenide (GaAs) semiconductor material, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			GA 9011 GA 9012	
			07	
			- other identification markings relating to devices complying	
			with the abovementioned description	θ
789 ex854	21998	<b>#</b> 13	Digital-to-analogue converter of gallium arsenide (GaAs) semiconductor material, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			or - other identification markings relating to devices complying	
			with the abovementioned description	θ
710 ex854	21998	<b>#</b> 16	Clock and data recovery circuit of gallium arsenide (GaAs) semiconductor material, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
			the following combination(s):	1
			166040	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ

	CN code	TARIC	Description	Rate of autonomous duty (
711 e	ex85421998	<b>≇</b> 17	Comparator circuit of gallium arsanida (GaAs) maniconductor material, for phase and frequency differences of frequencies not exceeding 1 GHz, in the form of a monotithic integrated circuit contained in a housing bearing: - an iden ification marking commisting of or including (one of) the following combination(a):	
			166044	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
697	ex85421998	¥19	Transmitter/receiver of BiM08 technology, in the form of m monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking conmisting of or including (one of)</u> the following combination(m):	
			74ABT543         CY7B956         8N 74         BCT         2423           CY7B9392         D8         36959         8N 74         BCT         2424           CY7B923         D8         3884         SN 74         BCT         2425           CY7B933         D8         3886         8N 75         LBC         976           CY7B955         SN 74         BCT         2428	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	6
713	ex85421998	\$20	Quadruple digital-to-analogue converter with a capacity of 12 bits, of BiMOS technology, in the form of a monolithic integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			AD 664	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
714	ex85421998	\$22	Clock generator/buffer of gallius arsenide (GaAs) semiconductor material, capable of frequency synchronisation or multiplication, in the form of a monolithic integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			GA 1888 GA 1886 GA 1888 GA 1118 Ga 1885 ga 1887 ga 1889 ga 1218	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
715	ex85423010	₹01	Wafer, not yet cut into chips, of gallium mrsanide (GaAs) semiconductor material, consisting only of transimpedence amplifiers, operating at a bandwidth of 900 MHz, having m resistance not exceeding 4 kOhm, for use in the manufacture of goods of subheading <u>85423030</u> contained in a housing bearing:	
			<ul> <li>an identification marking consisting of or including (one of) the following combination(s):</li> </ul>	
			GD 16885	
			or	

	CN code	TARIC	Description	Rate of autonomous duty (%)
716	BX85423818	¥82	Wefer, not yet cut into chips, of gellium ersenide (GaAs) semiconductor material, consisting only of laser diode control circuits, providing an output current in a range of 10 mA to 70 mA at a power supply of -5 V (±1 %), for use in the manufacture of goods of subhaeding <u>85423878</u> contained in a housing bearing:	
			<ul> <li>- an identification marking consisting of or including (one of) the following combination(s):</li> </ul>	
			GD 16077	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	θ
717	ex85423818	•63	Wafar, not yet cut into chips, of gallium armenide (GaAs) memiconductor material, consisting only of amplifiers with a typical output power of 25 dBm in m fraquency range of 1850 MHz to 1950 MHz, comprising rediofraquency (RF) switches, for use in the menufacture of goods of subheading <u>85423030</u> contained in m housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			6D 12833	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	θ
718 ex85423010	ex85423010	*04	Wafer, not yet cut into chips, of gallium arsenide (GaAs) semiconductor material, consisting only of dual amplifiers with a typical gain of 18 dB at a frequency of 1,5 GHz, for use in the manufacture of goods of subheading <u>85423030</u> contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			GD 10012	
			10	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	6
719	ex85423818	¥85	Wafer, not yet cut into chips, consisting only of amplifiers with an input current not exceeding 80 nA, for use in the manufacture of goods of subheading <u>85423030</u> contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			INA 101 OPA 111 OPA 121 OPA 2111	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	e
720 e	ex85423010	¥86	Wafer, not yet cut into chips, consisting only of amplifiers with a programmable gain factor, for use in the manufacture of goods of subheading <u>85423030</u> contained in a housing bmaring:	
			<ul> <li>an identification marking consisting of or including (one of) the following combination(s):</li> </ul>	
			3686G	
			or	
	•		<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	θ

	CN code	TARIC	Description	Rate of autonomous duty (%)
721	ex85423010	•07	Wafer, not yet cut into chip <b>s, consisting of speech</b> circuits of C-MOS technology, for use in the senufacture of goods of subheading 85423895 contained in a housing beering: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(m):	
			AS 2528 AS 2531	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description (a)</li> </ul>	8
722	ex85423020	<b>*</b> 01	Asplifier, in the fors of a sonolithic integrated analogue circuit not contained in a housing (chip), for use in the sanufacture of products falling within subheading 902140 00 (a)	θ
723	ex85423020	¥02	Amplifier of bipolar technology, for the amplification of read/write signals of thin file magnetic heads, in the form of a aonolithic integrated analogue circuit not contained in a housing (chip), for use in the manufacture of disc storage units (a)	8
724	ex85423020	¥03	FN receiver/amplifier of bipolar tachnology, in the form of an monolithic integrated analogue circuit not contained in a housing (chip), for use in the manufacture of products falling within subheading 90214000 (a)	θ
725	ex85423020	≇ θ 4	Audio recording/reproducing circuit of C-MO8 technology, capable of direct analogue storage of audio data, comprising an electrically erasable, programmable, read only memory (E <sup>2</sup> PROM), 3 amplifiers, an automatic gain control circuit and 2 filters, in the form of a monolithic integrated analogue circuit not contained in a housing (chip), for use in the manufacture of clocks and watches (m)	θ
726	ex85423828	¥85	Control circuit of C-MOS technology, capable of driving inductive and resistive loads, having 4 outputs with a current of 2 A or more but not exceeding 7,2 A, in the form of a monolithic integrated enalogue circuit not contained in a housing (chip), for the manufacture of motor control systems (a)	8
728	ex85423020	<b>\$</b> 87	Differential amplifier of bipolar technology, with a gain not exceeding 375 and a nominal input voltage of 1 mVpp, in the form of a monolithic integrated analogue circuit not contained in a housing (chip), for use in the manufacture of products falling within heading No 8471 (a)	θ
737	ex85423030	<b>\$</b> 61	Microwave amplifier of bipoler technology, with a nominal gain of 18 dB at 0,5 GHz or 32 dB at 0,9 GHz or 11 dB at 1 GHz or 22,5 dB at 1 GHz and 32,5 dB at 0,1 GHz or 26 at 1,5 GHz, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s): A-06 HPMX 3002 N10	
			A-88 NSA 8311 PC 1652G	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
738 ex8542303	8×85423030	•62	Quadruple amplifier of C-MO8 technology, with an input current not exceeding 20 pA, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			LWC 668	
			0 F	
			- other identification markings relating to devices complying	

CN code	TARIC	Description	Rate of autonomous duly (%)
39 ex85423038	<b>#03</b>	Amplifier of bipolar technology, with a typical supply current not exceeding 1 mA at a voltage of 12 V and a temperature of 25°C, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		LN 1964	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
40 ex85423030	*84	Amplifier of bipolar technology, with a typical operating frequency of 1,3 GHz, 2,3 GHz or 3 GHz and a single supply voltage of 5 V, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		CID CIE CIF CIG CIH CIJ	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
41 Ex85423030	¥85	Amplifier with an off-set voltage not exceeding 10 mV at 25°C, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
		the following combination(s): LT 1006 NC 33272 OPA 275 TLC2022	
		LT 1028 MC 33274 OPA 628 TLC27M2	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
42 ex85423030	*86	Amplifier, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		C 85 V 35	
		or	
		- other identification markings relating to devices complying with the abovementioned description These devices are for use in the menufacture of products falling within mubheading 90214000 (a)	θ
43 ex85423030	¥07	Transispedance asplifier, with a typical gain of 72,5 dB at a frequency of 750 MHz, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
,		ITA 12318	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
44 ex85423030	<b>\$</b> 88	Amplifier of gallium arsenide (GeAs) semiconductor material, operating within a frequency range of 82 <u>0</u> MHz to <u>2,5 G</u> Hz, in the form of a monolithic integrated analogue circuit contained in m housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		AWT 8988 AWT 1988 SPFIC48K82	
		· · · · · · · · · · · · · · · · · · ·	

	CN code	TARIC	Description	Rate of sutonomous duty
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
745	Bx85423030	¥89	Amplifier with a typical gain of 10,5 dB at a frequency of 2 GHz and with an output power of 10 dBm (10 mW), in the form of a monolithic integrated analogue circuit contained in a housing bearing:	
			<ul> <li>- an identification parking consisting of or including (one of) the following combination(s):</li> </ul>	
			MAR 3SM	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
746	ex85423030	¥10	Video seplifier of bipoler technology, with a bandwidth of 200 MHz, comprising a contrast control circuit, a comparator and a voltage reference circuit, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking conmisting of or including (one of) the following combination(s):	
			LN 1201	
			or	
			- other identification markings relating to devices complying	
			with the abovementioned description	0
747	ex85423030	≢11	Amplifier with an input current not exceeding 80 rA, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (onm of)</u>	
			the following combination(s):	
			INA 101 OPA 27 OPA 37 OPA 111 <b>opa 121</b>	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	ß
748	ex85423030	¥12	Video seplifier of bipolar technology, providing separate amplification of red, green and blue (RGB) colour mignals, comprising at least a contrast control circuit and a comparator, in the form of a monolithic integrated enalogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			HA 11533NT LM 1203 <u>LM 1208</u> LM 1202 LM 1205	·
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
749	ex85423030	¥13	Variable amplifiers for the range of frequencies of 10 Hz or more but not exceeding 30 kHz, with a gain of 85 dB or more, in the form of a monolithic integrated analogue circuit contained in a housing bearing: ~ an identification marking consisting of or including (one of) the following combination(s):	
			N 5218	
			or	
			- other identification markings relating to devicem complying with the abovementioned description	8
750	ex85423030	¥14	Thermocouple amplifier for instrumentation control mt temperatures from 0 to 50°C, incorporating an mlarm system, in	
	· · ·		the form of a monolithic integrated analogue circuit contained in a housing bearing:	
			<ul> <li>an identification marking consisting of or including (one of)</li> </ul>	

CN code	TARIC	Description	Rate of autonomous duty (%)
		AD 594 AD 595	······································
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
751 Bx85423838	¥15	Asplifier with a progresseble gain factor, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
		the following combination(s):	
		PGA 102 PGA 202 PGA 203	
		or - other identification markings relating to devices complying with the abovementioned description	θ
752 ex85423030	€16	Logarithmic amplifier, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(m):	
		AD 606	
		or	
		- other identification markings relating to devices complying	
		with the sbovesentioned description	θ
753 ex85423030	<b>≇</b> 17	Audio seplifier, with a voltage noise density not exceeding 108 nV/Hz at a frequency of 1 kHz, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		SSM 2017	
		or	
		<ul> <li>other identification markings relating to devices complying with the upovementioned description</li> </ul>	θ
754 ex85423030	<b>*</b> 18	Variable gain amplifier, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		AD 606 AD 602	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
755 ex85423030	¥19	Amplifier for processing read signals in a storage unit, in the form of a monolithic integrated analogue circuit contained in a housing bearing:	
		<ul> <li>an identification <u>marking consisting of or including (one of)</u></li> <li>the following combination(m):</li> </ul>	
		1118884-81	
		or	
		- other identification markings relating to devices complying with the abovementioned description	θ
757 ex85423030	•21	Interendiate frequency (IF) or FM amplifier of bipolar technology, comprising a mixer, a receive signal strength indicator (R881), a detector and an oscillator in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	,
		CXA 1343 CXA 1744R 8A 607D 6A 617D	
		07	

	CN code	TARIC	Description	Rate of autonomous duty
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
758	■x85423030	*22	Amplifier of gallium mrammide (GaAs) semiconductor material, having a nominal gain of 15,4 dB or more but not exceeding 38 dB and a frequency range of not more than 8 GHz, in the form of m monolithic integrated analogue circuit contained in m housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			166871 166872 166874 865 NGF 7131	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
759	■x85423838	*23	Audio septifier of bipoler technology, with a typical gain of 26 dB or more but not exceeding 47 dB in a frequency range of 20 Hz to 20 kHz, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			LN 3875 TA 2018	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
760	ex85423030	¥24	Single, dual or quadruple amplifier operating with a supply current per amplifier not exceeding 8 mA, in the form of m monolithic integrated analogue circuit contained in a houming bearing: - an identification marking consisting of or including (one of)	
			the following combination(s): 014B LN 224 LT 1078 NC 14573 NC 3403 5W01 LN 2902 LT 1079 NC 14574 NC 3503	
			AD 826 LH 324 LT 1178 HC 14575 DP 292 LM 124 LS 404 LT 1179 HC 3383 DP 492	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
731	ex85423030	\$25	Differential line seplifier, with a typical output current of 400 sA and a differential peak-to-peak output voltage of 40 V, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			<u>AD</u> 815	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
733	ex85423030	₽26	Amplifier of gallium armenide (GaAs) semiconductor material, having a frequency range of <u>1,8 GHz or more but</u> not <u>exceeding 2</u> GHz and an output power of 126 mW (21 dBm) or <u>398 mW (26 dBm) at an input power of 1 mW (0 dBm)</u> in the form of a monolithic integrated analogue circuit contained in m housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			RFIC <u>1866</u> RFIC <u>1887</u>	
			or	
			- other identification markings relating to devicem complying	

CN code	TARIC	Description	Rate of autonomous duty (%)
734 ex85423030	*27	Amplifier of gallium armenide (GaAs) memiconductor material, having a fraquency range of <u>0.8 GHz or more but</u> not axceeding <u>16</u> GHz and an output power of <u>355 mV</u> (25,5 dBm) at an input power of <u>1.12 mV</u> (0.5 dBm) or an output power of <u>1.48 W</u> ( <u>31.7 dBm</u> ) at an input power of <u>10 mV</u> (10 dBm), in the form of a monatithic integrated analogue circuit contained in m housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		RFIC <u>8984</u> RFIC <u>8813</u>	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
735 ex85423838	128	Transispedance asplifier, with a dynamic range of 3,981 W (36 dBm), operating at a bandwidth of 180 MHz or more and having differential outputs with an offset voltage not exceeding 28 mV, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		AD 8015	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
766 ex85423050	¥01	Voltage regulators with a quiescent current of 75 µA and a drop out voltage of 380 mV at 100 mA, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		LP 2858 LP 2851 NIC 2851	,
		or	
		- other identification markings relating to devices complying with the abovementioned description	0
767 ex85423050	¥02	Current and voltage regulator, operating on a battery input voltage of 0,85 V or more but not exceeding 5,5 V or an unregulated input voltage of 7 V or more but not exceeding 20 V, providing a selectable output voltage of 3,3 V (±0,13 V) or 5 V (±0,20 V), in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		NAX 717 NAX 719 NAX 721 NAX 723 Nax 718 max 720 nax 722	
		10	
		<ul> <li>other identification serkings relating to devices complying with the abovesentioned description</li> </ul>	θ
768 ex85423050	∎03	Voltage regulator, providing reverse battery protection, operating with an input voltage not exceeding 68 V and a quiescent current not exceeding 78 pA at zero load or a quiescent current not exceeding 38 aA at load current of 1 A, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
		the following combination(s):	
		LW 2848 LT 1129	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ

	CN code	TARIC	Description	Raie of suionomous duty (
769	■x85423858	• 0 4	Adjustable shunt voltage regulator, comprising an internal voltage reference and divider remistors with a collector (sink) current of 1 mA or more but not exceeding 100 mA and an initial voltage reference tolerance of 0,4 %, in the form of a monolithic integrated analogue circuit contained in a housing bearing:	
			<ul> <li>- an identification <u>marking conmisting of or including (one of)</u> the following combination(s):</li> <li>LT 1431</li> </ul>	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
770	ex85423050	<b>₩0</b> 5	Voltage regulator, with a quimacent current not exceeding 75 mA and a dropout voltage not exceeding 0,8 V at an output current of <u>500 or</u> 750 mA, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			<u>PQ05RH1 PQ12RH1</u> TL750N TL751N	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
771	ex85423050	*86	Veriable voltage regulator with a supply current not exceeding 120 µA at an output current not exceeding 100 µA and a dropout voltage not exceeding 0,85 V at an output current of 125 aA, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - ar identification marking consisting of or including (one of) the following combination(s):	
			LT 1020 LT 1120	
			or	
			- other identification sarkings relating to devices complying with the above#sationed description	θ
772	вx85423050	*67	Voltage regulator, having an output voltage of 12 V (±3 %), a quiescent current not exceeding 10 mA and a dropout voltage not exceeding 22 V at an output current of 50 mA, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			CS 8109 (7032FB)	
			10	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
773	ex85423858	¥08	Voltage regulator with an output voltage of 2,1 V (±2,5 %) or 3 V (±2,5 %) at a nominal output current of 40 mA, in the form of a monotithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u>	
			<u>the following combination(s):</u> 0 C (RH5 RA 30 AA) 1 B (RH5 RA 21 AA)	
			0 ( (KH5 KR 30 AH)   0 (KH5 KH 21 HH)	
			÷.	

	CN code	TARIC	Description	Rate of autonomous duty (X
774	ex85423050	*89	Voltage regulator with an input voltage range of 4,75 V or more but not exceeding 80 V and a quiescent current not exceeding 10 mA, comprising a 1 A switch circuit and an oscillator with a fixed frequency of 52 kHz, in the form of a monotithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(a):	
			LM 1575 LM 2575	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
775	ex85423858	<b>*</b> 19	Voltage regulator, having an autput voltage of 1 V or more but not exceeding 8 V, a typical quiescent current of 400 or 500 µA, a typical dropout voltage of 170 mV at an output current of 60 mA, in the form of a monetithic integrated analogue circuit contained in a housing bearing: - an identification marking compisting of or including (one of) the following combination(m):	
			TK 114 (R3) TK 115 TK 116	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
776	ex85423858	\$11	Voltage and current regulator of bipolar technology, capable of generating 3 ouput currents of respectively 7,5 mA, 50 mA and 750 mA at an ouput voltage of 5 V (15 X), in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			34992	
			or - other identification markings relating to devices complying with the abovementioned description	θ
777	ex85423050	*12	Voltage regulator, having an output voltage of 3,9 V (±3 X), a typical output current of 48 aA at an input voltage of 6 V and a typical operating current of 2,2 µA, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			SCI 7718V-KA	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
778	ex85423050	<b>#</b> 13	Voltage regulator, with a dropout voltage not exceeding 1,5 V at an output current of 3 A or more but not exceeding 9,5 A, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(m):	
			LT 1083 LT 1084 LT 1085 LT 1585	
			07	
			- other identification markings relating to devices complying	θ

	CN code	TARIC	Description	Rate of autonomous duty
779	■×85423858	¥14	Voltage regulator, with an output current of 50 mA at a typical input to output differential voltage of 0,35 V or an output current of 30 mA at a typical input to output differential voltage of 0,15 V, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			8 8420 8 8850	
			or	
			<ul> <li>other identification serkings relating to devices coeplying with the abovementioned description</li> </ul>	θ
780	ex85423858	¥15	Voltage regulator, with an input voltage not exceeding 6 V, a typical output voltage of 3,3 V, a quiescent current not exceeding 18 mA and a dropout voltage not exceeding 1,3 V, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			EZ 1083 EZ 1084 EZ 1085 EZ 1086	
		•	or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned descrip<sup>4</sup> ion</li> </ul>	θ
781	ax85423858	*16	Voltage regulator, with an input voltage of 4 V or more but not exceeding 11 V and a typical output voltage of 12 or 15 V, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			MAX 732 NAX 733	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
782	ex85423858	*17	Voltage regulator with an input voltage range of 3 V or more but not exceeding 64 V and a quiescent current of 6 mA or more but not exceeding 8,5 mA, comprising an internal 1,25 A, 2,5 A, 4 A or 5 A switch circuit, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			LT 1070 LT 1074 LT 1170 LT 1172 LT 1071 LT 1076 LT 1171 LT 1271	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
783	ex85423858	\$18	Voltage regulator, with an input voltage of -8.5 V or more but not exceeding 26 V, a typical output voltage of 5 V, a quiescent current not exceeding 15 mA and a dropout voltage not exceeding 1.5 V at an output current of 588 mA, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			CS 8149 CS 8141	
			or	
			- other identification markings relating to devices complying with the abovementioned description	θ

	CN code	TARIC	Description	Rate of autonomous duty (%)
761	ex85423058	¥19	Voltage regulator, with an input voltage of 2,1 V or more but not exceeding 16 V, a typical output voltage of 3, 3,3 or 5 V at a nominal output current of 50 an and a dropput voltage not exceeding 225 mV, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (onm of) the following combination(m):	
			LP 2988	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
83bis	ex85423858	\$28	<u>Switching v</u> oltage regulator, with an input voltage of - <u>1</u> 5 V or more but not exceeding <u>68</u> V <u>and</u> an output voltage of <u>3,2</u> <u>V or more but not exceeding 5,2</u> V, in the form of a monolithic integrated analogue circuit contained in a housing bearing:	
			<ul> <li>an identification marking consisting of or including (one of) the following combination(s):</li> </ul>	
			<u>LT 1142</u> LT 1149	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
784	ex85423061	•∂1	Quadruple fuel injector driver emertpower circuit of BiMOS technology, comprising a voltage regulator, an overvoltage detection circuit and an output status control circuit, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			7100058FSE	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
785	ex85423061	<b>#</b> 02	Smartpower circuit, capable of controlling DC motors, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			NPC 17450VM	
			10	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
786	ex85423861	¥03	Smartpower circuit, capable of power supply switching of memory cards, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			NAX 780 NIC 2557 NIC 2558	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
78?	ex85423061	¥04	Smartpower circuit, capable of controlling battery voltage charge, in the form of a monotithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	,
			NPC 1825VN TOP 201 TOP 203 TOP 214	

	CN code	TARIC	Description	Rate of autono∎ous duty
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
788	ax85423065	*01	Techoseter or techoseter and speedometer control circuit of BiMOS or bipoler technology, comprising a voltage regulating function, in the form of a monotithic integrated mixed amalogue-digital circuit contained in a housing bearing: - an identification marking commisting of or including (one of) the following combination(s):	
			<b>C8 8190 T 8557G TB 9226N TB 9228N TB 92</b> 33N	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
789	Bx85423865	€82	Video control circuit of bipoler technology, capable of swithching VUV/RGB signals and controlling contrast, brightness and colour, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			CXA 1839	
			or	
			<ul> <li>other identification sarkings relating to devices complying with the abovesentioned description</li> </ul>	θ
798	ex85423065	*83	Spendometer and odometer drive and control circuit, whether or not having amplification functions, comprising 4 frequency dividers, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			TA 8906 TB 9207 TB 9208 TB 9212 TB 9230	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	6
791	₽x85423865	*04	Video control circuit of bipolar technology, providing control pulse generation for image recording, comprising an amplifier for write-signals and an amplifier for read-signals, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			TA 8823	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	Θ
792	ex85423065	•05	Disc storage unit controller of C-MOS or BiMOS technology, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			1323453 M52896FP (5367897) 18P9-0003 PD 16828 5368800	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	0

	CN code	TARIC	Description	Rate of autonomous duty (%)
793	ex85423865	₿06	Control circuit of BiHOS technology, capable of switching video signals, with 3 video inputs, 3 control outputs and a buffer output, comprising a clamp circuit, in form of a monotithic integrated mixed analogue-digital circuit contained in a housing bearing:	
			<ul> <li>an identification marking conmisting of or including (one of) the following combination(s):</li> </ul>	
			BA 7021	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
794	ex85423065	¥87	Clock recovery circuit of bipoler technology, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing:	
			<ul> <li>- an identification marking conmisting of or including (one of) the following combination(m):</li> </ul>	
	,		AD 800 AD 802	
			or	
			- other identification markings relating to devices complying	
			with the abovementioned description	θ
795	ex85423665	<b>≇</b> 08	Control circuit of BiMOS technology, capable of switching audio signals, with 5 audio inputs, 5 control outputs and 3 output buffers, in form of a monolithic integrated mixed analogue-digital circuit contained in a houming bearing: - an identification marking conmisting of or including (one of) the following combination(s):	
			BA 7632	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
796	ex85423865	¥09	Speedometer, tachometer or odometer drive and control circuit, comprising at least a digitat-to-analogue converter and a multiplexer, in the form of a monolithic integrated mixed analogue-digital circuit contained in a houming bearing: - an identification marking commisting of or including (one of) the following combination(s):	
			SA 5775 SA 5777	
			10	
			- other identification markings relating to devices complying with the abovementioned description	θ
797	ex85423065	<b>\$</b> 10	Temperature control circuit, with a temperature sensor and an internal voltage reference, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing:	
	,		<ul> <li>an identification marking consisting of or including (one of) the following combination(m):</li> </ul>	
			TNP 81	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
798	ex85423865	¥11	Video control circuit of BiMOS technology, cspable of driving a cathods-ray tuba, providing horizontal/vertical deflection and colour signal processing, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s);	
			CXA 1840	
			70	
			110	

C	N code	TARIC	Description	Rate of autonomous duty (
			<ul> <li>other identification aarkings relating to devices complying with the abovementioned description</li> </ul>	8
799 e	2×85423065	¥12	3-phase motor control circuit, comprising a 9-bit digital-to-analogue converter, an 11-bit serial port, with a apindle drive current not exceeding 1 A and a voice coil motor current not exceeding 400 añ, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			HA 13544	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
800 e	x85423065	*13	Bidirectional DC motor control circuit of bipolar technology, comprising a drive current switching circuit, in the form of e monolithic integrated mixed malogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			TA 8858P	
			07	
			- other identification markings relating to devices complying	
			with the abovementioned description	θ
801 e	x 85423065	<b>≇</b> 14	Control circuit, capable of driving field-effect transistors (FETs), in the form of a monolithic integrated mixed malogue-digital circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			HAA9P-51123R	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
802 e	x85423065	¥15	3-phase DC motor control circuit of bipolar technology, comprising an oscillator, power and phase changeover circuits and a ring counter, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			AN 8225	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
803 e	xx85423865	¥16	Circuit for driving linear motors or motors with rotating arms, of C-MOS technology, comprising a drive current switching circuit and a power fault detection circuit, in the form of a monolithic integrated mixed analogua-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(m):	
			3246818 5862896	
			or	
			- other identification earkings relating to devices complying	٥
		-	with the abovementioned description	θ

CN codi	1	TARIC	Description	Rate of autonomous duty (%)
804 ex85423	3065	•17	Video control circuit of bipolar tachnology, capable of awitching and claaping video signals, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			CXA 1860	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
885 ex8542	3065	\$18	Gain control circuit, capable of controlling and amplification of rand signals for a storage unit, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing:	
			<ul> <li>an identification marking consisting of or including (one of) the following combination(s):</li> </ul>	
			1118885-84	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
698 ex8542	3865	<b>*</b> 19	Brushless three-phase_DC motor control circuit of BiMOS technology, operating at a power supply of <u>3 V or more but</u> not exceeding 5,5 V, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			A 8983 PRD 1829	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
808 ex8542	3869	<b>\$</b> 01	Control circuit, capable of driving inductive or resistiva loads, having an output current not exceeding 1,3 A at a supply voltage not exceeding 28 V, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			71064 SB	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
889 ex8542	3869	¥02	Control circuit, capable of driving inductive and resistive loads having 4 outputs with a current of 2 A or more but not exceeding 7,2 A, in the form of a monolithic integrated malogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			100904 HIP 0082	
			0 r	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
810 ax8542	3069	¥03	Control circuit of bipolar technology, for driving DC motors with brushes, in the form of a monotithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking conmisting of or including (onm of)</u> the following combination(s):	
			BA 6189 BA 6289	
			or	

CN cod	e TAR	C Description	Rate of autonomous dut
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
811 ex8542	3869 •84	DC motor control circuit of bipolar technology, providing an output corrent of 2 A at an output saturation voltage of 3,2 V, comprisi g 3 TTL inpute, 4 transistors in a full bridge configuration and an overvoltage shutdown circuit, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		71884 MB	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
812 ex8542	3869 <b>*</b> 85	Three-phase DC motor control circuit of BiMO8 technology, comprising a Hall effect threshold detection circuit, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(m):	
	•	1323454	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
813 ex85423	1869 <b>*86</b>	Circuit for driving linear motors or motors with rotating arms, of bipolar technology, working with an supply voltage not exceeding 24 V and an operating temperature of -48°C to +125°C, comprising an overvoltage shutdown circuit and a thermal shutdown circuit, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		34993	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
814 ex85423	869 *87	Circuit for driving linear motors or motors with rotating arms, of bipolar technology, working with an output voltage of 45 V at an output current of 1,75 A, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		UDN 2917	
	,	or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
815 ex85423	869 88	Brushless three-phase DC motor control circuit of bipolar technology, operating with an input current of 1 µA and having an input off-set current of 0,1 µA at an input off-set voltage of 5 aV, comprising a therast shutdown circuit, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		HA 13498	
		10	
		- other identification markings relating to devices complying	
		with the abovementioned description	θ

	CN code	TARIC	Description	Rate of autonomous duty (X)
816	€x85423069	*89	Control circuit of bipolar technology, capable of driving solenoids, operating with a power supply current not exceeding 50 mA at a supply voltage not exceeding 7 V and a dissipation rate not exceeding 19 V, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			71008SB 71013SB	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
817	ex85423869	\$10	Control circuit of C-MO8 technology, for monitoring the voltage of microprocessors, microcontrollers or microcomputers, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			DS 1231 H 6060 NN 13882 NN 13821C DS 1232 H 6061 NN 1381 NN 13822C H 6006 NN 1380 NN 13811 NN 1382C H 6052 NN 13801 NN 13812 V 7039	
			or	
			<ul> <li>other identification markings retating to devices complying with the abovementioned description</li> </ul>	8
818	■×85423869	#11	Voltage regulator control circuit, operating with a supply voltage of 6 V or more but not exceeding 30 V, providing an output voltage of 5 V (±0,1 V) at an output current of 220 µA, in form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			LT 1432	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
819	ex85423869	*12	Control circuit of C-MOS technology, capable of amplifying/inverting voltage levels to drive vertical lines of a charge-coupled (CCD) image sensor, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			CXD 1267	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
820	ex85423869	¥13	Control circuit of bipolar technology, capable of switching video and audio functions, comprising amplifiers and a mixer of luminance and chrominance signals, in form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			CX 1545 CXA 1845 CXA 1855	
			or	,
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ

	CN code	TARIC	Description	Rate of autonomous duty (
821	Bx85423869	\$14	Control circuit, capable of recording and reproduction of signals in a video servo system, in the form of a monolithic integrated enalogue circuit contained in a housing bearing: - an identificat <u>ion marking conmisting of or including (one of)</u> the following combination(m):	
			TA 8823M	
			or	
			<ul> <li>other identification earkings relating to devices couplying with the abovementioned description</li> </ul>	8
822	ex85423069	*16	Drive circuit for heads of a storage unit, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
			the following combination(s):	
			1110007-01	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
823	ex85423069	<b>₽</b> 17	Control circuit of bipolar tachnology, providing volume control, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
	-		the following combination(s):	
			BA 3574 CXA 1846 CXA 1948	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
824	ex85423869	≇18	Control circuit, capable of driving power field-effect transistors (PETs), in the form of a monolithic integrated analogue circuit contained in a housing basring: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			7188988 LTC 1155	
			70	
			<ul> <li>other identification markings rulating to devices complying with the abovementioned description</li> </ul>	θ
827	ex85423870	¥01	Interface circuit of dielectric isolation technology, for telephone sets with a line voltage not exceeding 265 V, in the form of a monolithic integrated enalogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			LH 1497	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
828	Bx85423070	\$02	Interface and control circuit of C-NOS technology, for the generation of graphic symbols on a cathode-ray tube, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			NN 1297	
			or	
			- other identification markings relating to devices complying	6

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CN code	TARIC	Description	Rate of autonomous duty (%)
29 ex85423070	*03	Interface circuit of bipolar technology, capable of converting a differential input signal into a square wave output signal of the same frequency, comprising 4 signal samsor channels and a timer, in the form of a monolithic integrated analogue circuit contained in a housing bearing:	
		<ul> <li>an identification sarking consisting of or including (one of) the following combination(s);</li> </ul>	
		71001AB	
		- other identification markings relating to devices complying	
	• 0.4	with the abovementioned description	θ
30 ex85423070	*04	Interface circuit or interface circuit with control functions, for a local area network (LAN), in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(m):	
	· •	8MC 83C885	
		01	
		- other identification markings relating to devices complying with the abovementioned description	θ
31 ex85423070	¥05	Video signals interface circuit of bipolar technology, capable of interfacing with a red, green and blue (RGB) colour signal circuit, comprising 3 automatic white balance adjustment circuits, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
		the following combination(s):	
		CXA 10248	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
32 mx85423878	\$86	Subscriber line interface circuit (SLIC), in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
		the following combination(s):	
		Am 79M535 Am 79M574 Am 79M576 or	
		or - other identification markings relating to devices complying with the abovementioned description	θ
44 ax85423895	*01	Audio recording/reproducing circuit of C-MOS technology, capable of direct analogue storage of audio data, comprising an electrically erasable, programmable, read only memory (E <sup>2</sup> PROM), 3 amplifiers, an mutomatic gain control circuit and 2 filters, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		ISD 1012A ISD 1020A ISD 1210 ISD 2545 ISD 2575 ISD 1016A ISD 1200 ISD 1400 ISD 2560 ISD 2590	
		07	
		- other identification markings relating to devices complying with the abovementioned description	8
45 mx85423895	\$82	Dual-tone multi-fraquency (DTMF) generator of C-MOS technology, capable of decoding 4-bit binary data and generating 16 tone pairs, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	

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	CN code	TARIC	Description	Rate of autonomous duty (
			TP 5008	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
846	ex85423895	<b>₽</b> 03	Signal processing circuit of C-MO8 technology, providing analogue signal filtering and gain control, comprising a dual-tone auttifrequency (DTNF) transmitter and a DTNF receiver, and a modulator/demodulator (Nodem), in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			SC 11370	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
848	8×85423895	•05	Local talephone natwork circuit of C-NOS tachnology, capable of tone generation and of awitching, amplifying and decoding audio signals from not more than 2 external telephone lines and from not more than 12 internal telephone lines, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			SC 11390	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
849	ex85423095	886	Analogue communication circuit, capable of date conversion and signal transfer, comprising a serial input/output port for a digital signal processor (DSP), a 18-bit analogue-to-digital converter, a 16-bit digital-to-analogue converter and a clock generator, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			AD 28MSP61	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
850	ex85423895	€87	Encoder/decoder of C-MOS technology, for base-band and voice-band frequencies, providing data conversion, comprising a modulator for digital signals, analogue-to-digital converters, digital-to-analogue converters, maplifiers and filters, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			AD 7015	
			10	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
851	ex85423895	•68	16-bit stareo encoder/decoder with C-MO8 technology, having sample rates of 4 kHz or more but not exceeding 48 kHz, comprising a multiplexer, a digital-to-analogue converter, an analogue-to-digital converter, a mute circuit, a voltage reference circuit, a microphone-input, a Loudapeaker-output and a headphone-output, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	

		Description	Rate of autonomous duly (%)
		AD 1849 C8 4215	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
852 ex85423895	*89 *	Encoder/decoder with pulse-code-modulation filter of C-MOS tachnology, operating with a +5 V mingle-power supply, comprising an analogue-to-digital converter and a digitat-to-analogue converter, in the form of a monotithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
		the following combination(s):	
		MC 145480 <u>TMC 129C18</u>	
		07	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
853 ex85423095	¥10	Encoder/decoder with pulse-code-modulation filter of C-MOS technology, with a dual-power supply and having a typical dissipation rate of 50 mW, comprising an analogue-to-digital converter and a digital-to-analogue converter, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		MC 145503	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
854 ex85423095	#11	Adaptive differentiated pulse-code-sodulation circuit of C-MOS technology, for encoding/decoding data with a data transfer rate of 8, 16, 24, 32 or 64 Kbits per second, in the form of a monolithic integrated mixed malogue-digital circuit contained in a housing bearing: - en identification marking consisting of or including (one of) the following combination(s):	
		T 7280	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
855 ex85423095	¥12	Encoder/decoder with pulse-code-modulation filters of C-MOS technology, capable of voice digitisation and reconstruction at a speed of 64 Kbits/s or more but not exceeding 2048 Kbits/s, with m mingle power supply of S V, a power dissipation not exceeding 37 mV in operating mode and not exceeding 3 mV in power down mode, in the form of a monolithic integrated mixed aratogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		7568 B 7509 B	
		10	
		<ul> <li>other identification markings relating to devices complying</li> <li>the abovementioned description</li> </ul>	θ
856 ex85423095	•13	FM receiver of bipoler technology, capable of operating at an input frequency rage of 200 MHz, with an FM signal demodulating function, comprising at least 2 mixers, an oscillator, a diode and a Receive Signal Strangh Indicator (RSSI), in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	

...

	CN code	TARIC	Description	Rate of autonomous duty (%)
			or	· •
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
857	ex85423695	ŧ14	FM-band receiver of BiMOS technology, comprising a compression circuit, a decompression circuit, 2 mixers, 2 phase-locked loop (PLL) circuits, an intermediate frequency (IF) amplifier, a receive mignal strength indicator (RSBI), a merial interface circuit and a supply voltage detection circuit, in the form of a monolithic integrated mixed enalogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			NC 13188	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
858	ex85423895	*15	Comparator of C-MOS technology, capable of voltage comparison, with a propagation delay of not more than 12 µs, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			NAX 921 NAX 923 NAX 931 NAX 933 Nax 922 nax 924 nax 932 nax 934	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
859	ex85423895	<b>*</b> 16	Circuit for connecting/disconnecting busses, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			89F6248 89F7000 TL2218	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
860	ex85423095	<b>≇</b> 17	Audio and video signal processing circuit of bipolar technology, comprising a phase-locked loop (PLL) circuit, a FM signal detector, an intermediate frequency (IF) amplifier, a pre-amplifier, a radio frequency (RF) automatic gain control amplifier and a video signal amplifier, in the form of a monolithic integrated mixed amalogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			LA 75?7	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
861	ex85423095	#18	Circuit for speed and angle position measurement, of C-MOS technology, comprising 4 amplifiers, a demodulator, a counter, a voltage inverter, a latch and a voltage controlled oscillator, in the form of a monolithic integrated mixed amaloque-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	

RDC 19228

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- other identification markings relating to devices complying

C N	l code	TARIC	Description	Rate of autono∎ous duty (%)
			with the abovecentioned description	θ .
862 ex854	85423885	<b>€19</b>	Transmitter/receiver of C-MO8 technology, providing line distortion equalization and data conversion, in the form of a monotithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			TXC 87225	
			0 r	
			- other identification markings relating to devices complying	
			with the abovementioned description	θ
863 ex	85423895	¥20	Desodulator of BiNOS technology, capable of processing encoded data from a segnetic stripe reader, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking conmisting of or including (one of) the following combination(s):	
			N 58718FP	
			07	
			- other identification markings relating to devices complying	
			with the abovementioned description	θ
864 ex	85423895	<b>₽</b> 21	Modulator of C-M08 technology, having a dynamic range of 123 dB in a bandwidth of 375 Hz or a dynamic range of 124 dB in a bandwidth of 500 Hz, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identificat <u>ion marking conmisting of or including (one of)</u> the following combination(s):	
			C8 5321 C8 5323	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovesentioned description</li> </ul>	θ
865 ex	85423095	¥22	16-bit digital-to-analogue converter, having a hands free function, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			16485	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
866 ex	85423895	•23	6-bit dual analogue-to-digital converter BiMOS technology, comprising a voltage reference circuit, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			AD 9866	
			70	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
867 ex	85423095	¥24	4-channal 12-bit pulse width modulation generator, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification parking consisting of or including (one of) the following combination(s):	
			M 66242	
			or	

	CN code	TARIC	Description	Rate of autonomous duty (X
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
868	Bx85423895	¥25	Circuit for detecting pre-ignition of an automotive engine, comprising at least 1 emplifier and 1 bandpass filter operating at a frequency of 1 kHz or more but not exceeding 20 kHz, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			HIP 9010 HIP 9011	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
869	ex85423095	\$26	Hall effect sensor with digital signal outputs, comprising a differentiator and peak detector, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
			the following combination(s):	
			AD 22482	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
870	ex85423095	¥27	Audio signal processing circuit of C-MOS technology, operating at a typical sypply voltage of 3 V, comprising a dual-tone multifrequency (DTMF) generator, mute switches, digitally controlled signal attenuators and passband filters, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			SA 5753	
			o <i>r</i>	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
871	ex85423695	\$28	Transmitter/receiver of bipolar technology, comprising an UHF frequency oscillator, an oscillator operating at a frequency of 117 MHz and an oscillator operating at a frequency of 284 MHz, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			₩ 2020	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
872	Bx85423895	\$29	Serial/parallel or parallel/serial converter for a network with an optical-fibre or coaxial cable, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (onm of) the following combination(s):	
			6460175 6460176	
			01	
			- other identification markings relating to devices complying	
		~	with the abovementioned description	θ

CN code	TARIC	Description	Rate of autonomous duty (%)
875 ex85423095	+32	<ul> <li>Audio circuit of C-MOS technology, with a dynamic range of 76 dB or more, comprising 2 digital-to-analogue converters and 2 analogue-to-digital converters, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing:         <ul> <li>an identification marking consisting of or including (one of)</li> </ul> </li> </ul>	
		the following combination(s):	
		AD 1845 AD 1847 AD 1848 C8 4231 C8 4248	
	a	or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
876 ex85423895	•33	Voice signal processing circuit of C-MOS technology, comprising an encoding circuit, a decoding circuit, a compression circuit and a decompression circuit, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing:	
		<ul> <li>- on identification working consisting of or including (one of) the following combination(s):</li> </ul>	
		AK 2342 AK 2353 TC 35492 TC 35493	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
877 ex85423895	134	Frequency synthesiser, operating with an input frequency not exceeding 2 GHz and a DC supply voltage not exceeding 18 V, comprising a phase-locked loop (PLL) circuit and a programmable 14-bit or 20-bit counter, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	• .
		LC 7218 LNX 2320 NC 145158 NC 145162	
		07	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
878 ex85423095	₹35	Passive decoder of BiMO8 technology, comprising a fixed matrix, a 7-kHz filler, a noise-reducing circuit and a digital delay circuit, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		LV 1888 LV 1811	
		or	
		<ul> <li>other identification earkings relating to devices complying with the abovementioned description</li> </ul>	θ
79 ex85423895	*36	Natrix decoder, comprising an adaptive matrix circuit, a noise generator and an automatic-balance control circuit, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combined (a):	
		<u>the following combination(s):</u> LA 2785 N 69032P NJN 2177 88N 2125 88N 2126	
		0f	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
80 ex85423095	#37	Video processing circuit of bipolar technology, providing discrimination of synchronisation signals, in the form of a monolithic integrated mixed analogue-digital circuit contained in a howeing bearing: - an identification serking consisting of or including (one of)	

	CN code	TARIC	Description	Rate of sulonomous duty (
			CXA 1616	
			10	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
954	ex85423895 ex85423899	#38 <u>*62</u>	Video processing circuit, for colour or luminance signals, in the form of a monolithic integrated <u>mixed maloque-digital or</u> analogue circuit contained in a housing bearing: - en identificat <u>ion marking conmisting of or including (one of)</u> the following combination(s):	
			AD 722 CXA 1288 <u>CXA 1587</u> <u>CXA 2000</u> CXA 1207 <u>CXA 121388</u> CXA 1779P <u>LC 8997</u>	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
				0
701	ex85423695	*40	Frequency synthesiser of BiNOS technology, comprising <u>1 or</u> <u>more</u> phase-locked loop (PLL) circuits and 1 or more programmable frequency dividers, with an operating frequency of 20 MHz or more but not exceeding 2 GHz, in the form of a monolithic integrated <u>mixed analoque-digital</u> circuit contained in a housing bearing: - an identification <u>marking consisting of or including (one of)</u> the following combination(s):	
			UHA 1015M UMA 1018M LMX 2332 LMX 2335 LMX 2336 or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	6
887	Bx85423895	\$41	Video signal switching circuit, comprising an amplifier and a mixer of luminence and chrominence signals, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s): A 20400	
			0r	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
836	вх85423095	≇42	Quadruple 8-bit digital-to-analogue converter with serial input <u>of C-NOS technologu</u> , in the for∎ of a ∎onolithic integrated mixed analogue-digital circuit contained in a housing bearing:	
			- an identification warking consisting of or including (one of) the following combination(s):	
			NAX 509 MAX 510	
			10	
	······································		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	6
837	ex85423895	\$43	28-bit enelogue-to-digital or digital-to-enalogue converter, in the form of a sonolithic integrated mixed analogue-digital circuit contained in a housing bearing: - <u>an identification marking consisting of or including (one of)</u> the following combination(s):	
			AD 75878 AD 75879	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ

	CN code	TARIC	Description	Rais of autonomous duty (%)
838	ex85423095	*44	Transmitter/receiver capable of modulation/demodulation of radio frequency (RP) mignals, comprising 5 mixers and 2 programmable filters, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			AD 8432	
			or	
			<ul> <li>other identification earkings relating to devices complying with the abovementioned description</li> </ul>	0
842	ex85423895	¥45	Demodulator, capable of receiving and demodulating a data stream with a transfer rate from <u>10</u> to <u>85</u> Mbits/s, in the form of a monolithic integrated mixed analogue-digital circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			AD 8461	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
843	ex85423095 ex85423099	#46 #65	Active filter, providing filter type and operating frequency selection, in the form of a monolithic integrated <u>mixed</u> analogue <u>-digital or</u> analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			NAX 274 NAX 275 <u>NAX 280</u>	
			or	
			- other identification markings relating to devices complying with the abovementioned description	θ
893	ex85423899	*01	Filter of C-MOS technology, with a programmable cut-off frequency of 4,5 MHz or more but not exceeding 25,2 MHz and a programmable frequency amplification not exceeding 9 dB, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			AD 896	
			٥٢ ,	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
894	Bx85423899	<b>8</b> 62	Programmable filter of bipolar technology, with a programmable cut-off frequency of 5 MHz or more but not exceeding 15 MHz and a programmable peak frequency and bendwidth, comprising a seven-pole filter and a differentiator, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			32F8011 32F8012	
			0F	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
895	B×85423099	<b>8</b> 83	Analogue signal sicroprocessor of bipolar technology, providing automatic gain control, read-signal processing and generation of head-positioning signals for asgnatic heads in disc storage units, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	

	CN code	TARIC	Description	Rate of autonomous duty
			SN 28961	
			10	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
896	ex85423889	*04	Modulator of bipolar technology, operating in the UHF band, for the conversion of audio and video signals, in a frequency range of 478 MHz or more but not exceeding 838 MHz, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			ALP 101 CXA 1333	
			or	
			<ul> <li>other identification serkings relating to devices complying with the abovementioned description</li> </ul>	6
899	ax85423899	<b>8</b> 87 ►	AM-band receiver of bipolar technology, providing conversion of radio frequency (RF) into dual intersediate frequency (IF) and detection of sudio frequency, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			3848	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
988	ex85423899	€8	FM-band receiver/demodulator of bipolar technology, comprising 2 conversion mixers, a data slicer and 6 amplifiers, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			10×6	
			70	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
962	ex85423899	<b>≇</b> 10	Switch unit of bipolar technology, for audio signals, having a distortion not exceeding 8,885 %, comprising 2 control units and 2 alternating switches, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			TK 15022 Z	
			or	
			<ul> <li>other identification merkings relating to devices complying with the abovementioned description</li> </ul>	8
993	Bx85423899	. <b>4</b> 11	Switch unit of gallium ersenide (GaAs) semiconductor material, with an insertion loss not exceeding 1,6 dB at a frequency of 2 GHz, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			SW 239 SW 259 SW 419	
			or	
			- other identification markings relating to devices complying	

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	CN code	TARIC	Description	Rate of autonomous duty (%)
984	Bx85423899	<b>*</b> 12	Audio noise reduction circuit of bipoler technology, having an input voltage not exceeding 18 V, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			LN 1894 TK 10654	
		1	or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
985	ex85423899	¥13	Monolithic integrated analogue circuit of bipolar technology, for overvoltage protection, contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			1515         P2         P6         TI8P         2180           P0         P3         TI8P         1872F3         TI8P         2290           P1         P4         TI8P         1882	
			or	
			<ul> <li>other identification sarkings relating to devices complying with the abovementioned description</li> </ul>	θ
906	ex85423099	<b>≢</b> 14	Frequency converter of gellium ersenide (GeAs) semiconductor material, for the conversion of frequencies of 10,25 GHz or more but not exceeding 12,75 GHz to frequencies of 950 MHz or more but not exceeding 2050 MHz, in the form of a monolithic integrated enalogue circuit contained in a housing bearing: - an identification marking commisting of or including (one of) the following combination(s):	
			20070C AKD 12010 AKD 12575 AND 2001T4C AKD 12000 AKD 12011 AKD 2400 FMM 5103 or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
907	ex85423099	<b>#</b> 15	Voltage-to-frequency converter, comprising an amplifiar, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	· · · · · · · · · · · · · · · · · · ·
			VFC32 VFC100 VFC101	
			or - other identification markings relating to devices complying with the abovementioned description	θ
908	ex85423099	≢16	Frequency converter of bipoler technology, with a conversion gain of 7 dB, capable of converting an input frequency of 65,8 MHz into an output frequency of 800 kHz, in the form of a monolithic integrated analogue circuit contained in a housing bearing:	
			<ul> <li>an identification marking consisting of or including (one of) the following combination(s):</li> </ul>	
			806-0227	
			or - other identification markings relating to devices complying with the abovementioned description	θ
909	ex85423099	¥17	Current-to-voltage converter with an input current not exceeding 100 pA and an output voltage not exceeding -10 V, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s): ACF 2101	

CN	code	TARIC	Description	Rate of autonomous duty (X)
			or '	· -
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
910 ex8	85423099	≇18	Converter/amplifier of bipoler technology, with an output level of 22 dBm at a frequency of 900 MHz and an input level of -6 dBm, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			HP 3001	
			or	
			<ul> <li>other identification sarkings relating to devices complying with the abovementioned description</li> </ul>	8
911 ex8	35423099	¥19	RM8-converter for computing the root mean square (RMS) value of wave-forms and converting this value to an aquivalent direct current or an aquivalent direct voltage, in the form of an monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			AD 536 A AD 636 AD 637	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
912 ax8	35423889	¥28	Temperature transducer, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			AD 590 AD 592	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
913 ex8	35423899	<b>#</b> 21	Air pressure sensor, operating with a pressure range of 28 kPa to 185 kPA, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			NPX 4100A	
			10	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
914 ex8	35423099	¥22	<pre>Image sensor consisting of m row of photosensitive sreas and a matrix linked to shift registers, in the form of m monolithic integrated enalogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):</pre>	
			<u>ILX 508</u> PD 3573 TCD 105 TCD 141 <u>LZ 2019</u> TCD 103 TCD 133	
			or - other identification markings relating to devices complying with the abovementioned description	θ
915 ex8	35423099	+23	Interline charge-coupled (CCD) image sensor, in the form of a monolithic integrated analogue circuit contained in a housing	
			bearing: - an identificat <u>ion marking consisting of or including (one of)</u> _ the following combination( <u>s):</u>	
			ICX 018 ICX 022 ICX 038 PD 3732	

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		or	
		<ul> <li>other identification markings relating to devices complying with the abovesantioned description</li> </ul>	θ
916 ex85423899	\$24	Viduo processing circuit of bipoler technology, for signals from a charge-coupled (CCD) isage sensor, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		AN 20146 CXA 1390 IR 3P69 IR 3P97 An 2145Fhp CXA 1391 IR 3P81A IR 3V17 CXA 1310AQ CXA 1392 IR 3P92	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
917 ex85423099	\$25	Signal processing circuit of C-MOS technology, providing datay of scanning periods for horizontal image times of a charge-coupled (CCD) image sensor, comprising a clockgenerator, a clamp circuit and a smaple and hold circuit, in the form of a monotithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following results of the contained in a set of the c	
		<u>the following combination(m):</u> CXL 1586 <u>M7483A</u> MSM 7481 R8 <u>LC 89968</u> MSM 6965 R8	
		or - other identification markings relating to devices complying	
		with the abovementioned description	θ
918 ex85423099	#26	Detector for explitude peaks in read/write signals of disc storage units, consisting of a differential explifier with automatic gain control and a precision full-wave rectifier, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		32P3841 ML 8464	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
919 Bx85423899	₹27	S-channel voltage comparator for monitoring lamp-circuits, in the form of a monolithic integrated malogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		AD 22881	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
920 ex85423099	\$28	Voltage reference circuit providing a typical output voltage not exceeding 10 V with a drift slope (output voltage temperature co-efficient) not exceeding 25 pps/°C, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(m):	
		AD 580 AD 680 LT 1021 REF 102	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ

	CN code	TARIC	Description	Rate of autonomous duty ()
921	■x85423899	•29	Voltage reference circuit with a reverse breakdown of 1,235 V (±4 mV) or 2,5 V (±20 mV), in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking commisting of or including (one of) the (ollowing combination(m):	
			LT 1884	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
922	Bx85423099	<b>₩38</b>	Voltage converter and regulator of bipolar technology, with a voltage loss net exceeding 1,8 V at an output current of 100 sA, operating with a supply voltage range of 3,5 V or more but not exceeding 15 M. In the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking conmisting of or including (one of) the following combination(s):	
			LT 1054	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
923	ex85423899	€31	Voltaga converter of C-MOS technology, capable of inverting, doubling, dividing or aultiplying input voltages, operating at a supply voltage rangs of 1,5 V or sore but not exceeding 18 V, in the form of a monotithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			ICL 7688 MAX 1844	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
924	ex85423899	<b>*</b> 32	Voltage-to-current converter of bipoler technology, with a selectable input voltage range and a power supply voltage of 13,5 V or more but not exceeding 40 V, comprising a current transmitter and a voltage reference circuit, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			XTR 118	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
925 ex854236	ex85423699	•33	Voltage converter of C-MOS technology, capable of transforming an input voltage level not exceeding 5 V at an input current not exceeding 8,1 µA into an output voltage not exceeding 15 V at an ouput current not exceeding 1 mA, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			LR 36683N	
			0 Г	
			<ul> <li>other identification markings relating to devices complying</li> </ul>	

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CN code	TARIC	Description	Rate of autonomous duty (%)
926 ex854238	99 \$34	Current transmitter of bipolar technology, with an output current of 4 mA or more but not exceeding 20 mA, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		XTR 103 XTR 104	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
927 ex854230	99 \$35	Frequency converter of gellium armenide (GeAs) memiconductor material, capable of converting an input frequency of 500 MHz or more but not exceeding 2,5 GHz into an output frequency of 30 MHz or more but not exceeding 500 MHz, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
		<u>the following combination(s):</u> TO 9201 TO 9202 TO 9203	
		or	
		- other identification markings relating to devicem complying	
		with the abovementioned description	θ
929 ex854238	99 •37	Frequency converter of bipoler technology, operating with a frequency range of 800 MHz to 900 MHz and with an input level not exceeding -6 dBa, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> <u>the following combination(s):</u>	
		CXA 1851N	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
930 ex854230	99 \$38	6-channel DC-to-DC converter of BiMOS technology, in the form of a monolithic integrated analogue circuit contained in m housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		MB 3799	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
931 ex854230	99 +39	Amplifier/comparator of bipolar tachnology, for the amplification and comparison of phame/frequency mignals from sensor inputs, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		CXA 1418 N	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
932 ex854230	99 \$40	Voltage detection circuit, capable of resetting externat circuits, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> <u>the following combination(s):</u>	
		M 51957 M 51958	
		10	

	CN code	TARIC	Description	Rate of autonomous du
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
933	ex85423099	*41	Half-bridge rectifier, consisting of 2 field effect transistors of MOS technology (MOSPETs), capable of driving inductive or capacitive loads with a nominal voltage of SG V and a nominal current of 2 A, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			8 i 9950D Y	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
934	ex85423899	\$42	Programmable diode array, consisting of 14 individual diodes and a rectifier, of gallium arsenide (GaAs) semiconductor seterial, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		•	186010 186011	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
935	ex85423099	₹43	Phase-locked loop (PLL) demodulator, with a typical operating fraquency of 488 MHz, comprising an oscillator and a cerrier detector, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			TDA 8012M	
			OF	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
936	ex85423099	≢44	Acceleration measurement circuit, comprising a capacitif sensor, in the form of a monolithic integrated analogue circuit contained in a housing bearing:	
			<ul> <li>- an identification marking consisting of or including (one of) the following combination(s):</li> </ul>	
			ADXL50	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
937	ex85423899	\$45	Fhotodetector, operating at a usvelangth of 788 nm, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
938	ex85423899	\$46	Mixer/oscillator, with a frequency range of 48 MHz or more but not exceeding 860 MHz, comprising a frequency bandswitch and an intermediate frequency (IF)-amplifier, in the form of m	
			<pre>monolithic integrated analogue circuit contained in a housing bearing:</pre>	

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CN code	TARIC	Description	Rate of sutonomous duly (X)
		TDA 5338	•
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
39 ex85423899	¥4?	Filter network only consisting of 16 resistors, 18 capacitors and 18 diodes, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		USRC 1982	
		or	
		<ul> <li>other identification serkings relating to devices complying with the abovementioned description</li> </ul>	9
40 mx85423099	₹48	Isolation circuit for error signals, comprising an amplitude modulator and an amplifier, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		UC 1901 UC 2901 UC 3901	
		or	
,		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
41 ex85423899	<b>*4</b> 9	Level indicator circuit, capable of interfacing between a theraal sensor and a display unit, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		TL 527	
		or	
		<ul> <li>other identification merkings relating to devices complying with the abovementioned description</li> </ul>	<b>0</b> ·
42 ex85423099	¥58	Timer, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (onm of)</u> the following combination(s):	
		NE 555 TS 555	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
43 ex85423899	#51	Audio compression/decompression circuit, operating at a supply voltage of 3 V or more but not exceeding 18 V, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		8A 5752 SA 578	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
44 mx85423099	₹52	FM-band receiver, providing FM-signal demodulation, comprising at least a mixer, an intermediate frequency (IF) amplifier and a limiter amplifier, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	····· , ····
		SA 605 SA 807 SA 617	

CN code	TARIC	Description	Rate of autonomous duly (%)
		or	,
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
946 Bx85423099	¥54	RF-band receiver of bipolar technology, comprising a mixer, a receive signal strength indicator (R881) and a logarithmic/limiting amplifier, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		AD 808	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
948 ex85423099	¥56	Video signal discriminator, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		LA 7311 LA 7356	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
949 ex85423899	₽57	Current breaking device, coeprising an array of 8 field effect transistors (FETs) of the N- or P-channal type, having a typical drain-to-source breakdown-voltage of +380 or -380 V, in the form of a monolithic integrated enalogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
		the fellowing combination(s):	
		ANG132NAR APG136NA	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
550 ex85423899	\$58	Frequency-to-voltage converter, comprising a voltage regulator and an output protected against short-circuit, in the form of a monolithic integrated analogue circuit contained in a housing bearing:	
		<ul> <li>an identification marking consisting of or including (one of) the following combination(s):</li> </ul>	
		8N29736P1	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
951 ex85423899	≢59	Speech-transfer circuit of bipolar tachnology, in the form of a monolithic integrated analogue circuit contained in a housing bearing:	
		<ul> <li>- an identification marking consisting of or including (one of) the following combination(s):</li> </ul>	
		NC 34118	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
\$52 ex85423899	\$68	FM-band receiver of bipolar technology, providing FM-signal demodulation, comprising at least a sixer, an intermediate frequency (IF) amplifier and a limiter amplifier, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	

	CN code	TARIC	Description	Rate of autonomous duty (%)
			MC 13156 NC 13158 TA 2827F	
			a	
			<ul> <li>other identification merkings relating to devices complying with the abovementioned description</li> </ul>	θ
955	■x85423899	*63	Vollage comparator, operating within a common voltage range of -12 V or more but not exceeding +16 V and a differential voltage range of -24 V or more but not exceeding +24 V and a response time not exceeding 2,2 µs, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			EL 2019 LM 119 LM 219 LM 319 LT 1016 TB 3702	
			or - other identification markings relating to devices complying with the abovecentioned description	8
956	●x85423889	₹64	Phase-locked loop (PLL) circuit of bipoler technology, comprising an oscillator and a frequency and/or phase detector, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			N523198P 8N 28967	
			10	
			<ul> <li>other identification merkings relating to devices complying with the abovementioned description</li> </ul>	θ
254 ex854236	Ex85423899	¥66	Circuit capable of <u>swithching</u> inductive and resistive loads, comprising not more than 4 diodes, 2 resistances and 1 insulated gate bipolar transistor (1687) of the N-channel type having a <u>collector-emitter breakdown voltage of 319 V or more, operating</u> <u>with a continuous collector current not exceeding 19 A and</u> with a dissipation rate not exceeding 180 W, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			14N366VL 14N48FVL	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	∕θ
806 ex8542	ex85423899	<b>*</b> 67	Audio signal processing circuit, capable of switching audio signals, comprising automatic lavel control circuits, amplifiers and mute circuits, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			LA 7282	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
883	ex85423009	¥58	Videc - «cording and reproducing signal <u>s</u> processing circuit, in two form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			LA 7437	
			or	
			- other identification markings relating to devices complying with the abovementioned description	

	CN code	TARIC	Description	Rate of autonomous duty (x
885	ex85423099	¥69	Intersediate frequency (IF) receiver, operating at an input frequency range of 400 kHz to 500 MHz, comprising a sixer, septifiers, demodulators, an automatic gain control detector and an oscilator, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			AD 687	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	9
886 ex8542369	ex85423899	¥78	Frequency converter of gellius arsenide (GeAs) semiconductor saterial, for the conversion of <u>input</u> frequencies of 78 MHz or more but not exceeding 350 MHz to <u>output</u> frequencies of 1,7 GHz or more but not exceeding 2,5 GHz, in the form of a monolithic integrated enalogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(a):	
			RFIC 1813 RFIC 1814	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
887	ex85423899	•71	Switch unit of gellius arsenide (GeAs) semiconductor meterial, with an operating frequency range between 500 MHz and 1200 MHz, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			RFIC 8983	
			70	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
889	ex85423899	\$72	Graphic display equalizer circuit, comprising <u>7 passband</u> filters, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			XR 1008	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovesentioned description</li> </ul>	θ
890	ex85423099	173	Audio signal processing circuit, providing enhancement of non-encoded sound mignals and phase/maplitude distortion compensation, in the form of a monolithic integrated analogue circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			XR 1071	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
957	ex85424010	•61	Hicroprocessor of C-MO8 technology, with a processing capacity of 32 bits, consisting of a single substrate layer on which are sounted 2 chips, one comprising a central processing unit (CPU) and the other a memory unit, in the fore of a hybrid integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	

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	CN code	TARIC	Description	Rate of autonomous duty (X
			57-00000 57-19400	
			0 F	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
958	ex85424838	*81	4-channel digital-to-analogue converter, each channel having a capacity of 12 bits, in the form of a hybrid integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			AD 398	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
959	ex85424838	•82	16-bit digital-to-analogue converter, in the form of a hybrid integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			DAC 785 DAC 786 DAC 787 DAC 788 DAC 789	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
960	sx85424030	<b>#</b> 03	12-bit snalogus-to-digital converter of C-MOS technology, comprising a sample and hold amplifier having a dynamic performence of 1 MHz per second or more, in the form of a hybrid integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			ADS 112 ADS 117	
			70	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
835	ex85424838	#84	12-bit enalogue-lo-digital converter of bipolar technology, comprising a voltage reference circuit, providing a sampling rate of at least 10 MHz, in the form of a hybrid integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of)	
			the following combination(s):	
			AD 9842	
			0 <i>r</i>	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
962	ax85424858	¥01	Amplifier for the frequency range 20 Hz to 20000 Hz, in the form of a hybrid integrated circuit contained in a housing	······································
			bearing: - an identificat <u>ion marking consisting of or including (one of)</u> <u>the fotlowing combination(s):</u>	
			STK 4841 STK 4151 STK 4281	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
963	Bx85424858	¥82	Amplifier of gallium arsenide (GaAs) semiconductor material, operating within a fraquency range of 872 MHz to 985 MHz, with an output power not exceeding 1,259 W (31 dBm) and an input power not exceeding 0,01 W (10 dBm), in the form of a hybrid integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	

	CN code	TARIC	Description	Rate of autonomous duty (X)
			5P6612301 <u>FNC 888981-79</u> F <u>NC 888981-68</u> NC 5952	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
964	8×85424050	¥03	Amplifier for a nominal range of 8 or more but not exceeding 78 kHz, with an implation voltage of 758 V or more and a lamkage of not more than 1 µA, in the form of a hybrid integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			ISO 100 ISO 102 ISO 106 ISO 120 ISO 121	
	•		or	
			<ul> <li>other identification earkings relating to devices complying with the abovementioned description</li> </ul>	θ
965	ex85424050	¥84	Amplifier with a programmable gain factor, in the form of a hybrid integrated circuit contained in a housing basering: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			3606 G	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
966	ex85424050	<b>₽</b> 05	Amplifier, operating with a supply voltage of 28 V, for frequencies of 1625 MHz or more but not excedding 1645 MHz, in the form of a hybrid integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			STM 1645-30	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
967 ex854240	ex85424050	¥06	Amplifier of bipolar technology, operating within a fraquency range of 800 MHz to 850 MHz, with at least one of the following characteristics: - a) an output power of 12,5 W at an input power of 180 mW, - b) an output power of 20 W at an input power of 200 mW, in the form of a hybrid integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			B)PHW 5113 b)NHW 828-1 b)NHW 828-2	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
968 6	ex85424050	\$87	Amplifier, operating within a frequency range of 68 MHz or more but not exceeding 470 MHz, with an output power not exceeding 40 W and an input power of 150 eW or more, in the form of a hybrid integrated circuit contained in a housing baaring: - an identification marking consisting of or including (one of) the following combination(s):	
			BGV 135 BGV 145 BGV 45	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ

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	Amplifier, operating within a frequency range of 400 MHz to 470 MHz, with an output power of 2 W at 6 V and an input power not exceeding 30 mW, in the form of a hybrid integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
	N 8 <u>8</u> 710	
	or	
	<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
*89	Amplifier with an input power of 1 mW and an output power not exceeding 3,5 W at a frequency range of <u>880</u> MHz or more but not exceeding <u>915</u> MHz or at a frequency range of 1710 MHz or more but not exceeding <u>1785</u> MHz, in the form of a hybrid integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
	FA 81314 <u>QCPM 9481</u>	
	ог	
	<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
<b>#</b> 01	Dual caramic filter, opersting within a frequency range of 872 MHz to 950 MHz, in the form of a hybrid integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
	7F66314B	
	or	
	<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
¥82	Current detector, having an input resistance not exceeding 9 Ohe, withstanding an isolation AC voltage of 3,75 kV or 4 kV during 1 minute, in the form of a hybrid integrated circuit contained in a housing bearing: - an identification marking conmisting of or including (one of) the following combination(s):	
	HF8 113F001A1 NA 91000018	
	or	
	<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
¥03	Voltage regulator with an input voltage not exceeding 1 kV and a fixed output voltage of 41,8 V (±8,5 V), 182,6 V (±1 V) or 124,3 V (±1 V), in the form of a hybrid integrated circuit contained in a housing bearing: - an identification earking consisting of or including (one of) the following combination(s):	
	8TR 51482 8TR 51424 8TR 54841	
	07	
	<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	0
¥84	Vollage and current regulator, having an output voltage not exceeding <u>1 kV</u> at a drive current not exceeding 8,7 A, comprising a power transistor and a control circuit with an oscillator, in the form of a hybrid integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	,
	*01 *02 *03	<ul> <li>contained in a housing bering: <ul> <li>- en identification servings containing of or including (one of)</li> <li>the following combination(2):</li> <li>R \$§718</li> <li>or</li> <li>- ether identification servings relating to devices complying with the abovementioned description</li> </ul> </li> <li>480 Asplifler with an input power of 1 aV and an output power not acceeding 315 W at a frequency range of 200 MHz or sore but not acceeding 115 MHz or at a frequency range of 1718 HHz or area but not acceeding 1185 MHz, in the fors of a hybrid integrated circuit contained in a housing berring: <ul> <li>an identification servings relating to devices complying with the abovementioned description</li> </ul> </li> <li>601 Dust constitution generating to device complying <ul> <li>with the abovementioned description</li> </ul> </li> <li>601 Dust constitution servings relating to devices complying <ul> <li>with the abovementioned description</li> </ul> </li> <li>601 Dust constitution servings relating to devices complying <ul> <li>with the abovementioned description</li> </ul> </li> <li>601 Dust constitution servings relating to devices complying <ul> <li>with the abovementioned description</li> </ul> </li> <li>602 Current detector, having an input resistance not accessing 3 <ul> <li>603 Or</li> <li>other identification servings relating to devices complying <ul> <li>with the abovementioned description</li> </ul> </li> <li>602 Current detector, having an input resistance not accessing 3 <ul> <li>603 Ohs withstand genering: <ul> <li>m identification servings relating to devices complying </li> <li>with the abovementioned description</li> </ul> </li> <li>603 Current detector, having an input resistance not accessing 3 <ul> <li>604 Ohs</li> <li>605 Or</li> <li>other identification servings relating to devices complying </li> <li>with the abovementioned description</li> </ul> </li> <li>603 Vating regulator with an input voting of or including (one of) <ul> <li>the following combinition(2):</li> <li>The following combi</li></ul></li></ul></li></ul></li></ul>

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CN code	TARIC	Description	Rate of autonomous duty (%)
		or	v
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
977 ex85424898	*85	Voltage regulator with a nominal input operating voltage of 278 V, an input current not exceeding 8 A and an operating frequency not exceeding 208 kHz, in the form of a hybrid integrated circuit contained in a housing bearing: - an identification marking conmisting of or including (one of) the following combination(m):	
		NA 2810 NA 2820 NA 2830	
		or	
		- other identification markings relating to devices complying with the abovementioned description	0
978 ex85424898	\$86	Voltage and current regulator, having an input voltage not exceeding 35 V and a quiescent current not exceeding 180 µA, comprising a field-effect transistor (FET) with a drain current not exceeding 32 A, in the form of a hybrid integrated circuit contained in a housing bearing: - an identification marking consisting of or including (onm of) the following combination(s):	
		STR N6523	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
979 ex85424898	*07	Clock generator, in the form of a hybrid integrated circuit contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
		6468211	
		or - other identification markings relating to devices complying with the abovementioned description	8
380 ex85424090	\$68	Vollage regulating and relay circuit for central locking and alarm system, comprising a constant voltage circuit and m sampling circuit, in the form of a hybrid integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		BX 6531 BX 6563	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
981 ex85424898	*89	Transmitter of gallium ersenide (GeAs) memiconductor material, operating with frequencies of 21 GHz or more but not exceeding 48 GHz, in the form of a hybrid integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		371-230 371-380	
		0 7	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
983 sx85424090	¥10	Amplifier control circuit, comprising digital-to-analogue converters and analogue-to-digital converters, in the form of a hybrid integrated circuit contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	

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		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
985 ex85425000	*81	Silicon power bridge rectifier, with reverse voltage not exceeding 800 V and an average forward current of 1 A <u>or more</u> <u>but not exceeding 4 A</u> , in the form of a microssembly contained in a housing	θ
986 ex85425000	*82	Duel silicon zener diode, with a zener voltage of 11 V or more but not exceeding 13 V and a dissipation rate not exceeding 200 mV, in the form of a microsseebly contained in a housing	θ
987 ex85425000	*83	Quintuple field-effect transistor (FET), having a drain-to-source breakdown-voltage of 100 V or more, operating with a continuous drain current not acceeding 5 A, and with a dissipation rate not exceeding 35 V, in the form of a microssessity contained in a housing bearing: - an identification aarking consisting of or including (one of) the following combination(s):	
		8LA 5021	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
988 ex85425000	<b>₿</b> ₿ <b>4</b>	Silicon diode assembly, comprising a diode with a reverse recovery time not acceeding 1,5 µs, a racurrent peak reverse voltage not exceeding 1500 V and an average forward current not exceeding 5 A, in the form of a microassembly contained in a housing	θ
989 ex85425000	¥85	Assembly for overvollage protection, consisting of an array of 4 diodes, with a breakdown-voltage of 6 V or more, a peak putse power of 300 V for 8 overvoltage pariods of 20 ys each, in the form of a microassembly contained in a housing of the SMD (Surface mounted device) type	θ
233a ex85425000	*87	Overvoltege suppression circuit, comprising 2 diodes, having a reverse stand-off voltage not exceeding 4,5 V, a reverse leakage current not exceeding 10 pA, a peak pulse current not exceeding 30 A and a nominal capacitance of 50 pF, in the form of a micromessably contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		V2.8 V3.3 V4.5	
		of	
		<ul> <li>other identification sarkings relating to devices complying with the abovementioned description</li> </ul>	θ
997 ax85438990	€31	Amplifier of bipolar technology, operating within a frequency range of 68 MHz to 88 MHz, with an output power of 5 W at an input power of 1 mW, consisting of active and passive elements mounted on a printed circuit, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
		NHW 185 XHW 185	
		or	
		<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
998 ex85438998	<b>#</b> 32	Amplifier of gellium arsenide (GmAs) semiconductor material, operating with a frequency range of 1710 MHz to 1785 MHz, with an output power of 3 W at an input power of 1 mW or with an input level not exceeding 5 dBm and an output level of 30,8 dBm or more, consisting of active and passive elements mounted on m	
		printed circuit, contained in a housing bearing: - an identificat <u>ion aarking consisting of or including (one of)</u> <u>the following combination(a):</u>	

			or	
			- other identification markings relating to devices complying with the abovementioned description	θ
999 e:	ex85438998	#33	Amplifier of bipolar technology, operating within a frequency range of 136 MHz to 174 MHz, with an output power of 7 W at an input power of 1 mW, consisting of active and passive elements mounted on a printed circuit, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			MHW 607	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
1000	ax85438990	\$34	Amplifier of bipolar technology, operating within a frequency range of 480 MHz to 470 MHz, with at least one of the following characteristics: - a) an output power of 3 W at an input power of 1 mW,	
			- b) an output power of 7 ₩ at an input power of 1 m₩,	
			- c) an output power of 28 W at an input power of 158 mW,	
			consisting of active and passive elements mounted on a printed circuit, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			в)ИНИ 784 Б)ИНИ 787 с)ИНИ 728	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
1881	ex85438990	•35	Amplifier with an isolation voltage of 1588 V or more and with a leakage current not exceeding 8,5 µA, consisting of 2 capacitors and 2 monolithic integrated circuits on a printed circuit which is mounted on a plastic carrier, the whole contained in a housing the exterior dimensions of which do not exceed 8 x 21 mm, with not more than 8 connections and bearing: - an identification marking consisting of or including (one of)	
			the following combination(s):	
			1\$0 122	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
1002	ex85438998	₩36	Electromagnetic display consisting of 7 electromagnetic coils, which by means of the residual magnetism in the stators provide that the last indication remains available (met state), and 7 pivoting light-reflecting segments each of which is mathemated to a bar magnet. The display is contained in a housing the exterior dimensions of which do not exceed 28 x 36 x 50 mm	θ
1883	ex85438990	\$37	Digital image processor unit with a speed of 1 to 50 images per second, with a spatial resolution of 512 x 512 pixels or more and a radiometric resolution of 16 bits, comprising supply units and 11 printed circuits on which are mounted integrated circuits and other active and passive elements, the whole mounted in a frame, for use in the menufacture of cerdiodimgnostic appparatus (a)	θ
1004	Ex85438998	*38	Radio frequency (RF) modulator, operating with a frequency range of 43 MHz or more but not exceeding 870 MHz, capable of switching VHF and UHF signals, consisting of active and passive elements mounted on a printed circuit, contained in a housing	8

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CN co	de	TARIC	Description	Rate of autonomous duty (X)
1005 ex854	138998	<b>€39</b>	Amplifier, operating with a frequency range of 925 MHz to 960 MHz, with an output power of 16 W at an input power of 0,035 W (15,5 dBm), consisting of active and passive elements mounted on a printed circuit, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			NHW 916	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
1010 ex854	138996	<b>≇</b> 44	Reclifier assesbly of power barrier diodes, consisting of 2 diodes with an average forward current not exceeding 800 A and a repetitive reverse peak vollage not exceeding 40 V, each contained in a housing and connected by a common cathode	θ
1012 ex854	138990	\$46	Piszo-slectric crystal clock oscillator with a fixed frequency, within a frequency range of 1,8 MHz to 67 MHz, contained in a housing bearing: - an identification <u>warking consisting of or including (one of)</u> the following combination(s):	
			R400R.8 R4000.9	
			07	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
1013 ex854	138996	\$47	Transmitter/receiver powered by a received pulse with a frequency of 134,2 kHz, capable of transmitting message identifications with error correction codes, comprising a solenoid, a capacitor and an integrated circuit, the whole contained in a hereetically sealed glass capsule	θ
1014 ex854	138998	#48	Nechanical vibratory gyroscope driven by a 25 or 26 kHz oscillator, comprising a differential amplifier and a detector circuit, contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			ENC05D	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	e
1015 ex854		¥49	<pre>Amplifier, operating within a frequency range of 800 MHz to 960 MHz, with at least one of the following characteristics: - s) an output power of 1.41 W at an input power of 5 mW, - b) an output power of 2 W at an input power of 1 mW, - c) an output power of 1.8 ou 3.2 W at an input power not axceeding 2 mW, - d) an output power of 3.5 W at an input power of 1 or 100 mW, - e) an output power of 8 W at an input power of 1 or 100 mW, - e) an output power of 8 W at an input power of 1 or 100 mW, - e) an output power of 7 W at an input power of 1 or 100 mW, - f) an output power of 7 W at an input power of 1 or 100 mW, - h) an output power of 2.4 or 3.2 W at an input power not axceeding 5 mW, - i) an output power not axceeding 10 W and an input power not axceeding 200 mW, - j) an output power not axceeding 25 W and an input power not axceeding 150 mW, consisting of active and passive elements mounted on a printed circuit, contained in a housing bearing: - an identification marking commisting of or including (one of) the following combination(s):</pre>	
			•)NHW 9862 d)XHW 963 g)PF 6146 j)NHW 927 b)NHW 803 •)8HW 5115 <u>b)PF 6148</u> j)PHW 2985 <u>c)PF 6144</u> •)XHW 5115 <u>i)NHW 918</u> <u>j)PHW 925</u> c)PHW 902 <u>f)NHW 914 j)NHW 916 j)SHW 5116</u> d)NHW 953 f)NHW 915 j)NHW 926 j)XHW 2982	
			or	

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	CN code	TARIC	Description	Rate of autonomous duty (X)
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
1016	ax85438998	\$58	Opto-stattonic circuit comprising one or more light-amitting diodes (LEDs) and one photodiode with amplifier circuit and an integrated logic gate arrays circuit or one or more light-amitting diodes (LEDs) and at least 2 photodiodes with amplifier circuit, contained in a plastic housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			HC PL 2400 HC FL 2730	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
1017	ex85438998	•51	Temperature companiesting frequency oscillator with a nominal frequency of 12,8 or 13 MHz and operating at a supply voltage of 3 V (±0,3 V), comprising a printed circuit on which are mounted at teest a piezo-electric crystal and an adjustable capacitor, contained in a housing with not more than 5 connections and bearing: - an identification marking consisting of or including (one of) the following combination(s):	
			TCX0-111 TX0_2603	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned Jescription</li> </ul>	0
1818	sx85438998	*52	Oscillator, with a centre frequency of 28 GHz or more but not exceeding 42 GHz, consisting of active and passive alements not mounted on a substrate, contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):	
			372-02 372-03	
			or	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	8
1020	ex85438998	\$55	Voltage regulator with an output voltage of 5 V or more but not exceeding 12 V and a dropout voltage not exceeding 1 V at an output current of 1,5 A, consisting of a power transistor and an integrated circuit mounted on a metallic baseptate, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	-
			38580 38980 31280	
			70	
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ
233Ь	BX85438990	¥56	Overvoltage suppression assembly, comprising <u>8</u> diodes, having a reverse stand-off voltage not exceeding 4,5 V, a reverse Leakage current not exceeding 10 µA, a peak pulse current not exceeding 30 A and a nominal capacitance of 50 pF, contained in a housing	θ
993	ax85438990	\$57	Amplifier, operating within a frequency range of 1885 MHz to 1978 MHz, with at least one of the following characteristics: - a) an output power not exceeding 15 W at an input power not exceeding S8 mW (17 dBm), - b) an output power of 1 W or more at an input power of 2 mW (3 dBm), consisting of active and passive elements mounted on a printed circuit, contained in a housing bearing: - an identification marking consisting of or including (one of) the following combination(s):	

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or

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			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ			
1021	ex85439090	Dust field-effect transistor (FET) with at least one of following characteristics: - a) of the P-channel type, having a drain-to-source breakdown-voltage of -20 V, operating with a drain-current no axceeding 9,2 A and with a dissipation rate not exceeding 2 W - b) of the N-channel type, having a drain-to-source breakdown-voltage of 20 V or sore, operating with a drain-current not exceeding 3,5 A and with a dissipation rate not exceeding 2 W, contained in a housing bearing: - an identification earking consisting of or including (one of) the following combination(a):					
			a)9947 a)MNDF2C028 b)9956 b)MNDF1N50E a)9953 a)MNDF2P02HD b)9859 b)MNDF2C02E				
			70				
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ			
10215	ex85439090	\$58	<u>Stainless steel cathods in the form of a plate with an hanger</u> bar and plastic side strips	θ			
1024	ex85459090	<b>#</b> θ1	Cell and battery carbon, in the form of rods, with a length of 34 mm or more but not exceeding 160 mm and a dimmeter not exceeding 12 mm	θ			
1826	ex85489000	#31	Contact isage sensor	θ			
1027	ex85489666	₹32	Optical unit, consisting of a laserdiode and a photodiode, operating at a typical wavelangth of 635 or 678 na	θ			
1028	ex854890∂0	¥33	Infrared signal receiver unit, consisting of a photodiode and at least an amplifier in the form of a monolithic integrated circuit, contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> _ the following combination(s):				
			GP1U58XB 8BX 1610				
			or				
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ			
103ŭ	ex85489000	<b>#</b> 35	Optical unit consisting of a laser diode, a photodiode and a lens, operating at a typical wavelength of 1310 or 1550 nm, contained in a housing	θ			
148	ex85489000	137	<u>Unit, consisting of a</u> resonator operating within a frequency range of 1,8 MHz or sore but not exceeding 40 MHz and <u>a</u> capacitor, contained in a housing	θ			
1025	ex85489666	\$38	Electronic assembly for a thermal printer head, consisting only of conductor elements, integrated circuits and at least 9984 heater elements, the whole mounted on a ceramic substrate the exterior dimensions of which do not exceed 2 x 51 x 271 mm	θ			
1659	ex85489000 ex91109000	€39 €94	Clock/calandar circuit, consisting of a printed circuit on which are mounted at tasat a quartz oscillator and a monolithic integrated circuit, the whole contained in a housing bearing: - an identificat <u>ion marking consisting of or including (one of)</u> the following combination(s):				
			DS 1287 DS 1387 WK 48708 WK 48718 RTC 65271 DS 12887A WK 48702 WK 48712 RTC 63421 RTC 72423	,			
			or				
			<ul> <li>other identification markings relating to devices complying with the abovementioned description</li> </ul>	θ			

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	CN code	TARIC	Description	Raie of autonomous duty
1031	ex90011010 ex90011090	*10 *10	Image reverser made up from an assembly of optical fibres	θ
1032	ex90012000	¥10	Naterial consisting of a polarising film, supported on one or both sides by transparent material	θ
1033	ex98812888	\$28	Polarising plastic fils, consisting of a transparent protective file and a polarising masbrane	θ
1034	ex98812888	¥30	Polarising lanticular plastic plate with a lanticular array pitch of 0,78 mm, a thickness not exceeding 0,99 mm and the exterior dimensions of which do not exceed 740 x 974 mm	8
1035	ex96019099	¥19	Fresnel lens of plastic, unacunted, with a diagonal of more than 100 cm, for use in the manufacture of products falling within heading 8528 (m)	8
1036	ex96619696	¥28	Rear projection acrean, comprising a Freenet lens of plastic and a polarizing sheet of plastic, for use in the manufacture of products falling within subheading No 8528 (a)	θ
1037	ex98819898	<b>#</b> 30	Lens of plastic, unmounted, having a focal length of 3,86 mm (±0,1 mm) and with a diameter not exceeding 8 mm, for use in the manufacture of compact disc players (a)	θ
1038	ex90019098	¥40	Optical fibre plate, for use in the manufacture of screens and photocathodes for image intensifiers (a)	θ
1039	ex96619696	¥60	Prism for the splitting of light, unmounted, for use in the manufacture of charged-coupled <u>image (</u> CCD) cameras (a)	θ
1849	вх90021100	₹19	Adjustable lens unit, having a focal length of 90 mm or more but not axceeding 180 mm and comprising a combination of between 4 and 8 glass or methacrylic lenses with a dismeter of 120 mm or more but not exceeding 180 mm, each lens costed on at teast one side with a magnesium fluoride layer, for use in the manufacture of video projectors (a)	6
1841	ex98821188	<b>≇</b> 50	Lens unit, having a focal length of 75 mm or more but not exceeding 94 mm, consisting of glass or plastic lenses, with a diameter of 66 mm or more but not exceeding 188 mm	θ
1042	ex96821988	¥10	Lens unit, having a focal length of 24,96 mm (±0,1 mm), a dimmeter of 16 mm and a length of 16 mm, for use in the manufacture of products falling within mubheading 85172100 (m)	θ
1843	ex98829891	#10	Optical element comprising an octagonal Fresnel lens, for use in the manufacture of overhead projectors <u>(a)</u>	θ
1044	ex90029091	¥28	Lens, mounted, having a fixed focal length of 3,8 mm (±0,19 mm) or 8 mm (±0,4 mm), with a relative aperture of F2.0 and a diameter not exceeding 33 mm, for use in the manufacture of charged-coupled (CCD) cameras (a)	β
1045	ex96629699	\$18	Optical unit, comprising 1 or 2 rows <u>of optical glass fibres</u> in the form of lanses <u>and with a dismeter of 0,85 mm or more</u> but not exceeding 1,15 mm, embedded between 2 plastic plates	θ
1046	ex90109000	¥10	Parts of apparatus for the projection of drawings of circuit patterns on sensitised semiconductor material, only consisting of a plastic membrane with a thickness not exceeding 3 µm and a metallic frame	θ
1847	90138030		Liquid crystal devices, other than active matrix liquid crystal devices	θ
1048	ex90138090	\$18	Polarisation insensitive fibre-optic isolator, operating at a wavelength of 1300, 1480 or 1550 nm, contained in a cylindrical housing	θ
1050	■x96179888	¥10	Thermal printer head, comprising at least 7188 heater elements mounted on 2 or more ceramic supports, the whole contained in a housing the exterior dimensions of which exceed 21 x 39 x 639 mm	θ

	CN code	TARIC	Description	Rate of autonomous duty (%)
1052	ex90213090	#29	Vascular prothesis, neither woven nor knitted, of which the largest opening has an internal diseater of not exceeding 8 as	θ
1853	ex98213898	#38	Heart valves and parts thereof	θ
971	ex90318039	¥1 <del>0</del>	Acceleration measurement <u>device for automotive sirbage</u> , comprising <u>active and passive elements sounted on a printed</u> <u>circuit and a sensor, the whole contained in a housing</u>	θ
1854	ex98319898	*10	Assembly for a laser align sensor, in the form of a printed circuit comprising optical filters and a charge-coupled (CCD) image sensor, the whole contained in a housing	8
1055	ex98328998	¥10	Automotive mirbmg shock-mensor, comprising a contact capable of switching a current of 12 A at a voltage of 30 V, having a typical contact remistance of 80 moha	θ
1056	ex91101200	*91	Ansembly consisting of a printed circuit on which are mounted one quartz oscillator, at least one watch circuit and, whether or not integrated, at least one capacitor, of a thickness not exceeding 5 mm, for use in the manufacture of products falling within Chapter 91 (m)	θ
1057	ex91109000 ex91149000	<b>*</b> 92 <b>*</b> 91	Assembly consisting of a printed circuit on which is mounted a watch circuit or a watch circuit and a quartz oscillator, of a thickness not exceeding 5 mm, for use in the manufacture of products falling within Chapter 91 (mm)	θ
1058	ex91189888	<b>₽</b> 93	Assembly consisting of a printed circuit on which is mounted at least one watch circuit, a quartz oscillator and a piezo-electric sound element, with a thickness exceeding S mm, for the manufacture of products falling within Chapter 91 (m)	0
1868	ex96089100	<b>≇1</b> 0	Non-fibrous plastic pan-tips with an internal channel	θ
1861	ex96139000	\$28	Piezo-electric ignition mechanism	8

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(a) Control of the use for this special purpose shall be carried out pursuant to the relevant Community provisions.
(b) However, the suspension is not allowed where processing is carried out by retail or catering undertakings.

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## FINANCIAL STATEMENT

- 1. Budget heading concerned: Chapter 12, Article 120
- 2. <u>Title of operation:</u> Proposal for a Council Regulation (EC) temporarily suspending the autonomous Common Customs Tariff duties on certain industrial and agricultural products.
- 3. Legal basis: Article 28 of the Treaty.
- 4. <u>Objective of operation</u>: Suspension of Common Customs Tariff duties in respect of the abovementioned products.
- 5. <u>Prevention and protection measures</u>: The end-use of certain of the products covered by this Council Regulation will be monitored in accordance with Articles 291 to 304 of Commission Regulation (EEC) No 2454/93 laying down provisions for the implementation of the Community Customs Code.
- 6. <u>Cost of the operation</u>:

In order to limit the potential economic problems liable to arise on account of the time-limits set by existing regulations, this Regulation does not specify an expiry date. It will be reviewed, and amended if necessary, every six months, but in this case by means of a new regulation. The costs estimated below are therefore **annual costs** chargeable to the EC budget (uncollected customs duties). This Regulation covers products which have to date been the subject of three different regulations. Estimating costs is no easy task mainly due to the lack of recent Community statistics and to the arrival of the three new Member States, for which complete economic data is not yet available.

In establishing costs, account was taken of:

- the latest available EUROSTAT statistics relating to the last three regulations,
- Member States' declarations on the use of suspensions and import forecasts,
- the number of new and renewed suspensions.

Based on the figures for the last three years, uncollected duties in respect of the products covered by this Regulation should reach some ECU 1.6 billion (i.e. an increase of 40% per annum since 1993). The true figure is, however, expected to be lower on account of the reduction or abolition of customs duties on a certain number of products under agreements concluded pursuant to Article XXIV.6:

- 110 chemical products, currently under suspension, are now zero-rated
- a general drop in duty from 14% to 7% on the most widely used integrated circuits
- zero-rating for microprocessors and certain types of memory.

### Estimated annual cost of the current operation

In these circumstances, the closest possible estimate of the amount of uncollected duties for the year 1996-97 stands at ECU 1 200 million compared with ECU 1 135 million for the same period the previous year (1 July 1995 to 30 June 1996).

The current operation under the proposed Regulation will therefore give rise to an additional loss of resources of around ECU 65 million during the period 1 July 1996 to 30 June 1997.

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#### FINANCIAL STATEMENT ANNEX

Figures for imports under suspension, based on EUROSTAT statistics, are available for each calendar year until 1994. They can be used to calculate the annual amount of uncollected duties for each of the three areas in question, i.e. chemical, micro-electronic and agricultural products.

The figures for 1995, 1996 and 1997 are based on estimates, account being taken of:

- the average annual percentage rises in each area calculated on the basis of the 1991-94 figures,

- changes in the rate of CCT duties in 1995 and 1996 pursuant to agreements under the GATT and Article XXIV.6.

Year	1993	1994	1995	1996	1997
agricul. microelect. chemicals	20 471 216	26 704 283	27 920 265 <sup>c)</sup>	30 786 <sup>a),b)</sup> 210 <sup>d</sup> )	32 1.020 260
total	707	1.013	1.212	1.026	1.312

The amounts of uncollected duty, in ECU millions, are specified in the table below:

## Table 1Uncollected duty by calendar year

The amounts have been calculated on the following basis:

1- agriculture:

An average percentage increase of between 2% and 4% in the years 1995 to 1997.

#### 2-microelectronics:

An average percentage increase of between 40% and 30% in the years 1995 to 1997.

For 1996, the figure calculated in this way has been by:

a - ECU 150 million, on account of the zero-rating introduced for microprocessors and certain types of memory falling in CN headings 85 42 11 12 to 85 42 11 68. b - ECU 260 million, on account of the reduction in duties from 14% to 7% on other

products of heading 8542.

#### 3- chemicals:

An average percentage increase of between 10% and 13% for the years 1995 to 1997.

The figure calculated in this way has been reduced by:

c - ECU 63 million for the year 1995, on account of the zero-rating of pharmaceutical products and derivatives (GATT).

d - ECU 98 million for the year 1996, on account of the zero-rating of chemical products in Chapters 27 to 39 (Article XXIV.6).

As the regulations in question run from 1 July to 30 June of the following year the figures given for these periods were calculated using the arithmetic mean of two consecutive years (see Table 2).

Year	1.7.1993-94	1.7.1994-95	1.7.1995-96	1.7.1996-97
chemicals microelect. agricult.	249,5 587,5 23	274 812 26,5	237,5 853 28,5	235 903 32
total	860	1112,5	1119	1170

# Table 2Uncollected duties by "regulation" years

Account should also be taken of the accession of the new Member States, which submitted suspension applications in 1995 and 1996. Assuming that the percentage of uncollected duties equates to the number of suspensions granted to these States, a total of ECU 15 million and ECU 30 million in uncollected duties should be added for 1995 and 1996 respectively.

The estimated amount of uncollected duty for the periods 1.7.95-30.6.96 and 1.7.96-30.6.97 is therefore ECU 1135 million and ECU 1200 million respectively.

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